Theoretical Study on Nonlocal Effects in Resonant X-Ray Emission Spectra of Strongly-Correlated Systems

強相関電子系の共鳴X線発光スペクトルにおける非局所効果の理論的研究

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Chapter 1

General Introduction

In this chapter, a brief survey is given of the ideas that lie at the basis of the other chapters in this thesis. We first explain the historical background of this study. Next we derive formulae for scattering cross section of the second order optical process, and explain its general properties. Model Hamiltonians, the Zhang-Rice singlet, core excitons and numerical techniques are sketched in the rest of this chapter. We finally summarize our motivation of this thesis.

1.1 Historical Survey on High-Energy Spectroscopies

1.1.1 Core-level spectroscopies

Since before the advent of quantum mechanics, light rays have been used as a tool to investigate the microscopic world. In fact, it is since the success in explaining the experimentally observed optical spectra such as the Balmer series of hydrogen [1] that the Schrödinger and the Heisenberg equations have been acknowledged as the fundamental equations. The discovery of the spin degrees of freedom is also associated with spectroscopic experimental facts such as the Zeeman effect or the Pashen-Back effect [2]. In this sense, spectroscopies had played a role of a cradle of quantum mechanics. The atomic theory of spectroscopy had been completed before the end of the World War II by the famous papers by Slater [3], and by Racah [4], all of which were accidentally titled “theory of complex spectra”. It was Racah who introduced the notion of spherical tensors. In these papers, they classified the eigenstates of atoms containing many electrons according to SO(3) group, and clarified selection rules in an optical transition. Since sufficiently deep core orbitals in solids nearly exactly maintain the SO(3) symmetry, their theories often appear as a leitmotiv in core-level spectroscopy (CLS) studies on solids at present.

The development of many-body physics has promoted the application of CLSs to the solid state. Let us concentrate our attention to CLSs in the X-ray regime. Apart from the academic trend of research on the Fermi edge singularity, it was Siegbahn and co-workers who stated the significance of CLS in material science of solid states. They named X-ray photoemission spectroscopy ESCA (Electron Spectroscopy for Chemical Analysis), and had carried out extensive studies. Their first review article was issued in 1967 [5]. The systematic analysis let Siegbahn have won the Nobel Prize in 1981. Because of the recent development of synchrotron light sources, and the establishment of modern theory of CLS as will be explained in the next subsection, CLS occupies a huge research area in material science today.
Figure 1.1 shows several modes of CLS for insulators. In X-ray absorption spectroscopy (XAS), a core electron is photoexcited by incident X-rays with energy $\Omega$ into an empty valence state. Roughly speaking, the density of states (DOS) of the unoccupied band would reflect on the XAS spectrum. In the case of X-ray photoemission spectroscopy (XPS), a core electron is photoexcited into the high-energy continuum. The energy of the photoelectron is simply that of the core level if there were no core-valence Coulomb interaction. However, the existence of valence fluctuation in a class of materials and strong Coulomb interaction gives rise to complicated spectra. XAS and XPS are classified into first-order optical processes, where “first-order” means that they can be described within the first-order perturbation theory of electron-photon interaction.

Resonant X-ray emission spectroscopy (RXES) is one of the second-order optical processes, where a core electron is resonantly photoexcited to an empty valence level, then a valence electron makes a radiative transition to emit an X-ray with energy $\omega$. In contrast to XAS and XPS, there is no deep core hole in the final state, and the number of electrons in the final state is the same as that of the ground state. Thus, its spectra can be directly compared to those of valence level experiments, e.g., optical conductivity. RXES, however, has several advantages over other spectroscopies. First, it is a site- and shell-selective experiment. For example, one can separately excite a Cu $2p$ orbital or an O $1s$ orbital in a CuO$_2$ plane of high-$T_c$ cuprates, by tuning incident photon energy $\Omega$ at an appropriate range. This is a common feature of CLS, and it makes CLS free from overlapping effects between, e.g., the Cu $3d$ and O $2p$ orbitals in the CuO$_2$ plane in valence spectroscopies.

The second advantage of RXES as a photon-in and photon-out experiment is bulk-sensitivity, which owes the long escape depth of X-rays. Generally, the escape depth of X-rays is hundreds of times longer
than that of a photoelectron, which is of order of at most a few ten Å [6, 7]. The third advantage of RXES is due to its resonance behavior. By tuning $\Omega$ at a specific structure of XAS, one can choose the corresponding excited state "by hand" in the final state. This freedom is quite useful to study gap structures. In addition, RXES can sensitively reflect the electron dynamics associated with variety of relaxation processes after the creation of a core hole, through the resonant selection of an intermediate state. The fourth advantage of RXES is due to its selection rule. As will be explained using explicit expressions of the spectral function in § 1.2, RXES obeys selection rules of the local point group such as the dipole selection rule, as well as of the translational group of a whole crystal. This duality is extremely suitable for studying strongly correlated systems, where local as well as itinerant natures of electrons appear often at once.

Figure 1.2: Schematic explanation of valence spectroscopies and Auger electron emission process in an insulator. See the caption in Fig. 1.1 and the explanation in the text.

Let us turn our eyes to other spectroscopies again. Figure 1.1 (d) shows the "normal" X-ray emission spectroscopy (NXES), where a core electron is photoexcited into a high-energy continuum, not into valence states. Evidently, its intermediate state is the same as the final state of XPS, whereas the intermediate state of RXES is the same as that of XAS. Despite the apparent resemblance, NXES is quite different from RXES in at least two respects. First, the emitted photon energy $\omega$ is independent of the incident photon energy $\Omega$ in principle; $\omega$ roughly reflects DOS of the filled valence band. Second, apart from the photoelectron, the number of electrons in the final state decreases by one from that of the initial state. Accordingly, one has to use a spectral function considerably different from that of RXES in order to calculate NXES spectra.

Figure 1.2 (a) shows valence photoemission spectroscopy (v-PES or simply PES), where a valence electron is photoexcited into the high energy continuum, so that the valence band information is directly obtained. Figure 1.2 (b) shows a radiative process caused by a fast electron beam. As expected from the figure, it roughly reflects DOS of the unoccupied band. This type of spectroscopy is called inverse photoemission spectroscopy (IPES) or Bremsstrahlung Isocromat Spectroscopy (BIS). Although these valence spectroscopies have subtle things such as surface-sensitivity and charging effects for insulators,
the experimental resolution in the latest PES technique is still higher than that of RXES at present, where
the resolution of order of a few hundred meV is reported at best. Recent improvements in experimental
apparatus [8], however, would make possible higher resolution for RXES in the near future.

Figure 1.2 (c) shows the Auger decay process. After a core hole is photocreated, electronic correla-
tion between electrons can cause a nonradiative decay involving a simultaneous creation of an unbound
electron. Mathematically, this is due to a term such as

$$U_A c_r^{\dagger} \beta_{r1} \alpha_{r2}$$

in the Hamiltonian, where $U_A$ represents Coulomb interaction energy, and $c_r^{\dagger}$ is a creation operator of a
core electron at a given site $r$. $\alpha_{r1}$ and $\alpha_{r2}$ are annihilation operators of different kind of valence orbitals,
respectively. $\beta_{r}^{\dagger}$ is a creation operator of an unbound state with energy $\epsilon$. We discuss a role of the Auger
effect in RXES in the next section.

### 1.1.2 Origin of impurity models

The effects of impurity atoms on the properties of a metal is of considerable physical interest, because
of its singular behavior beyond uniform Fermi liquid theory [9]. A typical example is the resistance
minimum, which is observed in such metals as Cu and Al doped with a small amount of Fe or Ni.
In 1961, Anderson proposed the following model [10], the Anderson model, to discuss the magnetic
moment of the impurities,

$$H_{\text{And}} = \sum_{k, \sigma} \epsilon_k a_k^{\dagger, \sigma} a_k \sigma + \sum_{\sigma} \epsilon_d \sigma d_\sigma \sigma + \frac{1}{\sqrt{N}} \sum_{k, \sigma} \left( V_k a_k^{\dagger, \sigma} d_\sigma + H.c. \right) + U_{dd} d_\uparrow^{\dagger} d_\uparrow d_\downarrow^{\dagger} d_\downarrow + H.c.,$$

(1.2)

where $a_k^{\dagger, \sigma}$ is a creation operator of a conduction electron of the host metal with wave number $k$ and
a spin component $\sigma$. Similarly, $d_\sigma^{\dagger}$ is a creation operator of the impurity 3d orbital. $\epsilon_k$ and $\epsilon_d$ are
one-electron energies of the conduction band and the impurity orbital, respectively. $U_{dd}$ is the Coulomb
interaction of the impurity orbital. $V_k$ is the hybridization energy between conduction electron and
the impurity orbital. $N$ is the number of atoms of the host metal. In the limit of $|V_k/U_{dd}| \ll 1$, $H_{\text{And}}$ is trans-
formed into the $sd$ model through Schrieffer-Wolff transformation [11], the model with which Kondo
gives a clear-cut explanation for the long-standing challenge of the resistance minimum in 1964 [12].

Since the middle of the 1960s, the impurity model had been applied to the Fermi edge problem of X-
ray spectra. To discuss XAS or XPS spectra of simple metals $^1$, a localized core orbital was introduced
in place of $d_\sigma$ in $H_{\text{And}}$, and the Coulomb interaction $U_c$ between conduction and core orbitals were added,

$$H_{\text{MND}} = \sum_{k, \sigma} \epsilon_k a_k^{\dagger, \sigma} a_k \sigma - U_c \sum_{\sigma} a_0^{\dagger, \sigma} a_0 \sigma n_c + \epsilon_c (1 - n_c),$$

(1.3)

where $n_c$ is the number of core holes at a given site, say, the origin 0. $n_c$ is 0 for the initial state, 1
for the final state. $a_0^{\dagger, \sigma}$ is a creation operator of the conduction electron at the site 0. This is often
called Mahan-Nozières-DeDominicis (MND) model [13]. Based on this Hamiltonian, Nozières and
De Dominicis (ND) completely disclosed the origin of the Fermi edge singurarity [14], with elaborate
techniques in those days [15].

$^1$While X-ray emission spectra had been also discussed in those days, it was regarded as a first order optical process, i.e. neither resonant nor normal X-ray emission processes.
Subsequently to their celebrated work, Kotani and Toyozawa (KT) dealt with core level spectra of metals with incomplete shells [16]. They added a localized orbital \( f \) to the MHD model,

\[
H_{\text{KT}} = \sum_k \epsilon_k a_k^\dagger a_k + \epsilon_f f^\dagger f + \epsilon_c (1 - n_c) - U_{fc} f^\dagger f n_c + \frac{V}{\sqrt{N}} \sum_k \left( a_k^\dagger f + \text{H.c.} \right),
\]  

(1.4)

with which they explained a satellite structure of La 3d-XPS of La metal [17]. Figure 1.3 schematically shows their theory. In the ground (initial) state, La metal takes a \( f^0 \) configuration because the energy of La 4\( f \) level \( \epsilon_f \) is high enough from the Fermi energy \( \epsilon_F \). In the final state, however, the strong core hole potential \( U_{fc} \) pulls down the 4\( f \) level, so that “well-screened” 4\( f^1 \) and “poorly-screened” 4\( f^0 \) states are realized. The former involves the infinite number of electron-hole pairs near the Fermi level to exhibit a divergent line shape at the threshold. The \( f^0 \) state can be regarded as a virtual bound state occupied by a conduction electron, with a Lorentzian-broadened line shape. The KT theory is the first recognition that dynamic screening processes due to the local perturbation give rise to the variety of line shapes of core-level spectra, and in this sense it opened a door to the modern theory of CLS.

From a viewpoint of theoretical physics, the KT theory can be regarded as an epitaph on the ND theory, one of the most brilliant theories in the 1960s. Their framework has provided some topics ever since, such as a renormalization group study on the KT model [18] and a revisit of the ND theory in the context of Tomonaga-Luttinger theory [19].

The next remarkable development in CLS was done by Gunnarson and Schönhammer (GS) in 1983 [20]. They applied the KT model to valence-fluctuated systems. For CePd\(_3\) or CeO\(_2\), the 4\( f \) occupation number in the ground state takes a given value from 0 to 1 in contrast to the La metal, where the 4\( f^0 \) weight is predominant in the ground state. If one goes along the KT theory, it is expected that three peaks with mainly 4\( f^0 \), 4\( f^1 \) and 4\( f^2 \) configurations are observed in Ce 3d-XPS spectra. As will
be explained in § 1.4.1, GS extended the KT model to include the degeneracy of 4f orbital and the Coulomb interaction between 4f electrons, and showed a systematic way to calculate XAS, XPS and BIS. One can say that GS led the KT theory to its complete form within the impurity problem. The GS model is now referred to also as impurity Anderson model. We will use the word “impurity model” for the GS-type model hereafter.

1.1.3 Mott-Hubbard vs charge-transfer insulator

It is not surprising that the direction of studies on CLS turned toward application to material science after the establishment of the basic concept. This trend was motivated by successful works on the classification of insulators such as NiO by Fujimori-Minami [21] and Zaanen-Sawatzky-Allen (ZSA) [22].

Ti₂O₃, V₂O₃, NiO, etc. have been well-known insulators, where the Coulomb interaction $U_{dd}$ plays an essential role [23]. In fact, they would be metals according to the simple band theory if $U_{dd}$ were missing. Prior to the works by Fujimori-Minami and ZSA, the lowest charge excitation in these compounds were believed to be made by an inter-site $d$-$d$ charge transfer:

$$(d^n)_i(d^n)_j \rightarrow (d^{n-1})_i(d^{n+1})_j,$$

where $n$ is the nominal occupation number of a material considered, $i$ and $j$ label transition metal sites. This process gives a charge gap of order of $U_{dd}$, and this type of insulators have been called a Mott-Hubbard (MH) insulator after pioneer works by Mott [24] and their mathematical sophistication by Hubbard [25].

Using a NiO$_6$ octahedral cluster model, Fujimori-Minami discussed photoemission spectra of NiO, and they concluded from their calculation that the charge gap is realized by a transition to a metal 3$d$ site from its surrounding oxygen 2$p$ orbitals. They estimated the value of $\Delta_I = 4.0$ and $U_{dd} = 7.5$ for NiO, where charge-transfer (CT) energy $\Delta_I$ is defined by the energy difference

$$\Delta_I \equiv E(d^{n+1}L) - E(d^n),$$

(1.5)

where $L$ stands for a ligand hole $^2$. ZSA, on the other hand, performed systematic estimation of charge gaps in transition metal compounds with the GS theory. They classified the insulators into three groups according to relative value between $\Delta_I$ and $U_{dd}$: MH type, CT type and their intermediate type. Standing on their classification, one can regard NiO as a CT insulator because of $U_{dd} > \Delta_I$.

In this connection, a while after their works, Uozumi performed extensive calculations on 2$p$-XPS of M$_2$O$_3$-type transition metal oxides with a MO$_6$ cluster model for $M$=Ti, V, Cr, Mn and Fe including full multiplet [26, 27]. While he obtained parameter values that $\Delta_I > U_{dd}$ for Ti and V, and $\Delta_I < U_{dd}$ for others, he concluded that Ti, V, Cr and Mn sesquioxides should be classified into the intermediate type insulator because of large values of metal-ligand hybridization. His results are summarized in Fig. 1.4. This conclusion was supported by Bocquet et al., who also discussed 2$p$-XPS for various transition metal oxides [28]. These studies are representative of application of CLS to investigation of electronic structure for strongly-correlated insulators. The site-selectivity encourages us to use the impurity models for a quantitative analysis of core-level spectra. While CLS’s need additional parameters such as core-valence interaction, it is possible to estimate them to satisfactory accuracy with the standard atomic Hartree-Fock procedure [26, 27]. With contemporary numerical diagonalization techniques

$^2$One should average over all irreducible representations to evaluate the energy.
and new generation synchrotron radiation sources, a comparative study of this kind between theory and experiment in CLS has established reputation of being one of the most reliable tools to investigate correlated systems.

Figure 1.4: The ZSA diagram by Uozumi et al. [27]. Ti$_2$O$_3$, V$_2$O$_3$, Cr$_2$O$_3$ and Mn$_2$O$_3$ are located in the intermediate region between CT- and MH-insulators, whereas Fe$_2$O$_3$ is classified as a CT-type insulator.

1.1.4 Nonlocal screening

As is the case of the theories of Fujimori-Minami or Uozumi et al., theoretical studies with impurity models are based on an assumption that a broken translational symmetry calculation is, as far as transition metal ions are considered, a good approximation for transition metal compounds. An exact calculation in principle should include also the translational symmetry of the transition metal ions. Since $d$-band dispersion width have been believed to be usually very small compared to $U_{dd}$ or $\Delta_I$, it has been expected that neglect of this would only cause small errors in calculated insulating gaps, and would not change the physics unless perhaps if the gaps also turn out to be very small [22].

The discovery of high-$T_c$ compounds [29], however, provided a new viewpoint on this assumption, and thus on interpretation of core-level spectra. The traditional BCS theory states that Cooper pair creation at the Fermi surface gives rise to superconductivity [30]. The high-$T_c$ superconductivity is, however, caused by carrier doping into an insulating phase. In the insulating parent compounds such as La$_2$CuO$_4$, the stoichiometry leads to a $d^0$ configuration for Cu$^{2+}$ ions. Since these compounds with such incomplete filled $d$ band would be metals if strong $U_{dd}$ were absent, it is clear that the Coulomb correlation prevents the motion of electrons. There is a consensus that the parent compounds are located in the CT regime. Upon doping, by replacing a few percent of La with Sr in the case of La$_2$CuO$_4$ for instance, a dopant hole mainly goes into the O 2$p$ orbitals, keeping away from energetically unfavorable $d^8$ configuration. Experimental evidence of this negligible $d^8$ weight was given by valence PES results by Fujimori et al. [31] and other groups [32]. Subsequently, experimental studies on O 1$s$-XAS [33] and Cu 2$p$-XAS [34, 35] conclusively demonstrated their conclusion, making full use of the advantages of
CLS such as the site-selectivity and dipole-selectivity. These are also worth referring to as an example for application of CLS to material science.

The high-$T_c$ systems were impressive for the fresh interplay between localized (insulating) and itinerant (superconducting) natures. Analogous to these systems, it was natural for van Veenendaal and co-workers to anticipate doping dependence on Ni $2p$-XPS of $M_xNi_{1-x}O$ ($M$=Li, Na). Extending the NiO$_6$ cluster model of Fujimori-Minami to include a “reservoir” Ni, they showed that a description beyond an atomic multiplet calculation is required [36]. Subsequently, they discussed influence of superexchange interaction [37, 38] on isotropic Ni $2p$-XAS in NiO [39] with the reservoir model, and reported that spin-spin correlation has a direct effect on the spectra [40]. Encouraged by these results, they performed a calculation on Ni $2p$-XPS of NiO with a Ni$_7$O$_{36}$ cluster model, where only $3d$ $e_g$ orbitals and the $\sigma$-bonding O $2p$ orbitals are taken into account [41]. Thereby they pointed out that an experimentally observed shoulder structure in the main manifold of $2p$-XPS originates from a CT screening process from a neighboring NiO$_6$ unit, not only from the oxygen orbitals adjacent to the photoexcited Ni site. This is the first discovery of nonlocal screening effects.

Their results are shown in Fig. 1.5 in comparison with a result with NiO$_6$ cluster, where three peaks mainly due to $\xi 3d^9 L$, $\xi 3d^8$ and $\xi 3d^{10} L^2$ weight are observed (left figure). $\xi$ and $L$ represent a hole at a core orbital and a ligand orbital, respectively. In the right figure, the curve (b) exhibits a clear shoulder structure beside the main peak at zero. This is the contribution of the nonlocal screening.

More surprisingly, they disclosed that the main peak of Cu $2p$-XPS of CuO and high-$T_c$ cuprates also originates from a nonlocal screening process, where a hole is pushed out by a strong intra-atomic Cu $2p$-$3d$ interaction into the neighboring CuO$_4$ units to form a Zhang-Rice singlet [43]. The calculated curve in Fig. 1.5 (c) shows their result, where the main peak at zero is the Zhang-Rice singlet peak. The shoulder at about 2 eV and the satellite at about 9 eV are attributed to contributions mainly of $\xi 3d^{10} L$ and $\xi 3d^9$, respectively. These two peaks have been known from analysis based on impurity models.

Do these striking results mean that all theoretical studies on CLS to date based on the impurity models should be thrown away? The clear answer has not been known so far. Although a systematic study on CLS of transition metal compounds with such “large”-cluster models beyond the impurity limit is clearly desirable, the limitation of memory size of computers prevents us from investigation with realistic models. In fact, the inclusion of orbital degeneracy in a multi-metal-ion cluster is extremely difficult within exact diagonalization methods. To the author’s knowledge, the only attempt is a full-multiplet calculation of valence spectra with a Cu$_3$O$_{10}$ cluster by Tanaka and Jo [44]. This kind of calculation for $d^n$ materials with $2 \leq n \leq 8$ is far from the ability of the present supercomputers. Now clear that a model study to grasp the essential physics is needed.

At least for metal $2p$-XPS of NiO and high-$T_c$ cuprates, the reason why the nonlocal screening effect plays the severe role is that each material has a specific stabilization mechanism such as the Zhang-Rice singlet formation in cuprates. In this respect, van Veenendaal et al. demonstrated in their analysis on Ni $2p$-XPS [41] that the doubly-peaked structure disappears when raising the $d$ orbital energies on sites other than the photoexcited Ni atom, because of the absence of $d$ orbitals in the valence band region. The strong nonlocal contribution on $2p$-XPS in NiO and CuO or high-$T_c$ cuprates may be related to their character as a typical CT-type insulator [45].
Figure 1.5: The discovery of nonlocal screening effect in Ni 2p-XPS of NiO and cuprates [41]. Left: Calculated Ni 2p-XPS spectrum with a NiO$_6$ cluster model as described in the inset. Right: (a) Experimental spectrum of Ni 2p-XPS [42]. (b) Calculated Ni 2p-XPS spectrum with a Ni$_7$O$_{36}$ cluster model as described in the inset. (c) Calculated Cu 2p-XPS spectrum of a Cu$_3$O$_{10}$ cluster model as described in the inset.
1.1.5 A new aspect of nonlocal effects

Recent development of synchrotron radiation sources shed a light on nonlocal effects of CLS from another side. As explained, RXES, whose experimental resolution was drastically improved with such high-brilliance light sources, has the remarkable feature that it reflects local as well as itinerant natures of electronic systems. Thus, it is expected that nonlocal effects emerge in a specific manner different from XAS or XPS. Recent experiments on metal 3d-2p RXES of transition metal oxides clearly suggest this sign. Tezuka et al. first reported strange excitation energy (Ω) dependence of RXES spectra in a d0 compound TiO2 [46]. Figure 1.6 shows Ti 3d-2p RXES of a d0 compound FeTiO3 measured by Butorin et al. [47], exhibiting a similar feature to that of TiO2. We see that there is a broad spectrum at about 450 eV for nearly all Ω as if emitted photon energy (ω) had little dependence on Ω. We call these spectra fluorescence-like component hereafter. On the other hand, there are observed Ω-dependent spectra which move nearly in parallel to Ω, keeping their energy distance from the elastic line constant. If we arrange the same spectra with Raman shift, which is defined by ω − Ω, they will stand in a line at a value of Raman shift. Hence, we call them simply Raman component hereafter. This double-component feature in metal 3d-2p RXES is observed in various transition metal oxides [48] in addition to these compounds.

Figure 1.6: Experimental XAS, NXES and RXES spectra of FeTiO3 [47]. The arrows attached to the XAS spectrum indicate the excitation energy. The NXES spectrum is at the top of the array of RXES spectra for excitation energy well above the absorption threshold (490.0 eV). A small but relatively sharp peak at the highest emitted photon energy in each of excitation energy is the elastic line. The fluorescence-like spectra are clearly observed.
The fluorescence-like spectra are not understandable from a viewpoint of impurity models. XAS and XPS spectra of TiO$_2$ are extremely well reproduced with a TiO$_6$ cluster model [49]. Thus it is expected that a dominant class of intermediate state when $\Omega$ is tuned at the absorption threshold is fairly localized in a photoexcited TiO$_6$ unit, and that final states left after an X-ray emission process from these intermediate states should be described within local CT excitations, being strongly dependent on the well- or poorly-screened natures of the intermediate states. In other words, the intermediate state keeps full memory of the incident X-ray, and the corresponding final state should depend on $\Omega$ accordingly. Since energy scale of local CT excitations is determined by $\Delta_I$ or $V_{\text{eff}}$ (see § 1.4), which has the value of order of at most 10 eV, the energy conservation rule

$$\omega = E_g - E_f + \Omega$$

never predicts the fluorescence-like spectra over whole range of the absorption threshold, $E_g$ and $E_f$ being electronic energies of the ground state and a final state, respectively. It rather predicts only the existence of the Raman component.

The fluorescence-like spectra suggest a dynamical dissipation process of the photoexcited electron, which results in loss of the memory of the photoexcited site. If the dissipation from the photoexcited site to the surrounding reservoir system completely occurs in the intermediate state, an X-ray emission process necessarily resembles NXES, resulting in the fluorescence-like spectra. Hence, we consider the double-component spectra to be a direct consequence of interplay between local and itinerant excitations of an electronic system. This is a new kind of nonlocal effect in CLS, which might bring about a new understanding as to the local-itinerant duality of 3d systems. Together with the “traditional” nonlocal effect van Veenendaal et al. have demonstrated, the main theme of this thesis is to study how the nonlocal effects appear in RXES spectra.

1.2 Resonant Scattering

1.2.1 Quantum theory of radiation

The classical radiation field is governed by the following reduced Maxwell equations for the vector potential $A$ under the radiation (Coulomb) gauge [50]:

$$\left( \nabla \cdot \nabla - \frac{1}{c^2} \frac{\partial^2}{\partial t^2} \right) A = 0$$

$$\nabla \cdot A = 0.$$ (1.6)

We adopt the MKSA rationalized unit throughout this section. The magnetic field $B$ and electronic field $E$ are derived from $A$:

$$B = \nabla \times A$$

$$E = \frac{\partial A}{\partial t}. \quad (1.8)$$

$$E = \frac{\partial A}{\partial t}.$$ (1.9)

Multiplying Eq. (1.6) by $\partial A/\partial t$, we have

$$\frac{1}{2} \frac{\partial}{\partial t} \left[ \frac{1}{c^2} \left( \frac{\partial A}{\partial t} \right)^2 + (\nabla \times A)^2 \right] = \nabla \cdot \left[ \frac{\partial A}{\partial t} \times (\nabla \times A) \right]. \quad (1.10)$$
where the transversality condition Eq. (1.7) and mathematical identities that
\[
\nabla \times (\nabla \times A) = \nabla (\nabla \cdot A) - (\nabla \nabla) A
\]
and
\[
\nabla \cdot \left[ (\nabla \times A) \times \frac{\partial A}{\partial t} \right] = \frac{\partial A}{\partial t} \cdot [\nabla \times (\nabla \times A)] - (\nabla \nabla) \cdot \left( \nabla \times A \right)
\]
have been used. The right side of Eq. (1.10) vanishes according to the Gauss’ divergence theorem when integrated over the total volume, so that
\[
H_t = \frac{1}{2} \int d^3x \left( \varepsilon_0 E^2 + \frac{1}{\mu_0} B^2 \right)
\]
is a time-independent constant. \(\mu_0\) and \(\varepsilon_0\) are the magnetic permeability and dielectric constant of the vacuum, respectively. The integrand of the above equation has the unit of energy density, because the units of \(E\) and \(\varepsilon_0\) are \([NC^{-1}]\) and \([C^2Nm^{-2}]\), respectively. Hence, one can interpret \(H_t\) as the total energy function of the radiation field.

The quadratic form in Eq. (1.11) suggests Fourier decomposition as
\[
A(x,t) = \frac{1}{2\sqrt{\nu}} \sum_{q \neq 0} \varepsilon \left[ a_q^\dagger \varepsilon(q) e^{i\varphi X} + a_q \varepsilon(q) e^{-i\varphi X} \right],
\]
from which we have
\[
E(x,t) = -\frac{1}{2\sqrt{\nu}} \sum_{q \neq 0} \varepsilon \left[ a_q^\dagger \varepsilon(q) e^{i\varphi X} + a_q \varepsilon(q) e^{-i\varphi X} \right]
\]
\[
B(x,t) = \frac{1}{2\sqrt{\nu}} \sum_{q \neq 0} i e^X \cdot q \left[ a_q^\dagger \varepsilon(q) e^{i\varphi X} - a_q \varepsilon(q) e^{-i\varphi X} \right].
\]
The polarization vector \(\varepsilon\) is restricted within the plane perpendicular to \(q\) according to the transversality condition. Each Fourier component satisfies the condition \(a_{-q} \varepsilon = a_q \varepsilon\). By substituting with them, Eq. (1.11) reads
\[
H_t = \frac{\varepsilon_0}{2} \sum_{q \neq 0} \left( \dot{a}_{-q} \varepsilon \dot{a}_q \varepsilon + c^2 q^2 a_{-q} \varepsilon a_q \varepsilon \right)
\]
after some algebra. In the free radiation field, this function is regarded as the Langrangian \(\mathcal{L}\) for canonical coordinates \(\{a_q \varepsilon\}\). Following the standard procedure in classical mechanics [51], we define canonical momentum \(p_{q \varepsilon}\) as
\[
p_{q \varepsilon} \equiv \frac{\partial \mathcal{L}}{\partial \dot{a}_{q \varepsilon}} = \frac{1}{2} \varepsilon_0 \dot{a}_{-q \varepsilon}.
\]

Now we introduce quantized canonical variables by postulating quantization conditions
\[
[a_{-q \varepsilon}, p_{q \varepsilon'}] = i \hbar \delta_{q q'} \delta_{\varepsilon \varepsilon'}
\]
\[
[a_{q \varepsilon}, a_{q' \varepsilon'}] = [p_{q \varepsilon}, p_{q' \varepsilon'}] = 0,
\]
where square brackets represent the commutator, and the deltas represent the Kronecker’s delta functions. Additional conditions \(a_{q \varepsilon}^\dagger = a_{-q \varepsilon}\) and \(p_{q \varepsilon} = p_{-q \varepsilon}\) are naturally assumed. In addition, we introduce the Bose operators as
\[
b_{q \varepsilon}^\dagger = \sqrt{\frac{\varepsilon_0 \omega_q}{2\hbar}} a_{q \varepsilon} + i \sqrt{\frac{2}{\varepsilon_0 \omega_q \hbar}} p_{q \varepsilon},
\]
where \(\omega_q = \sqrt{q^2 c^2 + \varepsilon_0 \omega_0}\).
so that the classical Hamiltonian $\mathcal{H}(\{a_q, e, p_q, e\})$ is associated with quantum mechanical Hamiltonian $H_c$,

$$H_c = \sum_{q, \epsilon} \hbar \omega q b_{q, \epsilon}^\dagger b_{q, \epsilon},$$

(1.16)

where we denote $c|q|$ by $\omega q$. Equation (1.16) encourages us to interpret the Bose operator $b_{q, \epsilon}^\dagger$ as the creation operator of a photon with the polarization vector $\epsilon$ and wave number vector $q$. After all, $A$ is quantized in terms of the boson operators as

$$A(x) = \sqrt{\frac{\hbar}{2e_0\omega q}} \sum_{q, \epsilon} \epsilon \left( b_{q, \epsilon}^\dagger e^{iq \cdot x} + b_{q, \epsilon} e^{-iq \cdot x} \right).$$

(1.17)

### 1.2.2 Electron-photon interaction

The electron-photon interaction is given by [52]

$$H_{ep} = \int d^3x \Psi(x)^\dagger \left[ \frac{e}{m_e} A(-i\hbar \nabla) \right] \Psi(x),$$

(1.18)

where $\Psi(x)^\dagger$ represents the creation operator of the electron field at $x$. The charge and mass of an electron are represented as $e$ and $m_e$, respectively. We postulate that $\Psi(x)^\dagger$ and $\Psi(x)$ obey the anticommutation relations (quantization condition)

$$\{\Psi(x), \Psi(x')^\dagger\} = \delta^3(x-x')$$

$$\{\Psi(x), \Psi(x')\} = \{\Psi(x)^\dagger, \Psi(x')^\dagger\} = 0,$$

where $\delta^3(x-x')$ is the three-dimensional version of Dirac’s delta function. Since we are only interested in physics near absorption edges, the Thomson term $(eA)^2/2m_e$ is omitted from Eq. (1.18). In XAS and RXES, one can usually assign principal and angular quantum numbers of core and valence orbitals by tuning the excitation energy $\Omega$ at the appropriate absorption edge $^3$.

Now $\Psi(x)^\dagger$ is expanded as

$$\Psi(x)^\dagger = \sum_{R, \sigma} \left[ \sum_m \phi_m(x-R)^x l_{R, m, \sigma}^1 + \sum_{m_c} \psi_{m_c}(x-R)^x c_{R, m_c, \sigma}^1 \right],$$

(1.19)

where $\phi_m$ and $\psi_{m_c}$ are Wannier functions with atomic quantum numbers of $(n,l,m)$ and $(n_c, l_c, m_c)$, respectively. $l_{R, m, \sigma}^1$ creates a valence electron with $\sigma$-component of spin at $R$ site, and $c_{R, m_c, \sigma}^1$ is the same operator for the core electrons. Substituting the above equation and Eq. (1.17) into Eq. (1.18), $H_{ep}$ is expressed as the summation of the following operators

$$T_a = \frac{1}{\sqrt{N}} \sum_R e^{iq_1 \cdot R} T^a_\epsilon(R)$$

(1.20)

$$T_c = \frac{1}{\sqrt{N}} \sum_R e^{-iq_2 \cdot R} T^c_\epsilon(R),$$

(1.21)

where $N$ is the number of the unit cell of the electronic system, and

$$T^a_\epsilon(R) = \sum_{m, m_c} \sqrt{\frac{\hbar e^2}{2e_0\omega m^2 \omega q_1}} (n l m | e^{-iq_1 \cdot x} \epsilon | p | n_c l_c m_c \rangle l_{R, m, \sigma}^1 c_{R, m_c, \sigma}^1$$

(1.22)

$$T^c_\epsilon(R) = \sum_{m, m_c} \sqrt{\frac{\hbar e^2}{2e_0\omega m^2 \omega q_2}} (n_c l_c m_c | e^{iq_2 \cdot x} \epsilon' | p | n l m \rangle c_{R, m_c, \sigma}^1 l_{R, m, \sigma}^1.$$  

(1.23)

$^3$We can easily extend the theory when a few orbitals with different angular momentum participate in the transition.
Here we dropped the photon operators, assuming that a photon with \((q_1, \varepsilon)\) is absorbed into the electronic system, and a photon with \((q_2, \varepsilon')\) is emitted from the electronic system. The volume of the unit cell. Obviously, \(T_a\) and \(T_e\) describes X-ray absorption and emission processes, respectively. The factor before the Fermi operators is defined as

\[
(nlm|e^{-iq_1 \cdot \mathbf{x}} \varepsilon \cdot p| n', l, m_c) = \int d^3 x \phi_m(x)^* e^{-iq_1 \cdot \mathbf{x}} \varepsilon \cdot (-i\hbar \nabla) \psi_{m_c}(x).
\] (1.24)

In the hard X-ray regime, the wavelength of photon is of order of 1 Å, and is comparable to lattice constants of a crystal in consideration. Hence one must not neglect the exponential factor in Eqs. (1.20) and (1.21). The spatial extent of the core orbital, however, is expected to be much smaller than the lattice constants, so that we approximate the above equation as

\[
(nlm|\varepsilon \cdot p| n', l, m_c) \simeq \int d^3 x \phi_m(x)^* \varepsilon \cdot (-i\hbar \nabla) \psi_{m_c}(x).
\] (1.25)

This is the nontrivial lowest approximation of the integral, and we refer to it as atomic dipole approximation \(^4\). Note that \(T_a\) and \(T_e\) in Eqs. (1.20) and (1.21) become the form of Fourier summation of the atomic operators.

### 1.2.3 Perturbation Theory

Consider a direct product of the electronic ground state \(|g\rangle\) by a one-photon state \(|q_1 \varepsilon\rangle\), and Hilbert space spanned by such states \(|g; q_1 \varepsilon\rangle\). The transition amplitude from \(|I\rangle \equiv |g; q_1 \varepsilon\rangle\) to a final state \(|F\rangle \equiv |f; q_2 \varepsilon'\rangle\) is given by the \(S\)-matrix \(^5\) as

\[
S_{FI} \equiv \langle F| U_i(\infty, -\infty)| I \rangle,
\]

where \(U_i(t, t')\) is the time-evolution operator of the whole electron-photon system from time \(t'\) to \(t\) in the interaction representation \(^5\). The total Hamiltonian is given by

\[
H_{\text{tot}} = H + H_e + (H_{\text{ep}} + H_A),
\] (1.26)

where \(H_A\) represents an electronic Hamiltonian of the Auger process containing the terms like Eq. (1.1). \(H\) is the Hamiltonian of the electronic system other than \(H_A\). We denote \(H_{\text{ep}} + H_A\) by \(H'\) for a while. Apart from the case of \(F = I\), the \(S\)-matrix is directly reduced to \(^5\)

\[
S_{FI} = -2\pi i \langle F| H' U_i(0, -\infty)| I \rangle \delta(E_F - E_I),
\]

from which the transition probability per time is obtained,

\[
w_{FI} = \frac{2\pi}{\hbar} |\langle F| H' U_i(0, -\infty)| I \rangle|^2 \delta(E_F - E_I).
\] (1.27)

We here introduce the \(T\)-matrix as

\[
\langle F| H' U_i(0, -\infty)| I \rangle = \langle F| T | I \rangle.
\]

\(^4\)The quadrupole transition is experimentally observed, for example, as a prepeak in \(K\)-XAS of transition metal oxides \(^5\), where the intensity ratio of dipole and quadrupole transition is of order of 100.
The standard Lippman-Schwinger theory shows that the $T$-operator obeys equations such that

$$T = H' + H'GH'$$  \hspace{1cm} (1.28)

$$G = G_0 + G_0H'G,$$  \hspace{1cm} (1.29)

where $G$ and $G_0$ are resolvent operators which are defined as $(E_I - H_{tot} + i0)^{-1}$ and $(E_I - H + i0)^{-1}$, respectively. Counting the number of states within a region $d^3q_2$, and dividing Eq. (1.27) by the incident flux $c/V$, we have differential cross section as

$$\sigma(F;I) = \left( \frac{Vq_2}{2\pi\hbar} \right)^2 \left| \langle F|T|I \rangle \right|^2$$  \hspace{1cm} (1.30)

for a transition from $I$ to $F$ such that $E_F = E_I$.

Now we proceed to a perturbation theory with respect to $H'$. In general, electron-photon interaction is much weaker than interaction among electrons. Hence we are allowed to evaluate the $T$-matrix within the second order of $H_{ep}$ for RXES, whereas electron-electron interaction should be taken to the infinite order. Let us consider the contribution of the Auger effect in the context of perturbation theory. To the second order of $H_{ep}$, we have

$$\langle F|T|I \rangle = \langle F|H_{ep}\tilde{G}H_{ep}|I \rangle,$$  \hspace{1cm} (1.31)

where $\tilde{G}$ satisfies

$$\tilde{G} = G_0 + G_0H\tilde{G} + G_0H\tilde{G}H\tilde{G}.$$  \hspace{1cm} (1.32)

This is nothing but Eq. (1.29) in the $H_{ep} \to 0$ limit. Note that the first term of Eq. (1.28) is not contribute to the $T$-matrix, and that $H\tilde{G}|F\rangle = H\tilde{G}|I\rangle = 0$, because both $F$ and $I$ have no core hole to decay.

Exact evaluation of Eq. (1.31) is generally a tough task. To avoid mathematical complications, we introduce Feynman diagrams to represent the series of the $T$-matrix in Fig. 1.7. If we project out high energy transient states that have Auger electrons more than one, only diagrams (b), (c), ... contribute to give a renormalized intermediate state. Assuming

$$\langle r|H\tilde{G}|r' \rangle = \langle r|H\tilde{G}|r \rangle \delta_{r,r'}$$

for simplicity, where $|r\rangle$ and $|r'\rangle$ are some states with a core hole and no photon, we have

$$\langle r|\tilde{G}|r \rangle = \frac{1}{E_I - E_r + i0} \left[ 1 + \langle r|H\tilde{G}|r \rangle \langle r|\tilde{G}|r \rangle \right]$$  \hspace{1cm} (1.33)

from Eq. (1.32), resulting in

$$\langle r|\tilde{G}|r \rangle = \frac{1}{E_I - E_r - \langle r|H\tilde{G}|r \rangle}.$$  \hspace{1cm} (1.34)

Corresponding to the “open oyster” diagram [59] in Fig. 1.7 (b) or (c), we have “proper” self-energy [60] due to the Auger effect as

$$\Sigma_A(r) = \langle r|H_A\tilde{G}H_A|r \rangle$$

$$= \sum_m \frac{\langle m|H_A|r \rangle^2}{E_I - E_m + i0}$$

$$= \varphi \sum_m \frac{\langle m|H_A|r \rangle^2}{E_I - E_m} - i\pi \sum_m \langle m|H_A|r \rangle^2 \delta(E_I - E_m)$$  \hspace{1cm} (1.35)

as depicted in Fig. 1.7 (d). $\varphi$ denotes Cauchy’s principal value.
Figure 1.7: Feynman diagrams of the $T$-matrix expansion. The solid and wavy lines represent the propagation of electronic and photon states, respectively. (a) The ground state $|g\rangle$ absorbs a photon with a wave vector $q_1$, then the intermediate state emits a photon with a wave vector $q_2$, resulting in a final state $|f\rangle$. (b) The same as (a), but an Auger electron “A” is created once in the intermediate state. (c) The same as (a), but an Auger electron is created twice in the intermediate state. The transient states with two Auger electrons are out of the summation. (d) The Auger effect renormalizes the intermediate state.
Although the energy and $r$-dependence of the imaginary part of $\Sigma^\star_A(r)$ considerably contributes to relatively shallow core level photoemission spectra, for example Ni 3$p$-XPS of NiCl$_2$ [61] or 4$d$-XPS of heavy rare-earth elements [62], we take it as a given constant $\Gamma$ for each system in consideration in this thesis. The real part of $\Sigma^\star_A(r)$ is regarded to have been included in observed energies. Together with Eq. (1.30), we have

$$\sigma(F; l) = \left( \frac{V_{q_2}}{2\pi e} \right)^2 \frac{1}{(E_l - H + \text{i}\Gamma)} \left| \langle F | H_{ep} | E_l \rangle \right|^2,$$  

(1.36)

where we have dropped a nonresonant term, which brings about two-photon intermediate states [50].

Substituting the explicit representations of $H_{ep}$ into Eq. (1.36), we reach the final form of the differential cross section of RXES,

$$\sigma(q_2\epsilon'; q_1\epsilon) = r_0^2 \left( \frac{\hbar^2}{m_e} \right) \sum_{R} e^{i q \cdot R} M^{\epsilon'\epsilon}(R),$$

(1.37)

where $q = q_2 - q_1$, and $r_0$ is the classical radius of electron

$$r_0 = \frac{e^2}{4\pi\epsilon_0 m_e c^2} \simeq 2.8 \times 10^{-15} [\text{m}].$$

We assume that the electronic Hamiltonian $H$ is diagonal with respect to the core orbital, i.e.,

$$H_{core} = \sum_{\xi \sigma} \epsilon_{\xi \sigma} c^\dagger_{\xi \sigma} c_{\xi \sigma},$$

(1.38)

and that all the core orbitals are filled in $|g\rangle$. $\xi$ stands for a quantum number of the core orbital. Equation (1.38) means that the core orbitals are localized at each lattice site with no transfer to the neighboring sites, the assumption that would be justified in the soft and hard X-ray excitations. As a result, the nondimensional factor $M^{\epsilon'\epsilon}(R)$ is represented as

$$M^{\epsilon'\epsilon}(R) = \frac{1}{m_e} \sum_{m, m', m_c, \sigma} (n, l, m_c | \epsilon' \cdot p | nlm') (nlm | \epsilon \cdot p | n, l, m_c) \times$$

$$\langle f | e^\dagger_{l', m', \sigma} | \epsilon \cdot p | g \rangle,$$

(1.39)

where $G_0(\Omega)$ is re-defined as $(E_l - H + \text{i}\Gamma)^{-1}$ with $E_l = E_g + \Omega$. We write hereafter the incident and emitted photon energies as $\Omega$ and $\omega$, respectively. The local transition amplitude $M^{\epsilon'\epsilon}(R)$ obviously depends on $\Omega$, although we did not write it explicitly.

### 1.3 Some Aspects on Spectral Functions

#### 1.3.1 Momentum conservation law in RXES

Consider an electronic Hamiltonian with the translational symmetry, i.e.,

$$T_{r}(R)HT_{r}(R)^{-1} = H$$

for any Bravais vector $R$, where $T_{r}(R)$ is the translation operator of the electronic system. Its definition is given by

$$T_{r}(R) \equiv \exp(P \cdot R/\text{i}\hbar),$$

(1.40)
where $P$ is the momentum operator

$$P \equiv \int d^3x \Psi(x) \left( -i\hbar \nabla \right) \Psi(x).$$

For the translational Hamiltonian, $|g\rangle$ and $|f\rangle$ can be simultaneous eigenstates of both $H$ and $T_r$, so that, for $\forall R$, real vectors $K_g$ and $K_f$ exist such that

$$T_r(R)|g\rangle = \exp(K_g \cdot R / i \hbar)|g\rangle$$

(1.41)

$$T_r(R)|f\rangle = \exp(K_f \cdot R / i \hbar)|f\rangle.$$  

(1.42)

With these equations we have

$$\langle f| c_{\epsilon R_m}^\dagger \sigma_{l m} c_{\epsilon R_m'} \sigma_{l m'} G_0(\Omega) \sigma_{l m} c_{\epsilon R_m} \sigma_{l m'} |g\rangle = \langle f| T_r(R) c_{\epsilon R_m}^\dagger \sigma_{l m} G_0(\Omega) c_{\epsilon R_m'} \sigma_{l m'} T_r(R)^{-1} |g\rangle \times \exp \left[ i(K_f - K_g) \cdot R \right],$$

resulting in

$$M_{\epsilon'\epsilon}(R) = M_{\epsilon'\epsilon}(0) \exp \left[ i(K_f - K_g) \cdot R \right].$$

(1.43)

We have just used the fact $[G_0, T_r] = 0$. Now Eq. (1.37) reads

$$\sigma(q q' \epsilon' \epsilon; g q 1 \epsilon) = \frac{N^2 r_0^2}{\frac{\partial q q'}{\partial q 1}} \left| M_{\epsilon'\epsilon}(0) \right|^2 \delta_{q q'} \delta_{K_f K_g},$$

(1.44)

where a well-known relation

$$\frac{1}{N} \sum_R \delta_{k 0} = \delta_{k 0}$$

(1.45)

is used. Equation (1.44) states that the cross section is zero unless $q + K_f = K_g$ is satisfied. This is the wave vector conservation rule of RXES [63]. Equation (1.44) shows an essential aspect of RXES. The origin of this conservation rule is the summation in Eq. (1.37), where the cross section is proportional to a factor quite similar to the definition of the structure factor [64, 65]. If we fixed a core hole to a particular site, the wave vector conservation rule does not hold. This means that the all core orbitals in the system participate in one scattering process, and we can say that the wave vector conservation rule is a result of spatial coherence of the crystal. Intuitively speaking, the electron wave created by a photoexcitation survives without phase cancellation only when it “fits” to the lattice. In the case of first order optical processes such as XAS or XPS, however, we can calculate spectra by fixing the core hole site, as shown later. This feature makes impurity models, which breaks the translational invariance, appropriate to study the first-order spectra, but not the case in RXES.

On the other hand, $M_{\epsilon'\epsilon}(0)$ reflects an internal symmetry of an atom at the origin. In fact, first, it strictly obeys the dipole selection rule for both X-ray absorption and emission processes, as seen from Eq. (1.39). Second, it reflects a spatial direction of orbitals at 0 through the $\epsilon'$- and $\epsilon$-dependence. With these features, RXES should be one of the most useful tools to investigate strongly correlated systems, where interplay between itinerant and localized nature of electrons is realized.

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5We will briefly discuss an additional SU(2) selection rule in spin space in the next chapter.
1.3.2 Elastic-inelastic intensity ratio

We first prove a theorem on the elastic scattering.

**Theorem 1** If \( \varepsilon \cdot \varepsilon' = 0 \), then intensity of the elastic scattering such that \( m=m' \) is zero within the atomic dipole approximation.

Note that the elastic scattering of a system with no electron in the \( l\)-shell always satisfies the condition \( m=m' \). For example, any elastic scattering of 3d-2p RXES of \( d^0 \) compounds or Cu 4p-1s RXES of cuprates is forbidden when \( \varepsilon \cdot \varepsilon'=0 \) according to this theorem. For proof, we define a quantity

\[
I_{\varepsilon'\varepsilon}(m',m) \equiv \langle n,l,m_r|\varepsilon'\cdot p|nlm'\rangle\langle nlm|\varepsilon\cdot p|n,l,m_e\rangle.
\]

(Note that \( I_{\varepsilon'\varepsilon}(m',m) \) strictly obeys Wigner-Eckart’s theorem [66] of SO(3). We take \( \varepsilon=\varepsilon_\uparrow \) for simplicity, where \( \varepsilon_\uparrow \) is the unit vector along \( z\)-axis fixed to the electronic system. Since \( p\cdot\varepsilon_\uparrow=p_z \) is the zero component of spherical tensor operators of rank one, the Wigner-Eckart theorem limits \( m \) to \( m_e \)). However, this condition is never satisfied when \( \varepsilon \cdot \varepsilon'=0 \), because \( \varepsilon'\cdot p \) in this case is 1 or \(-1\) component of the spherical tensor operator. Hence \( I_{\varepsilon'\varepsilon}=0 \) follows in the case that \( m=m' \). The condition \( \varepsilon \cdot \varepsilon'=0 \) is experimentally called “depolarized” configuration.

We see from Eq. (1.44) that the cross section is \( O(N^2) \) (order of \( N^2 \)) as far as \( I_{\varepsilon'\varepsilon} \) and \( M_{\varepsilon'\varepsilon}(0) \) is \( O(1) \). Let us define a nondimensional quantity

\[
J_{m'\sigma}^{m}(0) \equiv \langle f|c_i^\dagger l_{\nu}^{\uparrow}G_0(\Omega)l_{\nu}\sigma c_\nu^\dagger c_\nu\sigma |g\rangle \times \Gamma,
\]

and assume that \( I_{\varepsilon'\varepsilon} \) is \( O(1) \). We first consider a local transition process, which will be realized when \( \Omega \) is tuned at a state bound to the core hole at 0. This contains two cases. One is the elastic scattering process with \( m=m' \), and the other is (inelastic) scattering involving an intra-site excitation such as intra-site \( 2g \rightarrow e_c \) excitation depicted in Fig. 1.8. Since the selected intermediate state should have the hole occupation number of order 1 in the \( l_m \) orbital, and moreover the electron occupation number of order 1 in the \( l_m' \) orbital, \( |J_{m'\sigma}^{m}(0)| \sim O(1) \) obviously holds. We have \( O(N^2) \) scattering intensity in these cases thereby.

As will be explained in § 1.4.4, there are unbound states in the intermediate state even under a strong core hole potential \( U_c \). Utilizing Fourier transformation

\[
I_{k\sigma}^{l} = \frac{1}{\sqrt{N}} \sum_{k'} e^{i k R_{k\sigma}^{l}},
\]

we have another expression of \( J_{m'\sigma}^{m}(0) \) as

\[
J_{m'\sigma}^{m}(0) = \frac{1}{N^2} \sum_{k_1 k_2} \langle f|l_{k_2 m'\sigma}^\dagger l_{k_1 m\sigma}^\dagger G_0(\Omega)l_{k_2 m}^\dagger c_{k_1 m,\sigma} c_{k_1 m,\sigma} |g\rangle \times \Gamma,
\]

where the wave vector conservation and Eq. (1.38) are implicitly assumed. Since the photoexcited electron is considerably delocalized, we are allowed to neglect \( U_c \) in the intermediate state, so that wave number is good quantum number also in the intermediate state. Let us consider an insulator having nearly independent electrons. When the incident photon energy is assigned to make resonance at its absorption edge, \( \Gamma G_0(\Omega) \sim -i \) follows, so that

\[
J_{m'\sigma}^{m}(0) \sim \frac{-i}{N} \sum_{k} \langle f|l_{k m'\sigma}^\dagger l_{k m,\sigma} |g\rangle,
\]

19
where we used the fact that both initial and final states have a filled core band, and we implicitly assume a condition

$$\Gamma \ll W,$$  \hfill (1.48)

where $W$ is a band width of an empty conduction band. For the elastic scattering such that $f=g$ and $m=m'$, the matrix element equals the hole occupation number of $l_m$ orbital in the ground state. Although other orbitals, especially ligand orbitals, strongly contribute to an upper band of the insulator in consideration, the matrix element is still expected to be $O(1)$, resulting in $|J_{m'm}(0)| \sim O(1)$.

For an inelastic scattering, there is one electron in a conduction band and one hole in a valence band in a typical final state, as shown in Fig. 1.8 (right), so that a final state $|f\rangle$ gives a nonzero matrix element for a few of $l_k^m\sigma_k^{m'\sigma}|g\rangle$. Consequently, $|J_{m'm}(0)| \sim O\left(\frac{1}{N}\right)$ for a specific final state of this kind. While this result leads to a cross section of $O(1)$, the $N$ dependence of density of states recovers spectral intensity of $O(N)$. This is because final states of this kind are densely distributed in general in a region $6$. Hence we have $N^2$ intensity for the elastic scattering, whereas $N$ intensity for nonlocally excited inelastic scattering in this case. The ratio of them diverges in the thermodynamic limit $[67, 92]$.

Experimentally, never is observed the divergence. A part of the reason possibly comes from a finite coherent length of X-rays. If an incident photon is incomplete plain wave, the $N \to \infty$ limit is not realistic, and interference between “fragments” of plain wave may occur, resulting in finite elastic intensity. Another possible reason is associated with Eq (1.48). It is evident that the above estimation is forced to make modifications if $\Gamma \sim W$ or $\Gamma$ has term-dependence. At any rate, quantitative estimation of the ratio is extremely difficult $7$. We will not discuss the elastic scattering hereafter.

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6Because of the assumption of insulator, the elastic line is isolated alone.

7Recently, Jiménez-Mier et al. reported an estimation of the ratio within a specific model on 3d-2p RXES of Ti compounds [68]. However, the estimated value sensitively depends in principle on what number of transition paths is taken into consideration. Since they made a drastic approximation that, e.g., the effect of core hole potential is completely disregarded, their statement on the ratio makes little sense.
1.3.3 Other spectral functions

Apart from a prefactor, the spectral function of RXES is now written as

\[ F_{\text{RXES}}(\omega; \Omega) = \frac{1}{N} \sum_f |\sigma(f_q \epsilon'; q g_1 \epsilon)|^2 \delta(E_f + \omega - \epsilon_g - \Omega). \]  

(1.49)

Similarly, the spectral function of XAS is written as

\[ F_{\text{XAS}}(\Omega) = \frac{1}{N} \sum_m R |\langle m(R) | T_g \epsilon(0) | g \rangle|^2 \delta(\Omega - E_m + \epsilon_g), \]  

(1.50)

where \(|m(R)\rangle\) is a final state with a core hole at \(R\). Note the assumption Eq. (1.38). Under this assumption, we can delete the position degrees of freedom of a core hole from \(F_{\text{XAS}}\). Since the core hole site is a good quantum number in the final state of XAS,

\[ \langle m(R) | T_g \epsilon(0) | g \rangle = \langle m(0) | T_g \epsilon(0) | g \rangle e^{-iK_g R}, \]

leading the XAS spectral function to

\[ F_{\text{XAS}}(\Omega) = \sum_m |\langle m(0) | T_g \epsilon(0) | g \rangle|^2 \delta(\Omega - E_m + \epsilon_g). \]  

(1.51)

Let us consider spectral functions of XPS, where a core hole is photoexcited to a high-energy continuum, as explained in § 1.1. Since interaction between the photoelectron and valence electrons is negligible, and the continuum states have nearly all kinds of symmetry, one does not need to handle the photoelectron degrees of freedom explicitly. Apart from a prefactor, we set the transition operator of XPS simply to be

\[ T_p = \sum_R T_p(R) = \sum_{R,m,\sigma} c_{Rm,\sigma}, \]

leading to the XPS spectral function

\[ F_{\text{XPS}}(E_B) = \sum_{\mu} |\langle \mu(0) | T_p(0) | g \rangle|^2 \delta(E_B - E_\mu + \epsilon_g), \]  

(1.52)

where \(E_B\) represents the binding energy, and the \(T_r\) manipulation as explained above has been used.

NXES is the second-order optical process where a core electron is excited by the incident photon to high-energy continuum well above the absorption edge. An energy interval of the continuum levels is so close that the momentum information of the system is hardly maintained through the NXES process. Therefore, final states with any wave number are allowed. This situation is mathematically realized by fixing the core hole site. The spectral function of NXES is then given by

\[ F_{\text{NXES}}(\omega) = \frac{1}{N} \int d\epsilon D(\epsilon) \sum_f |\langle f(T'_g(0) G_{0}(\Omega - \epsilon) T_p(0)) | g \rangle|^2 \times \delta(\omega + E_f + \epsilon - \Omega - \epsilon_g), \]  

(1.53)

where \(D(\epsilon)\) is the density of states of the continuum level \(\epsilon\), and \(G_{0}(\Omega - \epsilon) = (E_g + \Omega - \epsilon - H + i\Gamma)^{-1}\). We will take \(D(\epsilon)\) as a given constant. Because of the integration over \(\epsilon\), the spectral shape of NXES does not depend on \(\Omega\).
1.4 Model Hamiltonians and Their Implications

1.4.1 Impurity Anderson model

The impurity Anderson model which GS proposed for a degenerate 4f system is written as

\begin{equation}
H_{IAM} = \sum_{m,\sigma} (\epsilon_f - U_f n_c) f_{m\sigma}^\dagger f_{m\sigma} + \sum_k (V_k f_{m\sigma}^\dagger a_{k\sigma} + H.c.)
+ U_{ff} \sum_{m \neq m', \sigma, \sigma'} f_{m\sigma}^\dagger f_{m\sigma}^\dagger f_{m'\sigma'} f_{m'\sigma'} + \sum_k \epsilon_k a_{k\sigma}^\dagger a_{k\sigma} + e_c (1 - n_c),
\end{equation}

where \( f_{m\sigma}^\dagger \) creates a 4f electron with an orbital index \( m \) and spin component \( \sigma \), and \( a_{k\sigma}^\dagger \) creates a conduction electron with wave number \( k \) and spin component \( \sigma \). \( \epsilon_f \) and \( \epsilon_c \) are one-electron energies for 4f, conduction electron, and core orbitals, respectively. \( n_c \) is the number of core holes. \( V_k \) is the hybridization strength between 4f and conduction electrons. Note that this model exhibits a permutation symmetry such that \( m \leftrightarrow m' \). Making full use of this fact implicitly, GS introduced a set of states which have the same permutation symmetry as 4f\(^0\) state, and successfully discussed core-level spectra of valence-fluctuated systems, as explained before.

To apply this model to transition metal compounds, one should include the anisotropy of orbitals, which breaks the permutation symmetry. A simplified model in which only the nearest-neighbor ligand orbitals are taken into account is often used. We refer to this model as impurity cluster model, which breaks the permutation symmetry. A simplified model in which only the nearest-neighbor ligand orbitals are taken into account is often used. We refer to this model as impurity cluster model, which breaks the permutation symmetry.

\begin{equation}
H_{ICM} = \sum_{\gamma, \sigma} (\epsilon_{d\gamma} d_{\gamma\sigma}^\dagger d_{\gamma\sigma} + (V_f d_{\gamma\sigma}^\dagger p_{\gamma\sigma} + H.c.)) + e_c \sum_{\xi, \sigma} c_{\xi\sigma}^\dagger c_{\xi\sigma}
+ U_{dd} \sum_{\gamma \neq \gamma', \sigma, \sigma'} d_{\gamma\sigma}^\dagger d_{\gamma'\sigma'}^\dagger d_{\gamma'\sigma'} d_{\gamma\sigma} - U_{dc} \sum_{\gamma, \sigma, \sigma'} d_{\gamma\sigma}^\dagger v_{\sigma\sigma'} c_{\xi\sigma}^\dagger c_{\xi\sigma'},
\end{equation}

where \( \gamma \) runs over irreducible representations around the impurity atom. \( d_{\gamma\sigma}^\dagger \) and \( p_{\gamma\sigma}^\dagger \) are creation operators of a \( d \) orbital and a ligand molecular orbital, respectively. \( c_{\xi\sigma}^\dagger \) is a creation operator of the core orbital with a quantum number \( \xi \). One-electron energies of \( \epsilon_{d\gamma} \) and \( \epsilon_c \) are measured with respect to the one-electron energy of the \( p \) orbitals. In general, multipole part of Coulomb interaction and spin-orbit interaction are added to \( H_{ICM} \) or \( H_{IAM} \). Figure 1.9 shows a schematic picture of \( H_{ICM} \). We note that there is no transfer between different \( \gamma \)'s, and only \( U_{dd} \) couples them.

This model describes at least two excitation modes in RXES spectra:
1. intra-site \( d-d \) excitations (10Dq),
2. CT excitations (\( \Delta \) or \( V_{eff} \)),

where we write representative energy scales for each excitation in the brackets. 10Dq is crystal field splitting, which is the energy difference typically between \( 3d(t_{2g}) \) and \( 3d(t_{2g}) \) orbitals in a crystal of \( O_h \) symmetry. \( V_{eff} \) is the effective hybridization energy between metal and ligand molecular orbitals, and generally has a value of order of \( \sqrt{N_d V_f} \), where \( N_d \) is the number of unoccupied metal orbitals.

An example of intra-site \( d-d \) excitations has been shown in Fig. 1.8. Historically, the first theoretical prediction on the observation of intra-site \( d-d \) excitation with RXES was given by Tanaka and Kotani in 1993 for \( d^9 \) systems [69], which is also nominally \( d^1 \) configuration in the hole picture. It was the first theoretical study of RXES as a second-order optical process in the framework of many-body problem [70]. Very recently, Kuiper et al. measured Cu 3d-3p RXES of \( Sr_2CuO_2Cl_2 \), and observed the intra-site transition of a hole from \( 3d_{x^2-y^2} \) to \( 3d_{xy} \), and to \( 3d_{x^2} \) and \( 3d_{y^2} \) [71]. To distinguish between
Figure 1.9: Schematic diagram of an impurity cluster model for transition metal insulators. The metal 3d orbital and oxygen 2p molecular orbitals are represented with closed and open circles, respectively. The darkly-shaded smaller circle at the center stands for the core orbital. The Coulomb interactions which correlate different symmetry $\gamma$ each other are represented with the shaded area.

3$d_{\text{xy}}$ and 3$d_{\text{yz}}$ (or 3$d_{\text{zx}}$), they made use of the angular dependence of Eq. (1.46). This measurement is regarded as a quantitative experimental confirmation of the Tanaka-Kotani theory.

### 1.4.2 Periodic Anderson model

For systems in which nonlocal screening effects are expected, the relevant start point is the periodic Anderson model

$$H_{\text{PAM}} = H_{\text{core}} + H_{dp} + H_{dc}.$$  

This is the Hamiltonian with which we will investigate core level spectra in this thesis. The first term has already defined in Eq. (1.38). Corresponding to Eq. (1.55), the second and third terms are defined as

$$H_{dp} = \sum_{R,v} E_{dv} d_{vR}^\dagger d_{vR} + \sum_{r,\mu} \epsilon_{pv} p_{\nu r}^\dagger p_{\nu r} + \sum_{(r',\nu',\mu',\nu)} \left( T_{pp} p_{\nu r}^\dagger p_{\mu' r'} + \text{H.c.} \right)$$

$$+ \sum_{(r,\nu,\mu)} \left( T_{pd} d_{vR}^\dagger p_{\nu r} + \text{H.c.} \right) + U_{dd} \sum_{R,v,v'} d_{vR}^\dagger d_{vR} d_{v' R}^\dagger d_{v' R}$$  

(1.56)

$$H_{dc} = -U_{dc} \sum_{R,v,\xi,\xi'} d_{vR}^\dagger d_{vR} c_{\xi R}^\dagger c_{\xi' R}^\dagger$$  

(1.57)

where $d_{vR}^\dagger$ represents a creation operator of a $d$ carrier with a quantum number $v$ at $R$ site. Similarly, $p_{\nu r}^\dagger$ creates a $p$ carrier with $(r,\nu)$, and $c_{\xi R}^\dagger$ a creation operator of a core hole with $(R,\xi)$. We denote spin and orbital quantum numbers together by Greek indices $\nu$, $\mu$ and $\xi$. $U_{dd}$ and $U_{dc}$ are on-site Coulomb interaction for $d$-$d$ and $d$-core, respectively. Notice the $d_{vR}^\dagger p_{\nu r}$ term, where orbitals with different local
point group symmetry are no longer decoupled as the case in Eq. (1.55). It makes hard to calculate spectra for systems with an intermediate filling.

This model describes at least four excitation modes. In addition to those of the impurity model,
3. inter-site spin excitations ($J$),
4. inter-site $d$-$d$ excitations ($U_{dd}$),
where $J$ represents the superexchange interaction.

These modes appear in CLS in various phases, depending on filling and excitation process. Let us consider relatively simple cases: $d^0$ and $d^1$ fillings. For the former, valence excitations are mainly dominated by only CT excitations. Recall the fact RXES can strongly reflect charge dynamics due to core hole creation, and that its description would be hard within the impurity models. The relatively simple electronic structure of $d^0$ systems will be rather helpful to elucidate this side of spectra. This is the theme of Chap. 2.

For $d^1$ systems, all the modes are concerned in principle. In fact, we will show that intra- and inter-site $d$-$d$ excitations as well as CT excitations are observed in calculated spectra with specific excitation energy dependence. It is interesting to reproduce interplay between intra- and inter-site effects. This subject will be discussed in Chap. 3. For the dependence of inter-site spin excitations in RXES, few studies have been done so far, and it is left for the future problem.

### 1.4.3 Zhang-Rice singlet

Soon after the spectroscopic methods revealed that dopant holes are primarily on oxygen sites in high-$T_c$ cuprates, Zhang and Rice proposed a picture on the conductivity in the doped cuprates: A dopant hole forms a local singlet on a CuO$_4$ square, then it moves over the whole CuO$_2$ plane [43].

To elucidate their idea, consider a two-hole singlet state, where one hole is localized at a $3d_i$ orbital ($i$ labels a Cu site), and the other is contained in the O 2p molecular orbital around the $3d_i$ site. These orbitals are described in the left figure in Fig. 1.10. The molecular orbital which couples with $3d_i$ orbital is
\[
L_i^{\sigma} = \frac{1}{2} \left( -p_{i+\hat{x}}^{\sigma} + p_{i+\hat{y}}^{\sigma} + p_{i-\hat{x}}^{\sigma} + p_{i-\hat{y}}^{\sigma} \right),
\]
with which we can construct a singlet state
\[
\left| s_i \right> = \frac{1}{\sqrt{2}} \left( d_{i\uparrow}^\dagger L_i^{\downarrow} - d_{i\downarrow}^\dagger L_i^{\uparrow} \right) \left| 0 \right>,
\]
where $\left| 0 \right>$ is the vacuum of holes. Operation of the two-hole spin operator $s^2 = (s_d + s_L)^2$ directly leads to $s^2|s_i\rangle = 0|s_i\rangle$. With rearrangement of a set of Wannier functions, Zhang and Rice derived an effective Hamiltonian, which describes the motion of this kind of singlet state, the Zhang-Rice singlet. Their Hamiltonian is now called the $t$-$J$ model.

It is amusing that the motion of the Zhang-Rice singlet is directly observed in Cu 2p-XPS of undoped cuprates. When an incident X-ray photon comes into the system, the Zhang-Rice singlet is formed with the following procedure: The photo-created core hole acts as a strong repulsive potential to a $3d$ hole at the same plaquette, then the $3d$ hole escapes from the singular plaquette. The slipped hole goes into another plaquette to form the Zhang-Rice singlet there. In contrast to the photo-doping in the case of valence photoemission, we can call this process “potential doping”. This subject will be explored in Chap. 4.
Figure 1.10: Left: Explanation of relative phases between O 2p and Cu 3d\textsubscript{z^2−y^2} orbitals [43]. Right: Schematic picture of the hole-doped CuO\textsubscript{2} plane, where a dopant hole forms the Zhang-Rice singlet at the central plaquette. The open and closed circles represent O 2p and Cu 3d\textsubscript{z^2−y^2} orbitals, respectively. The arrows represent holes.

1.4.4 Core exciton

In this section, we sketch the core exciton theory with an exactly solvable model. The aim is twofold. First, to supply a basis for the estimation of \( N \)-dependence of the RXES cross section under the core hole potential \( U_c \). Second, to give an insight into the core hole effect especially in \( d^0 \) systems.

Let us consider a one-dimensional nondegenerate periodic Anderson model under \( d^0 \) filling in the limit of \( U_{dd}/|\varepsilon_{dv}−\varepsilon_{pu}| \to \infty \) and \( U_{dd}/|T_{pd}| \to \infty \). In this limit, the system is described with a spinless Fermion model without \( U_{dd} \). As far as periodic systems are concerned, the Hamiltonian is decomposed according to wave number \( k \) via Fourier transform (Eq. (1.47)), \( H = \sum_k h_k \). By diagonalizing each \( h_k \), we have a band structure of the system. There are an empty conduction band and a filled valence band in the ground state under \( d^0 \) filling, as well as the filled core band with no energy dispersion, as shown in Fig. 1.8 (right). As a model of the conduction band, we assume a cosine-type one-dimensional band

\[
\varepsilon_k = \eta_0 + 4\gamma \sin^2(k/2)
\]

for the first Brillouin zone \(-\pi < k \leq \pi\) with given energy constants \( \eta_0 \) and \( \gamma \). Our spinless Fermion model is now written as

\[
H = \sum_k \varepsilon_k a_k^\dagger a_k + H_c - U_c \sum_l a_l^\dagger a_l c_l^\dagger c_l,
\]

where \( a_k^\dagger \) creates a conduction electron with wave vector \( k \), \( a_l^\dagger \) and \( c_l^\dagger \) create a conduction electron and a core hole at \( l \) site. \( H_c \) describes the filled valence band. The energy origin is defined with respect to the core level.

Let us consider the X-ray absorption process in this model. As shown in Eq. (1.51), the only core orbital at a site, say, the origin 0 is sufficient to calculate XAS spectrum. Accordingly, the above Hamiltonian is reduced to a MHD type model,

\[
H = \sum_k \varepsilon_k a_k^\dagger a_k + H_c - U_c a_0^\dagger a_0 c_0^\dagger c_0,
\]

(1.59)

25
where $n_{c0}$ is the number of core hole at the origin. Although the transition operator can not be generally written in terms of only $a_k^\dagger$’s, we treat a simplified operator

$$T_a = \sum_i a_i^\dagger c_i = \sum_k a_k^\dagger c_k$$

in place of Eq. (1.20) under the assumption that the polarization vector of the incident photon is parallel to the chain. The second equal sign is due to Fourier transformation. This transition operator creates only one conduction electron in XAS final state ($n_{c}=1$). Hence we can set a $j$-th eigenstate as

$$|\alpha_j\rangle = \sum_k A_{jk} a_k^\dagger |g\rangle$$

without loss of generality. Operating $H$ to this state, we have the Schrödinger equation to determine the coefficients $A_{jk}$ as

$$(\varepsilon_j - \varepsilon_k)A_{jk} = -\frac{U_c}{N} \sum_{k'} A_{jk'},$$

where $N$ is the number of sites. Dividing the both sides by $(\varepsilon_j - \varepsilon_k)$, and summing over $k$, we have the eigen equation

$$\frac{1}{N} \sum_k \frac{1}{\varepsilon_j - \varepsilon_k} = -\frac{1}{U_c},$$

(1.60)

which is transformed into

$$\int_{-\pi}^{\pi} \frac{dk}{2\pi} \frac{1}{\varepsilon_j - \varepsilon_k} = -\frac{1}{U_c}$$

in the thermodynamic limit. For $\varepsilon_j < \eta_0$, an analytic solution is obtained by using the residue theorem,

$$\varepsilon_0 = \eta_0 + 2\gamma - \sqrt{(2\gamma)^2 + U_c^2},$$

where we labeled this solution with $j = 0$. Substituting $\varepsilon_j$ with $\varepsilon_0$, we have an eigenstate as

$$A_{0k} = \frac{1}{\sqrt{N}} \left( \frac{U_c}{\lambda} \right)^{\frac{1}{2}} \left( \frac{U_c}{\lambda - 2\gamma \cos k} \right)^{\frac{1}{2}},$$

where $\lambda = \sqrt{(2\gamma)^2 + U_c^2}$. Note that $A_{0k} \rightarrow \frac{1}{\sqrt{N}}$ in the limit of $2\gamma/U_c \ll 1$, so that Fourier transformation in Eq. (1.47) shows

$$|\alpha_0\rangle \rightarrow a_0^\dagger |g\rangle,$$

(1.61)

i.e. a state bound to the core hole. The bound state $|\alpha_0\rangle$ is called core exciton.

A graphical representation of Eq. (1.60) shows that other eigenvalues which do not satisfy $\varepsilon_j < \eta_0$ are nearly the same as the unperturbed values $\varepsilon_k$, so that an eigenstate with $\varepsilon_j \simeq \varepsilon_k$ has large amplitude only for the $k$.

In summary, the XAS final states are classified into two types. One is the core exciton state, which is fairly localized around the core hole. The others are itinerant states, whose wave functions are quite similar to those of the unperturbed states. As suggested by the formula of Fourier transformation

$$a_k^\dagger = \frac{1}{\sqrt{N}} \sum_l e^{ikl} a_l^\dagger,$$

(1.62)

Each of these states has amplitude of order of $\frac{1}{\sqrt{N}}$ at the core hole site.
Since the X-ray absorption process is the intra-site excitation, the more probability to find a conduction electron at the 0 site we have, the more absorption intensity we observe. Comparing Eq. (1.61) with Eq. (1.62), we can roughly estimate the intensity ratio between the above two states as $1 : \frac{1}{N}$, indicating the concentration of intensity at the exciton state. Figure 1.11 schematically shows the XAS spectrum. The same would be true for a more realistic model, although such analytic solution is possibly hard to obtain. This is the basis of the discussion on the $N$ dependence of the RXES cross section in § 1.3.

![Figure 1.11: Schematic shape of the XAS spectrum. Generally, the continuum has a few sharp peaks due to the van Hove singularity.](image)

### 1.5 Exact Diagonalization Techniques

#### 1.5.1 Lanczos method

Throughout this thesis, the exact diagonalization method is used to calculate the optical spectral functions. As explained, we are interested in dynamical properties in large-cluster models. Other "less exact" numerical approaches such as Quantum Monte Carlo methods [72] are not suitable for extracting dynamical information.

The newly developed technique, the density matrix renormalization group (DMRG) approach [73], is a renormalization-group-like diagonalization method where the basis set is optimized to well reproduce lower excited states as the cluster size is extended. DMRG is now accepted as a standard method to calculate static quantities of one-dimensional systems. Although a few attempts have done to extend DMRG to obtain dynamical correlation functions [74, 75], the exact approach based on Lanczos algorithm is currently the only reliable technique for evaluating the second-order spectral functions in higher dimensional systems involving charge excitations.

The Lanczos algorithm is a procedure to transform a Hermite matrix $H$ into a tridiagonalized matrix $T$ via a unitary transformation

$$T = U^\dagger HU.$$  

[^8]: Very recently, Tanaka developed a DMRG-like approach in a cell-perturbative manner to calculate electron removal spectra of one- or two-dimensional cuprates [76]. It would be possible in principle to extend his method to evaluate spectral functions of the second order processes.
We regard $H$ as the Hamiltonian of a given system, and set the order of $H$ to be $N_H$ ($\sim$ a few million). Since the number of nonzero elements of $H$ is much smaller than $N_H^2$ in many cases, we can make a subroutine in advance that returns $Hu$ for a column vector $u$, using, e.g., JDS method [77].

The Lanczos iterative procedure is as follows: Prepare an arbitrary column vector $u_1$ and $v_1 = Hu_1$. Repeat

\[
\begin{align*}
a_i &= u_i^\dagger v_i \\
w_i &= v_i - a_i u_i \\
b_{i+1} &= \sqrt{w_i^\dagger w_i} \\
u_{i+1} &= w_i / b_{i+1} \\
v_{i+1} &= Hu_{i+1},
\end{align*}
\]

then we have

\[
T = \begin{pmatrix}
a_1 & b_2 & 0 & \cdots \\
b_2 & a_2 & b_3 & \cdots \\
0 & b_3 & a_3 & \cdots \\
\vdots & \vdots & \ddots & \ddots
\end{pmatrix}
\]

and $U = (u_1, u_2, u_3, \cdots)$ [78]. By diagonalizing $T$ to give an eigenvector $x_i$, we have an eigenvector of $H$ as $Ux_i$. The eigenvalues of $T$ and $H$ are exactly the same because $U$ is unitary. Note that the number of iteration $N_i$ is often of order of only 100, much smaller than $N_H$, to obtain the lowest eigenvalue to a given accuracy, say, 0.0001%.

Generally, the limitation of memory size of computers forces us to repeat the whole Lanczos process twice to get the ground state vector $g$. In the first Lanczos process, all of $a_i$ and $b_i$’s but none of $u_i$’s are memorized. Then the tridiagonalized matrix $T$ is diagonalized with the Householder method [79] to give the ground state energy $E_g$ and the corresponding eigenvector $x_0 = (x_0^1, x_0^2, x_0^3, \cdots, x_0^N)^T$, where $T$ represents transposition. Then the second Lanczos process is started again with the same initial vector $u_1$. With $u_i$ in each step, we have the ground state as

\[
g = x_0^1 u_1 + x_0^2 u_2 + \cdots + x_0^N u_N.\]

The Lanczos method is easily extended to obtain a spectral function. Consider to calculate the XPS spectral function. We prepare the ground state vector $u_1 = g$ with the eigenenergy $E_g$. The Lanczos procedure is carried out with a final state Hamiltonian for a given iteration number $N_i$ to give the tridiagonalized matrix $T$. Then $T$ is diagonalized with the Householder method, resulting in a set of eigenvalues and eigenvectors

\[
\{E_i, f_i | i = 1, 2, \cdots, N_i \}\]

To obtain transition amplitude $F_i^\dagger g$ for one of the final states $F_i$, we do not need to explicitly handle the vector $u_i$. Since the transformation unitary matrix $U$ is written as $U = (u_1, u_2, u_3, \cdots, u_{N_i})$, the $F_i$ is expressed as

\[
F_i = U f_i = \sum_j u_j f_i^j,
\]

where $f_i^j$ is the $j$-th element of $f_i$. Hence the transition amplitude now reads $F_i^\dagger g = F_i^\dagger u_1 = (f_i^1)^*,$ so that

\[
F_{XPS}(E_B) = \sum_i |f_i^1|^2 \delta(E_B - E_i + E_g).
\] (1.63)
By choosing the initial vector $u_i$ as $T^a|g\rangle$ or $T^e G_0 T^a|g\rangle$, the spectral functions of other spectroscopies are numerically obtained in the same manner.

### 1.5.2 Conjugate gradient method

The other important algorithm to evaluate the spectral function of RXES and NXES is the BiCG (bi-conjugate gradient) algorithm [77, 80]. This is a procedure to evaluate a column vector $x$ such that

$$x = A^{-1}b$$

for a given column vector $b$. The matrix $A$ we are interested in is the type $A = (E_g + \Omega + i\Gamma)I - H$, which is not Hermite but transposed symmetric $A^T = A$. The unit matrix is written as $1$.

Now the BiCG procedure is as follows: For a given column vector $b$ and an arbitrary column vector $x_0$, set $r_0 = b - Ax_0$ and $\beta_{-1} = 0$. Repeat

$$p_n = r_n + \beta_{n-1}p_{n-1}$$
$$\alpha_n = \frac{r_n^T r_n}{p_n^T Ap_n}$$
$$x_{n+1} = x_n + \alpha_n p_n$$
$$r_{n+1} = r_n - \alpha_n Ap_n$$
$$\beta_n = \frac{r_{n+1}^T r_{n+1}}{r_n^T r_n}$$

for $n = 0, 1, 2, \cdots$ until $r_{n+1}^T r_{n+1} \leq \varepsilon b^T b$, where $\varepsilon$ is a given small real number (usually of order of $10^{-6}$), then the resultant vector $x_{n+1}$ is an approximate solution of the equation $Ax = b$. Note the discrimination between $^T$ and $^\dagger$. The latter means Hermite conjugate such that $r_{n+1}^\dagger = (r_{n+1}^T)^*$, where the star means complex conjugate. It is said that mathematically little has been known about convergence behavior of the BiCG algorithm [77]. To the author’s experience, the iteration number gets much smaller when $A$ is arranged so that all eigenvalues are positive definite.

To apply these iterative methods to large-clusters, it is essential to reduce the dimension of Hilbert space in advance by making full use of the space group of the whole system, as proposed by Fano, Ortolani and Parola [81]. The largest RXES calculation ever known was done by Tsutsui et al. for a $4 \times 4$ Hubbard model [82].

### 1.6 Scope

The motivation of this thesis is to clarify the role of nonlocal effects in RXES. It is roughly divided into two parts. The first part is associated with theoretical explanation of the appearance of the fluorescence-like component in $M 3d-2p$ RXES of transition metal ($M$) oxides, which is one of the most important problem in the theoretical study on RXES. This subject is explored in Chaps. 2 and 3. The other part (Chaps. 4 and 5) describes some theoretical aspects of Cu $4p-1s$ RXES of cuprates with special attention to the nonlocal screening effect due to the Zhang-Rice singlet formation. The content of each chapter is described somewhat in detail below.

With the aid of numerical calculations with a simplified periodic Anderson model, we discuss the origin of the fluorescence-like component in $d^0$ systems in Chap. 2. A crucial role of the translational
symmetry of the system, the momentum conservation law and electronic correlation is demonstrated. The reason why an analysis with an impurity Anderson model successfully explains the experimental spectra of an \( f^0 \) system is qualitatively clarified. This chapter is based on the first proposal of ours on the electronic-origin mechanism of the appearance of the fluorescence-like component [83].

The nondegenerate model calculations in Chap. 2 exhibit relatively weak Raman component for a TiO\(_2\)-like system. We demonstrate in Chap. 3 that the coexistence between fluorescence-like and Raman components is clearly shown by including orbital degeneracy into the model. The calculated results well explain the latest experimental data on polarization-resolved Ti 3d-2p RXES of TiO\(_2\) in spite of the simplicity of the model. Experimentally, the coexistence is observed also in MH systems. We also show in this chapter that the fluorescence-like component appears in the MH systems, and that orbital degeneracy is essential for it. The author believes that the electronic-origin mechanism of the interplay between fluorescence-like and Raman components is established by the investigation in Chaps. 2 and 3.

Chapter 4 is devoted to studying Cu 4p-1s RXES of Nd\(_2\)CuO\(_4\). While the nonlocal screening effect due to the Zhang-Rice singlet formation is known in 2p-XPS, no one has demonstrated its contribution to RXES so far. We quantitatively prove its essential role in Cu 4p-1s RXES in this chapter for the first time, and give a clear explanation in terms of spatial extent of CT excitations [84].

Theoretical study on newly-developed experimental techniques such as momentum- or angle-resolved RXES is another interesting theme. This point is discussed in Chap. 5 together with the latest experimental data on Cu 4p\(_\sigma\)-1s RXES of Nd\(_2\)CuO\(_4\). We will show that a local transition operator is sufficient to describe the polarization and angular dependence of the “6 eV” CT excitation, and therefore impurity models would work well. We will also point out that RXES with hard X-rays provides momentum-resolved information on electronic structure in \( k \)-space.

In the final chapter, a brief summary of conclusions in this thesis is given, and future problems are presented.
Chapter 2

A Model Study on Cluster Size Effects of Resonant X-Ray Emission Spectra

Cluster size dependence of XAS, XPS, and RXES are theoretically studied with a one-dimensional periodic Anderson model, which qualitatively describes effects of the translational symmetry for nominally $d^0$ (or $f^0$) compounds such as TiO$_2$ (CeO$_2$). It is shown that RXES depends more sensitively on the cluster size than XAS and XPS, so that RXES is a useful probe in studying the duality between itinerant and localized characters of 3$d$ or 4$f$ electrons. From results calculated by changing the cluster size and parameter values such as $d$-$p$ hybridization strength, $d$-$d$ Coulomb interaction etc., it is explained why the experimental Ce 4$f$-3$d$ RXES of CeO$_2$ is well reproduced by calculations with a single-cation impurity Anderson model, but the Ti 3$d$-$2p$ RXES of TiO$_2$ is not well reproduced.\(^1\)

2.1 Introduction

It has been accepted that one of the key concepts to understand electronic properties of strongly correlated systems involving 3$d$ or 4$f$ orbitals is the duality between localized and itinerant natures of electrons. High-energy spectroscopies have played vital roles to investigate these systems. It is reasonable that XPS and XAS of these systems are considerably well described with the impurity Anderson model including a single cation [6, 85], because a completely localized core electron is involved in these spectroscopies and the core hole acts as a localized attractive potential on the 3$d$ or 4$f$ electrons. However, since van Veenendaal et al. demonstrated importance of nonlocal screening effects in analyses of metal 2$p$ XPS for NiO [41] and high-$T_c$ compounds [86, 87, 88], those phenomena in which the itinerant property of 3$d$ electrons plays an essential role have attracted much attention in this field. As explained in the preceding chapter, it is likely that their itinerancy and their dynamics are well expressed with RXES. The main motivation of this chapter is to investigate how their itinerancy appears in the spectra. It necessarily needs an extended cluster model beyond the single-cation impurity limit.

Experimental data of RXES for graphite [89], Si [90] and diamond [91] have shown that the wave vector conservation rule, which is a mathematical consequence of the itinerancy of valence electrons, plays an important role in RXES spectra. Note that the wave vector conservation rule holds even when

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core hole effects exist [92]. As explained in the preceding chapter, for transition metal compounds such as TiO$_2$ [46] and FeTiO$_3$ [47] remarkable spectral features have been observed (Fig. 1.6): in addition to inelastic X-ray scattering peaks whose emitted photon energy moves in parallel with the incident photon energy, giant inelastic spectra are observed at nearly the same energy position for any incident photon energy, and they are connected smoothly to the line shape of NXES as the incident photon energy increases far above the absorption threshold. We named the former the Raman component, and the latter the fluorescence-like component.

A recent experimental and theoretical study on Ti $3d$-$2p$ RXES of gas-phase TiCl$_4$ [93] clearly suggest that the fluorescence-like feature, which is hard to understand with the single-cation impurity model, originates from the solid state effect. We would like to study how the translational symmetry of crystals modifies RXES spectra for the $3d$ system, and to give a physical picture of the X-ray emission process. On the other hand, Nakazawa et al. showed that Ce $4f$-$3d$ RXES of CeO$_2$, which have a $4f^0$ configuration, is well reproduced with an impurity Anderson model [94] despite the apparent similarity in electronic configuration between $d^0$ and $f^0$ systems. Their results is shown in Fig. 2.1 for readers’ convenience. Now questions come arise: What systems do impurity models cover? Does the translational symmetry give a negligible effect for a system corresponding CeO$_2$? To study these questions, we adopt a one-dimensional periodic Anderson model without orbital degeneracies as a minimal model having explicit translational symmetry.

![Figure 2.1](image.png)

Figure 2.1: Theoretical and experimental XAS and RXES spectra of CeO$_2$. The thin solid curves and dotted thick curves represent calculated and experimental results, respectively [94]. The calculation was based on an impurity Anderson model. The experimental spectra were measured by Butorin et al. [95]. The agreement between calculated and experimental results is good.

The structure of this chapter is as follows: in § 2.2 we explain the model used. In § 2.3 we give results of numerical calculations on XAS, XPS, RXES and NXES for TiO$_2$-like and CeO$_2$-like systems. In § 2.4 physical interpretations for these spectra are presented with special attention to role of the wave vector conservation rule. In the last section, we will give a brief summary of the present study.
2.2 Formulation

We consider a one-dimensional (1D) version of the periodic Anderson model:

\[ H = H_{dp} + H_{dc} + H_{core}, \]

where

\[ H_{dp} = \sum_{l, \sigma} \left[ (\Delta + \epsilon_p) d_{l\sigma}^\dagger d_{l\sigma} + \epsilon_p^p p_{l \sigma}^\dagger p_{l \sigma} \right] + \sum_{(i,j)} \sum_{\sigma} \left[ v d_{i\sigma}^\dagger p_{j\sigma} + H.c. \right] + U_{dd} \sum_i d_{i\uparrow}^\dagger d_{i\uparrow}^\dagger d_{i\downarrow} d_{i\downarrow}, \] (2.2)

\[ H_{dc} = -U_{dc} \sum_\sigma \left( \sum_{i} d_{i\sigma}^\dagger d_{i\sigma} \right) \left( \sum_{\sigma'} c_{i\sigma'}^\dagger c_{i\sigma'}^\dagger \right), \] (2.3)

and

\[ H_{core} = \sum_\sigma e_c c_{i\sigma}^\dagger c_{i\sigma}. \] (2.4)

In the above equations, \( d_{i\sigma}^\dagger (p_{i\sigma}) \) is a creation operator of an electron of \( \sigma \) (\( \uparrow \) or \( \downarrow \)) spin on the \( d \) (\( p \)) site in \( l \)-th unit cell, \( \Delta \) is the charge-transfer energy between \( d \) and \( p \) orbitals, \( U_{dd} \) is the on-site \( d-d \) Coulomb correlation energy, and \( U_{dc} \) is the intra-atomic core hole potential. One-electron energy of the \( p \) orbitals is represented with \( \epsilon_p \). \( c_{i\sigma}^\dagger (c_{i\sigma}) \) is a creation (annihilation) operator of a core electron with one-electron energy \( e_c \). Geometry of the system is shown in Fig. 2.2. We set the number of valence electrons in the ground state as \( 2N \) for \( d_{MnP} \) system, and assume the \( z \)-component of the total spin \( S_z \) to be zero. Note that our model explicitly comprises both \( U_{dd} \) and \( U_{dc} \), which are essential to have realistic discussion on both XAS and RXES [49].

The \( d_1 p_2 \) cluster with open boundary condition (Fig. 2.2 (b)) is used as a reference system representing the smallest cluster with a single cation (or the impurity Anderson model), and large-cluster effects are studied using \( d_N p_N \) clusters with the periodic boundary condition (Fig. 2.2 (a)) by comparing the results calculated with different \( N \) (also with the \( d_1 p_2 \) system).

The second term in Eq. (2.2) describes nearest-neighbor \( d-p \) hopping processes. Although the present model does not explicitly include orbital degeneracies, we take them into account by estimating the \( d-p \) hopping energy \( v \) as

\[ v = \frac{1}{2} \sqrt{4V(e_g)^2 + 6V(t_{2g})^2}, \] (2.5)

where \( V(e_g) \) and \( V(t_{2g}) \) are hybridization strengths of the TiO\(_6\) cluster model [49], so that we have the same bonding-antibonding separation in the final state of RXES as that of the TiO\(_6\) cluster model. We explain the derivation in Appendix.

Okada and Kotani [49] used parameter values \( V(e_g)=3.0 \) and \( V(t_{2g})=-1.5 \), from which we have \( \nu=3.5 \) (in units of eV). Other parameters are chosen to be the same as their estimation: \( \Delta=4.0, U_{dd}=4.0 \) and \( U_{dc}=6.0 \) (in eV). These will be referred to as “TiO\(_2\)-like” parameters.

We regarded the \( d, p \) and core orbitals as Ti 3\( d \), O 2\( p \) and Ti 2\( p \) orbitals. The Hamiltonian described above can also be used for Ce 4\( f \)-3\( d \) RXES spectra of a “CeO\(_2\)-like” system by regarding \( d, p \) and \( c \) as Ce 4\( f \), O 2\( p \) and Ce 3\( d \) orbitals, respectively. Since the impurity Anderson model with local SO(3) symmetry has well reproduced Ce 3\( d \) XAS spectra [94, 96], the \( f-p \) hybridization strength mapped onto 1D Hamiltonian should be simply given by \( \nu = \sqrt{14V}/2 \), where 14 is the degeneracy.
Figure 2.2: Geometry of the system. The closed circles represent $d$ and core orbitals, and the open circles represent $p$ orbitals. (a) The multi-cation $d_N p_N$ system with periodic boundary condition. The rectangle indicates a unit cluster of the system. (b) The single-cation ($d_1 p_2$) model with open boundary condition. This is used as a reference system representing the smallest cluster with a single cation. (c) The reduced single-cation model, where $L$ is a linear combination of the two $p$ orbitals in (b) such as

$$L_\sigma = (p_{1\sigma} + p_{2\sigma}) / \sqrt{2},$$

resulting in the value $\sqrt{2} v$ of $d$-$L$ transfer energy.

of $4f$ state. Considering the results by Jo and Kotani [96] and Nakazawa et al. [94], for “CeO$_2$-like” calculations we use a parameter set of $\Delta = 1.5$, $U_{ff} = 10.0$, $U_{fc} = 13.0$, and $\nu = 1.5$ eV.

For our 1D model, the transition operators of the photon absorption and emission process in the dipole approximation are quite simplified as

$$T_a = \sum_{l} e^{i q_1 l} \sum_{\sigma} d_{l\sigma}^\dagger c_{l\sigma}$$

and

$$T_e = \sum_{l} e^{-i q_2 l} \sum_{\sigma} c_{l\sigma}^\dagger d_{l\sigma}$$

in place of Eqs. (1.22) and (1.23). $q_1$ is the wave number of an incident photon and $q_2$ an emitted photon $^2$. Since we are interested in core level spectra in the soft X-ray regime, the photon wave numbers $q_1$ and $q_2$ are taken approximately as zero.

With these operators, the transition operator of RXES is given by

$$T(\Omega) = T_e G_0(\Omega) T_a$$

$$= \sum_{l} c_{l\sigma}^\dagger d_{l\sigma} G_0(\Omega) d_{l\sigma}^\dagger c_{l\sigma},$$

where $G_0(\Omega)$ is the resolvent operator defined by $G_0(\Omega) = (\Omega + E - H + i\Gamma)^{-1}$, $E$ being the energy of the ground state $|g\rangle$. Now the transition amplitude of the RXES process from $|g\rangle$ to a final state $|f\rangle$ is given by

$$U_{g\rightarrow f}(\Omega) = \sum_{l} \sum_{n=0} \langle f | T_e (l) (P_{l})^n c_{l\sigma}^\dagger d_{l\sigma} G_0(\Omega) d_{l\sigma}^\dagger c_{l\sigma} | g \rangle \times K_{l}(l)(P_{l\sigma})^n,$$

$^2$We have disregarded the geometrical (angular dependent) factor. In realistic three-dimensional systems, it is quite important for understanding experimental RXES spectra. For effects of the angular dependence on RXES, see, e.g., Ref. [97]. We will explore angular and polarization dependence of RXES in Chap. 5.
where \( K_g(l) \) is the eigenvalue of the ground state for the translation operator \( T_r(l) \) defined in Eq. (1.40). \( P_s \) is the spin-flip operator defined by
\[
P_s d_l^\dagger P_s^{-1} = d_l^\dagger
\]
e tc., and \( P_{s,g} \) is its eigenvalue of the ground state. Since \( T_r \) and \( P_s \) commute with \( H \), and moreover they commute each other, one can always take the ground state as an eigenvector of these operators. \( T_r \) and \( P_s \) are also commute with \( T(\Omega) \), so that the eigenvalue of each operators is conserved between \( |g\rangle \) and \( |f\rangle \). To evaluate the amplitude numerically, one needs to carry out the operation of \( T_r \) and \( P_s \) in Eq. (2.9). The former is associated with the wave vector conservation rule, which reflects a spatial coherence of crystal [98], as explained in § 1.3. The latter is associated with the well-known SU(2) rotational symmetry in spin space [99], the degrees of freedom to choose the quantization axis of spin. Note that the SU(2) selection rule limits the final state more stringently than the simple \( S_z \) conservation rule does. This fact is easily understood by considering a two-site \( d-p \) model with two electrons. Within \( S_z = 0 \), we have a triplet state
\[
\frac{1}{\sqrt{2}} \left( d_l^\dagger p_l^\dagger + d_l^\dagger p_l^\dagger \right) |0\rangle,
\]
and one of singlet states
\[
\frac{1}{\sqrt{2}} \left( d_l^\dagger p_l^\dagger - d_l^\dagger p_l^\dagger \right) |0\rangle,
\]
as well as trivial singlet states \( d_l^\dagger d_l^\dagger |0\rangle \) and \( p_l^\dagger p_l^\dagger |0\rangle \). The triplet state has an eigenvalue of \( P_s = 1 \), whereas all the singlet states \( P_s = -1 \). Hence the omission of \( P_s \) in Eq. (2.9) generally leads to a breakdown of the conservation rule as to \( P_s \), and therefore causes incorrect spectra which do not satisfy the SU(2) selection rule.

After all, RXES spectral function is calculated with the transition amplitude Eq. (2.9) as
\[
F_{\text{RXES}}(\Omega, \omega) = \frac{1}{N} \sum_{f \neq g} |U_{g \rightarrow f}(\Omega)|^2 \delta(\omega - \Omega + E_f - E_g),
\]
where \( \omega \) is the emitted photon energy and we introduce the normalization factor \( 1/N \) in order to compare systems of different cluster size.

## 2.3 Calculated Results

### 2.3.1 XPS spectra

We show XPS spectra for various cluster sizes with the TiO\(_2\)-like and the CeO\(_2\)-like parameters in Fig. 2.3. The calculated line spectra are convoluted with a Lorentzian function of width 1.0 eV (HWHM) corresponding to the lifetime broadening of the core hole, as well as experimental resolution. The XPS spectra for the TiO\(_2\)-like parameters shown in Fig. 2.3 (a) have roughly two-peak structure with a strong main peak and a weak satellite. For larger cluster sizes, we observe that a few very weak peaks come arise between them. In the impurity limit \((d_l p_l)\), the main peak corresponds to the bonding state between \( \xi d^0 \) and \( \xi d^1 L \) configurations [49], where \( L \) and \( \xi \) represent core and ligand holes, respectively. The satellite peak corresponds to the antibonding state. The small cluster-size dependence suggests that the main and satellite peaks could be characterized by the above local charge-transfer excitation also for larger cluster sizes.
On the other hand, clear three peaks are observed in the XPS spectra for the CeO$_2$-like parameters (Fig. 2.3 (b)), corresponding to three configurations of $c^3f^0$, $c^3f^1L$ and $c^3f^2L^2$. The three-peaked structure is experimentally observed in Ce 3d-XPS [101], and well reproduced with impurity Anderson models [94, 96]. The striking difference between the TiO$_2$-like and CeO$_2$-like systems originates from, first, the smaller values of $v/U_{ff}$ and $v/U_{fc}$, and second, the negative value of $\Delta + U_{ff} - U_{fc}$ [94]. As the cluster size increases, we have slightly broader and more asymmetric shapes for the peaks in the lowest and the second-lowest binding energies. However, the global structure is considerably well reproduced with the single-cation cluster $f_1p_2$.

2.3.2 XAS, RXES and NXES spectra for TiO$_2$-like parameters

Figures 2.4 (a)-(c) show XAS, NXES and RXES spectra for the TiO$_2$-like parameters in $d_1p_2$, $d_3p_3$ and $d_6p_6$ clusters. The value of $\Gamma$ for NXES and RXES is taken as 0.4 eV $^3$, and the Lorentzian convolution with width 1.0 eV (HWHM) is made for all the spectra, as in the case of XPS. To compare RXES spectra for various $\Omega$’s, each of original calculated spectra is magnified by a rate indicated as “$\times 10$” in the figure.

In the case of the $d_1p_2$ system, we see two-inelastic peaks, each of which moves in parallel with the incident photon energy $\Omega$, i.e. exhibits only the Raman component. The first (higher $\omega$) peak corresponds to a single-electron charge-transfer excitation, whereas the second one to a two-electron charge transfer state with dominant $d^2L^2$ weight. It is rather appropriate to call the former the antibonding state between $d^0$ and $d^1L$ configurations, because its energy separation from the elastic line is not ruled by $\Delta$ but mainly $v$. These inelastic peaks are necessarily local charge transfer excitations, and there is no room for fluorescence-like components.

In going from the $d_1p_2$ to $d_3p_3$ clusters, however, we find some inelastic scattering peaks which do not follow the change of the incident photon energy $\Omega$. For the $d_6p_6$ cluster, the energy $\omega$ of main RXES peaks does not follow $\Omega$ but is rather constant, and it oscillates around the constant energy with the change of $\Omega$, exhibiting the fluorescence-like behavior.

The line shape of NXES also shows, in Fig. 2.4, considerable dependence on the cluster size: A single peak is observed for the NXES of the $d_1p_2$ cluster, but it splits into two peaks for the $d_3p_3$ cluster, and the relative intensity of the two peaks changes for the $d_6p_6$ cluster.

2.3.3 XAS, RXES and NXES spectra for CeO$_2$-like parameters

Figures 2.5 (a)-(c) show XAS, RXES and NXES spectra with the CeO$_2$-like parameters for various sizes of the cluster. We see that the XAS spectra have two-peak structure. The main and satellite peaks correspond to the bonding and anti-bonding states, respectively, between $c^3f^1$ and $c^3f^2L$ configurations. The cluster size dependence of XAS is quite small, and we only recognize, with increasing cluster size, a slight increase of the spectral intensity in the region between the main peak and the satellite.

The cluster size dependence of RXES for the CeO$_2$-like system is much smaller than that of the TiO$_2$-like system, and the energy of the main inelastic scattering feature follows the change of $\Omega$ even in the case of large clusters. Apart from the incident photon energy 1, the single-cation model calculation shows a strong inelastic peak, which corresponds to a single charge-transfer excitation. This peak shifts

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3We have explicitly related $\Gamma$ to the Auger decay process in Eq. (1.35). In addition, we have to consider at least two factors to evaluate $\Gamma$: The experimental resolution of the incident X-ray, and finite energy interval of eigenstates due to finite cluster size.
Figure 2.3: XPS spectra calculated with various cluster sizes for (a) TiO$_2$-like and (b) CeO$_2$-like parameters.
Figure 2.4: Calculated XAS and RXES spectra for the TiO$_2$-like parameters with (a) $d_1p_2$, (b) $d_3p_3$ and (c) $d_6p_6$ clusters. NXES spectra are also shown on the top of the RXES curves. The arrows indicate energy positions of the incident photon.
in parallel with $\Omega$, exhibiting the Raman component. With increasing cluster size, the corresponding line spectrum shows a fine spectral splitting into some line spectra, so that this inelastic structure is broadened. Comparing the results calculated with $f_1p_2$ and $f_6p_6$ clusters, we see that the single-cation model is a good approximation for describing the RXES except for the incident photon energy 1, for which we will give some discussion in the next section.

The NXES spectrum with $f_1p_2$ cluster has two peaks, corresponding to the bonding and anti-bonding states between $f^0L$ and $f^1L^2$ configurations in the final state. With increasing cluster size, the lower energy peak is more broadened, but we observe much smaller dependence on the cluster size compared with the TiO$_2$-like system.

2.4 Discussion

2.4.1 Applicability of the single-cation model

According to Fig. 2.3, it is found that the cluster size dependence is extremely small for the calculated XPS spectra of both the TiO$_2$-like and CeO$_2$-like systems. While the XAS spectra shown in Figs. 2.4 and 2.5 depend on the cluster size slightly more than XPS, the dependence is still extremely small. This fact suggests that the single-cation model can well describe XPS and XAS, which are typical examples of the first-order optical process. Thereby we justify previous theoretical analyses of Ti 2p-XPS and 2p-XAS of TiO$_2$ [49], as well as Ce 3d-XPS and 3d-XAS of CeO$_2$ [94, 96], with impurity models. In addition, for RXES and NXES, it is shown that the single-cation model works as a good model for the CeO$_2$-like system, where only the Raman component appears. However, it is demonstrated that the cluster size dependence is greatly important for the TiO$_2$-like system. While the experimentally observed fluorescence-like spectra in d$_0$ systems[46, 47] are by no means reproduced with the single-cation model, we observe the fluorescence-like behavior with the large-cluster model. This result definitely means that the appearance of the fluorescence-like spectra is a direct consequence of the translational symmetry of the system. Detailed discussion on the origin of the cluster size dependence of RXES will be given in the next subsections.

2.4.2 Fluorescence-like spectra in large cluster models

In order to understand the cluster size effect in the TiO$_2$-like system, it is instructive to study the situation in the limit of $U_{dd} = U_{dc} = 0$. In this case, the initial and final states of RXES are described exactly with one-electron Bloch states with energy dispersion (Fig. 2.6):

$$
\varepsilon^\pm(k) - \varepsilon_p = \frac{\Delta}{2} \left( 1 \pm \sqrt{1 + \left(\frac{4v}{\Delta}\right)^2\cos^2\left(\frac{k}{2}\right)} \right).
$$

Figure 2.7 shows XAS and RXES spectra for the $d_6p_6$ cluster in the limit of $U_{dd}=U_{dc}=0$. The number of $k$-points in the first Brillouin zone of the $d_6p_6$ system is six, i.e. $\{0, \pm \pi/3, \pm 2\pi/3, \pi\}$, and the number of the excited electron energies is four. In accordance with these four points, the XAS spectrum displays four lines.

The $\Omega$-dependence of RXES spectra in Fig. 2.7 (solid curves), which is unlike the Raman behavior, is a consequence of the $k$-conservation rule. Close inspection shows that the inelastic spectrum for any excitation energy consists of three lines. These correspond to states with an electron-hole pair in
Figure 2.5: XAS and RXES spectra for the CeO$_2$-like parameters with (a) $f_1p_2$ (upper), (b) $f_3p_3$ (lower left) and (c) $f_6p_6$ (lower right) clusters. See the caption for Fig. 2.4.
Figure 2.6: One electron energy dispersion in the absence of $U_{dd}$ and $U_{dc}$. Parameters used are indicated in the panel.

$$\{0, \pm \pi/3, \pm 2\pi/3\}$$

from lower to higher energy. When $\Omega$ is tuned to 2, for example, a conduction electron at $k = \pm 2\pi/3$ is resonantly selected in the intermediate state. Then the resultant final state has an electron-hole pair at $k = \pm 2\pi/3$ according to the $k$-conservation rule. Similarly, $\Omega$ at 3 (4) leads to an electron-hole pair at $k = \pm \pi/3$ ($k = 0$) in the final state. The valence (conduction) band at $k = \pi$ is of pure $p$ ($d$) character as suggested by Eq. (2.11). Hence the final state with an electron-hole pair in $\pi$ has no contribution to the RXES spectra within the intra-atomic transition model as shown in Eq. (2.7), and the inelastic scattering process is necessarily virtual one for the incident photon energy 1.

If we fix a core hole site in the intermediate state, the $k$-conservation rule breaks down. RXES spectra calculated with a fixed core hole site are shown in Fig. 2.7 with dashed curves. In this case, the spectral shape of RXES is the same as that of NXES. This is because the excited conduction electron has no contribution to the RXES spectral shape, so that the situation is the same as NXES.

These results suggest the origin of the cluster size effect in the TiO$_2$-like system. If the cluster size is small, an excited conduction electron is necessarily localized and makes an active contribution to the X-ray emission process. In this case, the emitted photon energy shifts in parallel with the incident photon energy. However, when the cluster size is large, we have some intermediate states in which the excited conduction electron state is extended in space as in the case of $U_{dd}$=$U_{dc}$=0. Thereby the photoexcited electron can be dissipated from the unit cluster with a core hole to the surrounding system. If this dissipation completely occurs in the intermediate state, the X-ray emission process necessarily resembles NXES, then the fluorescence-like spectra come arise. The dependence of the fluorescence-like spectra on $\Omega$ is expected to come from the $k$-conservation rule within the present model (see §2.4.3).

Effects of finite values of $U_{dd}$ and $U_{dc}$ are also important in the TiO$_2$-like system. In order to see the effect of $U_{dc}$, calculated RXES spectra with $U_{dd}$=0 but $U_{dc}$=6.0 eV are shown in Fig. 2.8. In the XAS spectrum we observe a strong main peak 1, which corresponds to a bound state between the core hole and an electron excited from the core level, i.e. the core exciton $^4$. Comparison of Fig. 2.7 and

$^4$See the discussion in §1.4.4. For an original paper, see Ref. [100].
Figure 2.7: RXES spectra in the free electron limit $U_{dd} = U_{dc} = 0$ (solid line). Parameters other than $U_{dd}$ and $U_{dc}$ are the same as the TiO$_2$-like ones. The dashed curves represent core-fixed RXES spectra. See the caption for Fig. 2.4.

Fig. 2.8 shows that the RXES spectra are more broadened and exhibit new fine structures because of $U_{dc}$, which causes excitations with more than one electron-hole pairs in the final state, although the final state Hamiltonian is independent of $U_{dc}$. However, the RXES spectra of 2, 3 and 4 in Fig. 2.8 are found to resemble those in Fig. 2.7, and this suggests that these intermediate states have somewhat common characters with spatially extended conduction electron states.

It appears that a weak peak located at the highest energy $\omega$ shifts in parallel with $\Omega$, but this occurs as a result of the finite size $N$.\(^5\)

When we introduce a finite value of $U_{dd}$, occurrence of doubly occupied orbital states is considerably suppressed, and then the RXES in Fig. 2.8 is changed to that in Fig. 2.4 (c). The RXES spectral broadening in Fig. 2.8 is somewhat suppressed in Fig. 2.4 (c), because of the suppression of more than one electron hole pairs in the final state. However, the effect of $U_{dd}$ is not very strong except for the case of 1, because the occupation number of $d$ electrons is small in most states of the TiO$_2$-like system.

Compared with the TiO$_2$-like system, the cluster size dependence of RXES in CeO$_2$-like system is much smaller because of the smaller value of the hybridization $v$.

\(^5\)Although the statement that a finite cluster size is likely to excessively highlight this peak is true within the present model, it may be questionable whether or not it holds in realistic systems having orbital degeneracy. The experimentally observed Raman component involves nonbonding states (see § 2.4.4) as well as the antibonding state, and the intensity ratio between the Raman and fluorescence-like components strongly depends on how many states we have in a unit cluster, as will be discussed in the next chapter.
2.4.3 Role of the $k$-conservation rule

To study effects of the $k$-conservation rule in TiO$_2$-like and CeO$_2$-like systems, we calculate RXES spectra by fixing the core orbital on a single site and compare them with those including the translational symmetry of core orbitals (denoted as “coherent spectra”). The results are shown in Fig. 2.9. The TiO$_2$-like spectra in Fig. 2.9 (a) show clear difference between the fixed core-site and coherent spectra. The fixed core-site spectra are considerably broader than the coherent ones for the incident photon energy of 2, 3 and 4. This is clearly attributed to the $k$-nonconserving nature of the fixed core-site model. Thus, the role of the $k$-conservation rule is (1) to narrow the inelastic peak width, and (2) to fluctuate their peak position around that of NXES spectra.

Note that the RXES spectral shape depends on the incident photon energy even with the core-fixed $k$-nonconserving model. This is in strong contrast to the case of $U_{dd}=U_{dc}=0$ (Fig. 2.7). Because of finite values of $U_{dd}$ and $U_{dc}$, the photo-excited conduction electron in the intermediate state cannot be a single Bloch state, and some rearrangement between the conduction and valence electron states occurs in going from the intermediate to the final states. Therefore, the origin of the dependence of the fluorescence-like spectra on the incident photon energy is partly the effect of the $k$-conservation rule and partly the effect of $U_{dd}$ and $U_{dc}$.\(^6\)

According to Fig. 2.9 (b), there is little difference between the fixed core-site and coherent RXES spectra for the CeO$_2$-like parameters, although close inspection shows that we have slightly broader spectral shapes with the fixed core-site model. For the CeO$_2$-like system, the quasi-particle bandwidth is of the same order as the lifetime in the final state. Furthermore the small value of $\nu/U_{fc}$ makes the intermediate state almost localized. Then clear cluster size effects are not observed. The fact that

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\(^6\)We discuss the contribution of crystal field splitting in the next chapter.
the fixed core-site and coherent spectra are almost the same demonstrates the reason why the analyses of Ce 4f-3d RXES with the impurity Anderson model have successfully reproduced the experimental result [94].

2.4.4 Limitation of the present model

We have discussed qualitatively the cluster size effect of RXES in TiO$_2$ and CeO$_2$. In order to make a quantitative study, it is necessary to improve the model. Firstly, the atomic arrangement should be developed from the 1D chain to a 3D model that is more realistic. Secondly, the orbital degeneracies of $d$ (or $f$) and $p$ states should be taken into account. As shown in Appendix, we have introduced the effective hybridization $v$, in which effects of orbital degeneracies on the hybridization between $d^0$ and $d^1_L$ are taken into account. With this effective hybridization, however, effects of orbital degeneracies on the hybridization between $cd^1$ and $cd^2L$ configurations in the intermediate state cannot be well described. Furthermore, the effects of orbital degeneracies are essential in the calculation of RXES for the incident photon energy tuned to the main XAS peak. As shown by Nakazawa et al. [94], the main inelastic RXES spectra in resonance with the XAS main peak of CeO$_2$ originate from the nonbonding $f^{1L}$ final states, instead of the antibonding state between $f^0$ and $f^{1L}$ configurations. The nonbonding final states occur only by taking explicitly into account the orbital degeneracies. The situation is also the same for TiO$_2$. In this sense, the present calculation of RXES for the case 1 is not realistic. In the next chapter, we will discuss the cluster size dependence with degenerate models to remove this limitation.

2.5 Conclusions

We have numerically studied large-cluster effects on XPS, XAS, NXES and RXES spectra. The model we have used is a one-dimensional nondegenerate periodic Anderson model, which is a minimal model having the explicit translational symmetry. It qualitatively describes those spectra of $d^0$ and $f^0$ compounds. Following results have been obtained.

Firstly, we showed that the cluster size dependence is extremely suppressed for the first order optical process, XPS and XAS. It suggests that an impurity model is applicable to analyses of these spectra, in contrast to the second-order optical process, RXES and NXES.

Secondly, for TiO$_2$-like systems, we numerically demonstrated the occurrence of fluorescence-like spectra because of the large-cluster effect. Their behavior is qualitatively consistent with the Ti 3d-2p RXES experiment of TiO$_2$. The origin of the fluorescence-like spectra is the existence of spatially extended states of a conduction electron in the intermediate state. Apart from the effects due to orbital degeneracy, the dependence of fluorescence-like spectra on the incident photon energy originates from the $k$-conservation rule, as well as from the effects of $U_{dd}$ and $U_{dc}$.

Thirdly, for the CeO$_2$-like system we have shown that the large-cluster effects in RXES spectra are fairly suppressed, compared with the TiO$_2$-like system, because of the smaller hybridization strength $v$. The effect of the translational symmetry is the broadening of inelastic peaks.

Finally we pointed out that explicit orbital degeneracies should be taken into account to describe RXES spectra in resonance with the XAS main peak in $d^0$ and $f^0$ systems. This subject will be discussed in the next chapter.
Figure 2.9: Comparison between fixed core-site and coherent calculations of RXES spectra for the (a) TiO$_2$-like and (b) CeO$_2$-like systems with six unit clusters. The fixed core-site spectra are represented with dashed lines, and the coherent ones with solid lines. See the caption for Fig. 2.4.
Appendix: Effective Hybridization

In a TiO$_6$ cluster model with local O$_h$ symmetry and with full orbital degeneracies, the Hamiltonian of hybridization between Ti 3$d$ orbitals and O 2$p$ ligand molecular orbitals is given by

$$H'_1 = \sum_{\Gamma,m,\sigma} \left[ V(\Gamma) d^\dagger_{\Gamma m\sigma} p_{\Gamma m\sigma} + \text{H.c.} \right], \quad (2.12)$$

where $\Gamma$ runs over two irreducible representations of O$_h$, i.e. $e_g$ and $t_{2g}$, and $m$ distinguishes the 2- or 3-fold degeneracies of them. On the other hand, in the impurity limit (Fig. 2.2 (b)), the hopping energy of our model satisfies

$$2v = \langle d^0|H|d^1L\rangle, \text{ where } |d^0\rangle = L^\dagger_{\uparrow} |0\rangle$$

$$|d^1L\rangle = \frac{1}{\sqrt{2}} \sum_\sigma d^\dagger_{\sigma} |d^0\rangle.$$

The ligand orbital $L^\dagger_{\sigma}$ is defined by (see Fig. 2.2 (c))

$$L_{\sigma} = \frac{1}{\sqrt{2}} (p_{1\sigma} + p_{2\sigma}).$$

$|0\rangle$ denotes the state which has no valence electrons but has filled core levels.

Now we map the hybridization strength of TiO$_6$ cluster onto 1D $d$-$p$ model. It is quite natural to define our $v$ as

$$2v \equiv \max \{ \langle d^0|H'_1|d^1L\rangle \}, \quad (2.13)$$

where $|d^1L\rangle$ is a linear combination such as

$$|d^1L\rangle = \sum_{\Gamma,m,\sigma} \alpha_{\Gamma m\sigma} d^\dagger_{\Gamma m\sigma} |d^0\rangle, \quad (2.14)$$

and the coefficients $\{\alpha_{\Gamma m\sigma}\}$ are chosen to maximize $\langle d^0|H'_1|d^1L\rangle$ under the normalization condition

$$\sum_{\Gamma,m,\sigma} \alpha_{\Gamma m\sigma}^2 = 1.$$  

It is easy to solve the extremum problem and show that the effective hybridization defined by Eq. (2.13) is given by

$$v = \frac{1}{2} \sqrt{4V(e_g)^2 + 6V(t_{2g})^2} \quad (2.15)$$

for

$$\alpha_{\Gamma m\sigma} = \frac{V(\Gamma)}{\sqrt{4V(e_g)^2 + 6V(t_{2g})^2}}. \quad (2.16)$$

Within so-called two-configuration approximation, bonding and antibonding states in the final state of RXES are defined as lower and higher energy eigenstates, respectively, of the $2 \times 2$ Hamiltonian spanned by $|d^0\rangle$ and $|d^1L\rangle$. By definition, the bonding-antibonding separation of the present single-cation model with the effective $v$ is exactly the same as that of the TiO$_6$ cluster model.

In the case of the CeO$_2$-like system, we can take

$$H'_1 = V \sum_{m,\sigma} \left[ f^\dagger_{m\sigma} p_{m\sigma} + \text{H.c.} \right] \quad (2.17)$$

with SO(3) symmetry and 7-fold degeneracy of $l=3$ orbital. Therefore, the effective hybridization $v$ is given by

$$v = \frac{\sqrt{14}}{2} V. \quad (2.18)$$
Chapter 3

Interplay between Raman and Fluorescence-Like Components in Degenerate $d^0$ and $d^1$ Systems

XAS, NXES and RXES spectra are theoretically studied with a doubly-degenerate one-dimensional periodic Anderson model under $d^0$ and $d^1$ fillings. This is a simplified model of band insulators such as TiO$_2$, and Mott-Hubbard insulators such as Ti$_2$O$_3$. Comparing with nondegenerate model calculations, we point out the important role of orbital degeneracy in reproducing experimental excitation energy dependence of RXES. The calculated results exhibit interplay between Raman and fluorescence-like components in both band insulator and Mott-Hubbard insulator. The former and latter components reflect the local point symmetry and the translational symmetry of the system, respectively. Our results qualitatively well explain Ti $3d$-$2p$ RXES of TiO$_2$ and Ti$_2$O$_3$.  

3.1 Introduction

In this chapter, we discuss $M$ $3d$-$2p$ RXES ($M$ being a transition metal ion) for $d^0$ and $d^1$ insulators with multi-$M$ cluster models including orbital degeneracy. We have proposed a mechanism of electronic origin in the preceding chapter for the experimentally observed fluorescence-like spectra in Ti $3d$-$2p$ RXES [46, 47] (see Fig. 1.6). The key point of our picture is the existence of extended states against the strong $U_{dc}$ in the intermediate state, although such extended states may have almost negligible weight in the XAS spectrum. When $\Omega$ (incident photon energy) is tuned there, an electron excited to a $3d$ orbital can escape to the neighboring site (Fig. 3.1 (b)) because of a finite valence band width and finite electronic relaxation time of the core hole. Consequently, RXES spectra roughly reflect the valence band density of states. This transition process resembles NXES, which is schematically described in Fig. 3.1 (a), in the sense that a core electron is excited to a continuum state in the both cases. Thus, one can call this RXES spectrum NXES-like one, which has naturally less $\Omega$-dependence.

For the $\Omega$-dependence of RXES spectra, Minami and Nasu [102] stressed the role of phonon degrees of freedom. Using a model including the electron-phonon coupling but any Coulomb interaction,

Figure 3.1: Schematic diagram of (a) the normal X-ray emission process and (b) the fluorescence-like resonant emission in 3d-2p RXES of $d^1$ compounds. In (a), a core electron is excited by an incident X-ray with energy $\Omega$ to a high-energy continuum far from the valence level, so that the spectrum of the emitted X-ray $\omega$ is related to the density of states of the filled valence band (darkly-shaded area). In (b), a core electron is resonantly excited to an extended valence state located between the main and CT satellite peaks of XAS. Then the electron escapes from the core hole site, with probability involving 3d-ligand hopping integral and relaxation time $\tau_R$ of the intermediate state. After that, the X-ray emission process resembles the case (a).
they insist that the origin of the fluorescence-like component, “luminescence” component in their terminology, is attributed to the full phonon relaxation of electronic momentum in the intermediate state. The Raman component is, on the other hand, attributed to the zero-phonon process, and thus described with the simple band theory. Note that the Raman component in their sense comes from delocalized Bloch states, being completely different from our theory, where local charge-transfer excitations give rise to the Raman component. Making a comparison between the phonon relaxation time $\tau_p$ and lifetime of the core hole $\tau_R$, they concluded that the “luminescence” component due to the phonon relaxation contributes comparably to the Raman component in Ti $3d$-$2p$ RXES of TiO$_2$. No essential change in this conclusion has been made in their sequel theory including core and valence exciton effects within that approximation which takes only one electron-hole pair into account [103]. Experimental spectra, however, clearly show the comparable spectral weight of the two components even in the case of late transition metal oxides [104], which should be classified into Raman-dominant materials according to their theory. Hence it may well be questioned whether the phonon relaxation really governs the appearance of the fluorescence-like component in transition metal oxides, although the phonon coupling might play some role in materials either with a long $\tau_R$ and high Debye temperature such as diamond [105].

While our model successfully explained the origin of the fluorescence-like spectra, the lack of internal structure of atoms prevents us from discussing features of local origin such as polarization dependence in RXES. Very recently, Harada et al. observed polarization dependence of Ti $3d$-$2p$ RXES of TiO$_2$, where a drastic resonant enhancement occurs when $\Omega$ is tuned at a satellite peak of XAS [106], and Matsubara et al. pointed out that it is explained in terms of the selection rule of the local point group [107]. It is the purpose of the present chapter to extend the previous model to include orbital degeneracies, and show that calculated spectra represent coexistence of the fluorescence-like and Raman components, the latter being qualitatively consistent to the experimental polarization dependence.

Another purpose of this chapter is to study the RXES spectra in a Mott-Hubbard (MH) insulator. If an inter-site charge-transfer process crucially contributes to RXES spectra in appearance of the fluorescence-like component, it is interesting to study how RXES spectra are suffered from change in character of insulating gaps upon going from a band insulator to a MH insulator. Although effective hopping energy seems to be considerably reduced by $d$-$d$ on-site Coulomb interaction, experimental data on Ti $3d$-$2p$ RXES of Ti$_2$O$_3$ [108], which is often referred to as a typical MH insulator, show a clear fluorescence-like component. In the subsequent sections, we show that orbital degeneracy is essential in appearance of the fluorescence-like spectra in MH systems, and we sketch interplay between the fluorescence-like component and intra- or inter-site $d$-$d$ excitations in RXES spectra.

The layout of the present chapter is as follows: In the next section, the models used are explained. As a minimal model with both translational symmetry and orbital degeneracies, a doubly-degenerate one-dimensional (1D) model is introduced. In § 3.3 and § 3.4, main features of calculated results are discussed in detail for $d^0$ and $d^1$ systems, respectively, with special attention to the role of orbital degeneracy and translational symmetry of the system. In § 3.5, the aforementioned coexistence and relation with experimental data are discussed. In § 3.6, a brief summary is given.
3.2 Formulation

We use a 1D doubly-degenerate periodic Anderson model, which is topologically equivalent to the system schematically described in Fig. 3.2 (a). The Hamiltonian is written as follows:

\[ H = H_0 + V + H_{dd} + H_{dc}, \]  

(3.1)

where the first two terms describe one-electron part, the third one 3d-3d Coulomb interaction, and the forth one 3d-core intra-atomic Coulomb interaction.

\[ H_0 = \frac{1}{2} \sum_{l, \sigma} \left( \epsilon_0 Q_{l\sigma}^\dagger Q_{l\sigma} + \epsilon_q q_{l\sigma}^\dagger q_{l\sigma} + \epsilon_{c} c_{l\sigma}^\dagger c_{l\sigma} \right) + \left( \Delta + \epsilon_0 \right) D_{l\sigma}^\dagger D_{l\sigma} + (\Delta - 10Dq + \epsilon_0) d_{l\sigma}^\dagger d_{l\sigma}, \]

\[ V = \frac{1}{2} \sum_{l, \sigma} \left\{ d_{l\sigma}^\dagger \left[ v_1 (q_{l\sigma} + q_{l+1\sigma}) + u_1 (Q_{l\sigma} + Q_{l+1\sigma}) \right] + \sum_{\sigma} \left[ D_{l\sigma}^\dagger \left[ v_2 (Q_{l\sigma} - Q_{l+1\sigma}) + u_2 (q_{l\sigma} - q_{l+1\sigma}) \right] \right] \right\} \quad + \text{H.c.} \]

In the above equations, \( d_{l\sigma}^\dagger \) and \( D_{l\sigma}^\dagger \) represent creation operators of two 3d orbitals with spin \( \sigma \) at \( l \)-th unit cell, respectively. \( q_{l\sigma}^\dagger \) and \( Q_{l\sigma}^\dagger \) are creation operators of oxygen 2p orbitals with one-electron energy \( \epsilon_0 \). \( \Delta \) and \( 10Dq \) are the CT energy and the crystal field splitting energy between the two 3d orbitals. \( c_{l\sigma}^\dagger \) is a creation operator of a core electron with one-electron energy \( \epsilon_{c} \).

The interaction terms are defined as

\[ H_{dd} = U_{d1} \sum_{l} \left( d_{l\sigma}^\dagger d_{l+1\sigma}^\dagger d_{l\sigma} d_{l+1\sigma} + D_{l\sigma}^\dagger D_{l+1\sigma}^\dagger D_{l\sigma} D_{l+1\sigma} \right) + U_{d2} \sum_{l} \left( \sum_{\sigma} \left( d_{l\sigma}^\dagger d_{l\sigma'}^\dagger \right) \sum_{\sigma} \left( D_{l\sigma}^\dagger D_{l\sigma'} \right) \right) \]

and

\[ H_{dc} = -U_{dc} \sum_{l, \sigma, \sigma'} \left( d_{l\sigma}^\dagger d_{l\sigma'} + D_{l\sigma}^\dagger D_{l\sigma'} \right) c_{l\sigma'}^\dagger c_{l\sigma}, \]

(3.2)

where \( U_{d1} (U_{d2}) \) is the on-site \( d-d \) or \( D-D (d-D) \) Coulomb correlation energy, and \( U_{dc} \) is the intra-atomic core-3d interaction. Exchange and spin-orbit couplings are omitted for simplicity.

The \( d-p \) hopping energies are represented with \( \{ v_1, v_2, u_1, u_2 \} \). Depending on their relative phases and values, there are some ways to include orbital degeneracy into this model. The single-metal-ion cluster limit of our model is described in Fig. 3.2 (b). We consider that the single-M cluster is an effective model of an MOs cluster. In the case of a MOs cluster with \( O_6 \) symmetry, a subsystem having \( d(e_g) \) orbitals and ligand orbitals with \( e_g \) symmetry is coupled with a subsystem having \( d(t_{2g}) \) orbitals and ligand orbitals with \( t_{2g} \) symmetry through \( d-d \) Coulomb interaction (cf. Fig. 1.9). If there were no Coulomb interaction, the subsystems would be completely decoupled. Considering this fact, we set \( v_1 = u_1 \) and \( v_2 = u_2 \), then the ligand orbitals are separated into two orthogonal molecular orbitals as

\[ p_{\sigma} = \frac{1}{2} (q_{l\sigma} + q_{l\sigma} + Q_{l\sigma} + Q_{l\sigma}) \]  

(3.3)
and
\[ P_\sigma = \frac{1}{2} (q_{0\sigma} - q_{1\sigma} + Q_{0\sigma} - Q_{1\sigma}). \]  \hspace{1cm} (3.4)

Consequently, the single-\( M \) cluster is reduced to that in Fig. 3.2 (c). Now we can regard the \( d-p \) unit as an effective subsystem of the \( d(t_{2g})-L(t_{2g}) \) one, and the \( D-P \) unit as an effective subsystem of the \( d(e_g)\)-\( L(e_g) \) one, where \( L \) stands for ligand molecular orbital.  

To evaluate hopping energies, we apply the effective hybridization theory separately to \( e_g \) and \( t_{2g} \) orbitals. For \( t_{2g} \) (\( d \)) orbitals, the starting point is the equation
\[
\text{max}\{\langle d^\dagger | H | d^1 \rangle\} = \text{max}\{\langle d^\dagger | H | d(t_{2g}) \rangle | L(t_{2g}) \rangle\},
\]
where \( |d^1\rangle = \frac{1}{\sqrt{2}} \sum_\sigma d^\dagger_\sigma |p_\sigma\rangle |d^\dagger\rangle \). As suggested by Eq. (3.3), the left hand side is given by \( \sqrt{2} \times 2v_1 \), where \( \sqrt{2} \) represents the contribution of spin degeneracy. The right hand side is given by \( \sqrt{6}V(t_{2g}) \), where \( V(t_{2g}) \) is the hybridization strength of a \( \text{TiO}_6 \) cluster model. Hence we have \( v_1 = \sqrt{3}V(t_{2g})/2 \). Similarly, \( v_2 \) is estimated as \( v_2 = V(e_g)/\sqrt{2} \). For \( V(e_g) = 3.0 \) and \( V(t_{2g}) = -1.5 \text{ eV} \) \cite{49}, we have \( v_1 = u_1 = 1.3 \) and \( v_2 = u_2 = 2.1 \text{ eV} \). Other parameters are chosen to be the same as Ref. \cite{49}: \( \Delta = 4.0, 10Dq = 1.7, U_{dd} = U_{dd} = 4.0 \) and \( U_{dc} = 6.0 \text{ eV} \).

Uozumi \cite{109} and Taguchi \cite{110} report nearly the same value of \( U_{dd}, U_{dc}, 10Dq, \) and \( V(e_g) \) as those of \( \text{TiO}_2 \) in their analyses on \( \text{Ti}_{2p}\text{-XPS of Ti}_{2}\text{O}_{3} \), so that we take the same parameter also for \( d \) systems in this chapter.  

In addition to the doubly-degenerate models, we use also nondegenerate models shown in Fig. 2.2 to discuss the role of orbital degeneracy. The value of the parameter set including \( d-p \) hopping energy \( v \), CT energy \( \Delta \), on-site \( d-d \) Coulomb energy \( U_{dd} \), and on-site core-\( d \) attractive interaction \( U_{dc} \) will be explained in the subsequent subsections.

In the present model, X-ray absorption and emission processes at a metal site \( l \) are described with the following operators:
\[
T^a(l) = \sum_\sigma (a_1 d^\dagger_{l\sigma} + a_2 D^\dagger_{l\sigma}) c_{l\sigma} \hspace{1cm} (3.5)
\]
\[
T^c(l) = \sum_\sigma e^\dagger_{l\sigma} (b_1 d_{l\sigma} + b_2 D_{l\sigma}), \hspace{1cm} (3.6)
\]
where \( \{a_1,a_2\} \) and \( \{b_1,b_2\} \) are numerical factors, representing polarization dependence of the RXES. All of them are taken to be unity unless any particular mention is made. The transition operator of RXES is defined in Eq. (2.8),
\[
\sum_l T^c(l) G_0(\Omega) T^a(l).
\]
It is worth noting that the point group symmetry of operators \( d_{l\sigma}G_0 d^\dagger_{l\sigma} \) and \( D_{l\sigma}G_0 D^\dagger_{l\sigma} \) is different from that of \( d_{l\sigma}G_0 D^\dagger_{l\sigma} \) and \( D_{l\sigma}G_0 d^\dagger_{l\sigma} \). The latter leads to final states with a different local point group symmetry from the ground state. As will be discussed, it brings about a class of nonbonding final states. The spectral function of the RXES process has been defined by Eq. (2.10). In this chapter, we use the same value \( \Gamma = 0.4 \text{ eV} \) as that in the preceding chapter.

---

2 The other choice that \( v_1 = u_1 \) and \( v_2 = -u_2 \) also leads to the exactly same single-\( M \) cluster as in Fig. 3.2 (c). Since these two choices prove to be exactly equivalent even in the double-\( M \) cluster (periodic \( d_2p_2 \) case), it is conceivable that the conclusions in the present chapter do not drastically depend on the choice at all.

3 Reference \cite{110} reports a large CT energy 6.5 eV. Note that this corresponds to \( U_{dd} + \Delta - \frac{1}{4}10Dq \) in the notation of the present model, giving \( \Delta = 3.52 \) for \( U_{dd} = 4.0 \) and \( 10Dq = 1.7 \).
3.3 Calculated Results I: Band Insulators

3.3.1 Nondegenerate $d^0$ system

To elucidate role of orbital degeneracy, we first recapitulate results of nondegenerate models as shown in Fig. 2.2, where the parameter set $\Delta=4.0$, $U_{dd}=4.0$, $U_{dc}=6.0$, and $v=\sqrt{(2v_1)^2 + (2v_2)^2}/2=3.5$ eV are used. These are the same as those in the preceding chapter. For all XAS, RXES and NXES spectra in the present chapter, the momentum-transfer $q$ is fixed to be zero, and calculated line spectra are convoluted with Lorentzian 1.0 eV (HWHM). Moreover, the $z$-component of the total spin $S_z$ is taken to be zero except for single-$M$ cluster calculations with $d^1$ filling.

Figure 3.3 (a) and (b) show the calculated spectra with nondegenerate single- and multi-$M$ cluster models. Detailed discussions on the spectra have been given in the preceding chapter with special attention to the appearance of the fluorescence-like spectra in the multi-$M$ cluster model. Let us briefly review the bonding-antibonding separation in the XAS and RXES spectra in the single-$M$ cluster model. When photoexcited, there are only two states $\{|c_d^1\rangle, |c_d^2L\rangle\}$ in the Hilbert space of the single-$M$ cluster. Diagonalizing the $2 \times 2$ Hamiltonian matrix, we have the energy separation $W'_0$ between the bonding and antibonding states as

$$W'_0 = \sqrt{(\Delta + U_{dd} - U_{dc})^2 + 8v^2} \simeq 10.1 \text{ eV}.$$  

Similarly, in the final state of RXES, the bonding-antibonding separation is roughly estimated within so-called two-configuration approximation,

$$W_0 = \sqrt{\Delta^2 + 16v^2} \simeq 14.6 \text{ eV}.$$  

Note that matrix element $\langle d^1L|H|d^0 \rangle$ is $\sqrt{2} \times \sqrt{2}v$, where the first $\sqrt{2}$ originates from the spin degeneracy. These formulae will give a rough estimation on the bonding-antibonding separation in more
elaborate models.

3.3.2 Degenerate $d^0$ system

Figure 3.4 (a) shows XAS, NXES and RXES spectra calculated with the degenerate single-$M$ cluster model. In the XAS spectrum, we observe two strong peaks and a number of subpeaks in their high energy tail. Experimentally, four distinct peaks are observed in the main structure of Ti$_2$p$_3$d$_0$XAS of $d^0$ compounds such as TiO$_2$ and FeTiO$_3$ [46, 47]. Since our model does not include the spin-orbit interaction of the core level, the two experimental peaks with lower energies correspond to the calculated main structure.

We also see that the RXES spectra depend on incident photon energy $\Omega$ rather than the simple Raman component in the case of the nondegenerate single-$M$ cluster. For lower $\Omega$'s such as 1 and 2, the single spectrum which linearly shifts as $\Omega$ increases is observed. This inelastic spectrum highlighted with blank bars survives for higher $\Omega$'s, whereas another spectrum highlighted with the shaded bar suddenly appears for 5 and 6. This kind of enhancement when $\Omega$ is targeted at a satellite peak of XAS is also observed in the nondegenerate case, as marked also with shaded bars in Fig. 3.3 (a). However, the nondegenerate results have no peaks corresponding to the series of peaks marked with blank bars in Fig. 3.4 (a). Hence, we conclude that this series of peaks originates from the orbital degeneracy. By the reason discussed below, we call these peaks nonbonding ones hereafter.

To understand the origin of the inelastic spectra, consider the case of isotropic limit that $10Dq \to 0$ and $v_1 \to v_2$, where the Hamiltonian recovers permutation symmetry between $\{d, p\}$ and $\{D, P\}$. Within the two-configuration approximation, the bonding and antibonding states in the final state of RXES are described with state vectors $|0_0\rangle \equiv |d^0\rangle$ and

$$|1_0\rangle = \frac{1}{2} \sum_{\sigma} (d_{\sigma}^d p_{\sigma} + D_{\sigma}^d P_{\sigma}) |d^0\rangle.$$ 

Note that these two states have the same permutation symmetry as well as local point group symmetry. With a matrix element $V_{\text{eff}}(d^0) \equiv \langle 1_0 | H | 0_0 \rangle = \sqrt{2} \left( (2v_1)^2 + (2v_2)^2 \right)$, the bonding and antibonding separation is proven to be $W_0$, although calculated spectra exhibit somewhat smaller value than $W_0$. Similarly to the nondegenerate case, $|g\rangle$ is the bonding state with relatively large $|0_0\rangle$ weight, and the antibonding state has relatively large $|1_0\rangle$ weight. Since the transition operators are symmetric as to the permutation, all allowed intermediate states have the same symmetry as $|g\rangle$ in this case. In the two-configuration approximation, each of them is a linear combination of

$$|1_0\rangle = \frac{1}{2} \sum_{\alpha} (d_{\alpha}^d + D_{\alpha}^d) c_{\alpha} |0_0\rangle$$

and

$$|2_0\rangle \propto \sum_{\alpha} (d_{\alpha}^d + D_{\alpha}^d) c_{\alpha} |1_0\rangle,$$

giving bonding and antibonding intermediate states. Since $\Delta + U_{dd} - U_{dc} > 0$, the bonding intermediate state has mainly $|1_0\rangle$ weight, and would have large overlap with $(d_{\alpha}^d + D_{\alpha}^d) c_{\alpha} |g\rangle$. Similarly, the antibonding intermediate state has large overlap with $(d_{\alpha}^d + D_{\alpha}^d) c_{\alpha} |AB\rangle$, where $|AB\rangle$ is the antibonding final state.

\footnote{From a quantitative point of view, the two-configuration approximation is poor one in the context of the large-$N$ expansion theory [20, 111] because the number of degenerate orbitals is only two.}
Figure 3.3: XAS, RXES and NXES spectra calculated with nondegenerate models under $d^0$ filling. (a) the single-$M$ and (b) $d_4p_4$ periodic clusters. For each figure, the right and left panels show XAS and RXES spectra, respectively. There is also a NXES spectrum at the top of the array of the RXES curves in the left panel. The arrows in each XAS spectrum indicate the position of excitation energies, and the numbers in the XAS spectra correspond to those of RXES. The elastic scattering peaks are omitted from the figures, and they are replaced with the arrows. Each of original calculated RXES spectra is magnified by a rate indicated as “$\times 3$”.
Figure 3.4: XAS, RXES and NXES spectra calculated with degenerate models under $d^0$ filling, (a) the single-$M$ and (b) $d_4p_4$ periodic clusters. See the caption for Fig. 3.3.
state. Consequently, absorption intensity strongly concentrates at the main peak, and $|AB\rangle$ is strongly enhanced when $\Omega$ is tuned at the satellite peak in the XAS spectra.

Note that a final state such as $|N_1\rangle \equiv \frac{1}{\sqrt{2}} \sum_\sigma (d_\sigma^\dagger P_\sigma + D_\sigma^\dagger p_\sigma) |d_0\rangle$ can contribute to inelastic scattering. This has the same permutation symmetry as that of the ground state, but local point group symmetry around the metal site is different. This fact encourages us to call it a nonbonding state. By the reason explained above, it is the elastic line (ground state) that is most strongly enhanced when $\Omega$ is tuned at the main absorption manifold. The elastic line is, however, omitted from the figures, so that the main inelastic spectra originate from the nonbonding states for that $\Omega$. By definition, the existence of the nonbonding states is direct consequence of orbital degeneracy. The nonbonding state is energetically $\Delta$ higher than $|d_0\rangle$, being nearly independent of hybridization strength. Since the energy of the bonding state is estimated as $(\Delta - W_0)/2$ within the two-configuration approximation, the nonbonding state will be observed

$$W_{ON} \equiv (\Delta + W_0)/2$$

distant from the elastic line. Note that this is always smaller than $W_0$, and therefore the nonbonding state is located in between the bonding and antibonding states in any case.

When a finite $10Dq$ is introduced, we have a finite energy difference between $c_d^1$- and $c_D^1$-dominant intermediate states due to $10Dq$, so that we observe the doubly-peaked structure in the main manifold of the XAS spectrum. Similarly, the nonbonding lines split into several ones in a RXES spectrum. Since the Hamiltonian is not symmetric as to the permutation, an antisymmetric state

$$|N_2\rangle \equiv \frac{1}{\sqrt{2}} \sum_\sigma (d_\sigma^\dagger p_\sigma - D_\sigma^\dagger p_\sigma) |d_0\rangle$$

appears as a nonbonding peak in the final state. This state has the same local point group symmetry as the ground state. Furthermore, $|N_1\rangle$ split into the following two states:

$$|N_{11}\rangle \equiv \frac{1}{\sqrt{2}} \sum_\sigma d_\sigma^\dagger P_\sigma |d_0\rangle$$

$$|N_{12}\rangle \equiv \frac{1}{\sqrt{2}} \sum_\sigma D_\sigma^\dagger p_\sigma |d_0\rangle,$$

with energy separation of order of $10Dq$. Thus, we observe three nonbonding lines in this case. Generally, anisotropy of $V_1$ and $V_2$ gives rise to energy shift of the nonbonding peaks. As a result, $N_{11}$- and $N_{20}$-dominant states are accidentally seen at nearly the same position in Fig. 3.4 (a). The transition processes in the single-$M$ cluster is summarized in Fig. 3.5, where these three nonbonding states are represented with the shaded rectangle. Note that the nonbonding states are hardly perturbed with the metal-ligand hybridization.

These features of the degenerate single-$M$ cluster calculation are substantially conserved in the multi-$M$ cluster calculation. Apart from subpeaks such as 4, the main manifold of the XAS spectrum shown in Fig. 3.4 (b) is composed of two definite lines, and we can naturally attribute these lines to those states which have relatively large $c_d^1$ or $c_D^1$ weight in the photoexcited cluster. For RXES spectra, we see, firstly, that the nonbonding states give the main inelastic structure for the main peak.
resonance (spectrum 1 and 2). Secondly, the antibonding state marked with the shaded bar is strongly enhanced when $\Omega$ is tuned in the vicinity of the satellite peak (spectrum 7), although the satellite peak is greatly smeared out and does not give a clear structure.

Figure 3.5: The energy scheme of $3d$-$2p$ RXES of $d^0$ compounds in the standard notation. In the initial and final states, the metal-ligand hybridization creates the bonding (represented with the lowest horizontal bar), antibonding (the highest bar) and nonbonding states (the shaded rectangle). These three kinds of states similarly exist in the intermediate state. While the $d$-$p$ hybridization gives rise to the bonding-antibonding separation, the energy of nonbonding states is hardly perturbed with the hybridization.

Close inspection shows, however, certain modifications are observed in the spectra of local origin. Firstly, while the nonbonding states keep energy separation of order of $10Dq$ in the single-$M$ cluster calculation, the separation in Fig. 3.4 (b) is considerably contracted because of the finite transfer between unit clusters. Whether or not this is the case in realistic three-dimensional systems is unclear because whether the separation between the nonbonding states get smaller or larger would greatly depend on a band structure. Secondly, the intensity ratio of the main XAS peaks is slightly changed. This is possibly associated with a change in character of the main absorption peaks, i.e. from the simple bonding state to a core-excitonic state.

The most conspicuous change in RXES spectra is occurrence of the fluorescence-like spectra. Figure 3.4 (b) exhibits the inelastic spectra whose position is almost the same as that of NXES for almost all $\Omega$’s higher than 3. This is sharp contrast to the nonbonding-antibonding spectra explained above, which behave as if NXES spectrum has no relation with RXES. Similarly to the nondegenerate case, we confirm again that the origin of such spectra is itinerancy in the targeted intermediate state. The subpeaks in the high-energy tail of the main absorption peaks, such as 3, 4 and 5 in Fig. 3.4 (b), originate from a finite number of $k$-points, and highly itinerant according to the core exciton theory. In fact, a detailed analysis of the present author shows that a photoexcited electron in the intermediate state 3 is delocalized mainly through the $d$-$p$ transfer path, and that a photoexcited electron in the intermediate states 4 and 5 is delocalized mainly through the $D$-$P$ transfer path.
3.4 Calculated Results II: Mott-Hubbard Insulators

3.4.1 Nondegenerate $d^1$ system

Figure 3.6 shows calculated XAS, NXES and RXES spectra with nondegenerate models with $d^1$ filling, which simulates the $t_{2g}$ bands of Ti$_2$O$_3$. The parameters are taken as $v=2.0$, $\Delta=2.0$, $U_{dd}=4.0$ and $U_{dc}=6.0$ eV [109]. Because of $U_{dd}+\Delta>U_{dd}$, this system is in the MH regime in the Zaanen-Sawatzky-Allen diagram [22]. Note that the lowest charge excitation is made by inter-site $d$-$d$ excitations in this case. Then it is interesting to study RXES spectra of MH systems in the context of the nonlocal (or large-cluster) effects.

In the nondegenerate single-$M$ cluster model with $d^1$ filling, the only possible configuration in the intermediate state is $c_d^2$, so that we have the only single peak in XAS spectra in Fig. 3.6 (a). On the other hand, two configurations of $d^1$ and $d^2_L$ are possible in the final state. Thus, we observe the only inelastic peak due to charge-transfer

$$W_i = \sqrt{(\Delta+U_{dd})^2+8v^2} \approx 8.2 \text{ eV}$$

distant from the elastic line, and the RXES spectra exhibit necessarily only Raman component.

In the NXES spectrum in Fig. 3.6 we see a strong peak at about $-2$ eV and a weak structure at about $-10$ eV. The former corresponds to a $d^0$-dominant state, and the latter to a $d^1L$-dominant state.

In addition to the CT peak, the inter-site $d$-$d$ excitation should take part in RXES spectra in the multi-$M$ cluster model. There observed an inelastic peak approximately 4.4 eV distant from the elastic line in RXES spectra in Fig. 3.6 (b). While spectral weight of this peak is strong for lower $\Omega$’s up to 5, a structure about 10 eV distant from the elastic line is enhanced for $\Omega$’s higher than 5. To study these structures, we calculate valence photoemission spectra (PES) and Bremsstrahlung Isochromat spectra (BIS), whose spectral functions are written as

$$F_{\text{PES}}(k, \omega) = \sum_f |\langle f|d_{k,\uparrow}|g\rangle|^2 \delta(\omega+E_f-E_g)$$

(3.7)

$$F_{\text{BIS}}(k, \omega) = \sum_f |\langle f|d_{k,\uparrow}^\dagger|g\rangle|^2 \delta(\omega-E_f+E_g).$$

(3.8)

Figure 3.7 shows PES and BIS spectra, where we adopt a nondegenerate $d_8p_8$ cluster model with the same parameter to take more $k$-points. The figure clearly shows that the upper branch of the simple Bloch bands in the $U_{dd} \rightarrow 0$ limit (solid curves)

$$\epsilon^\pm(k) - \epsilon_0 = \frac{\Delta}{2} \left(1 \pm \sqrt{1+(4v/\Delta)^2\cos^2(k/2)}\right)$$

is substantially modified into the lower Hubbard band (LHB) and upper Hubbard band (UHB). Hence we attribute the aforementioned lower energy structure in RXES to a CT process, and the higher energy one to an inter-site $d$-$d$ transfer, which rules the Mott-Hubbard gap. We call the former one “CT” and the latter “MH” hereafter. Furthermore, the intense peak at $-4$ eV in the NXES spectrum (Fig. 3.6 (b)) is attributed to a radiative transition from LHB, whereas a bump in its low energy tail to a radiative transition from the lowest valence band. The difference in intensity is naturally explained by difference in $d$-weight of these bands.

Although the MH structure in Fig. 3.6 (b) is composed of the single line, there should be generally energy dispersion in this structure. To confirm this, we show XAS and RXES spectra calculated with
Figure 3.6: XAS, RXES and NXES spectra calculated with nondegenerate models under $d^1$ filling, (a) the single-$M$ and (b) $d_4p_4$ periodic clusters. See the caption for Fig. 3.3.
Figure 3.7: PES and BIS spectra calculated with the $d_8p_8$ nondegenerate chain. The calculated spikes are convoluted with Lorentzian 0.2 eV (HWHM). The solid curves show the Bloch bands in the $U_{dd} \to 0$ limit. The arrows show the upper and lower Hubbard bands. The Fermi level is represented with the dotted line. We take $\varepsilon_0$ as the origin of the energy.
the $d_8p_8$ cluster in Fig. 3.8, where all RXES spectra are plotted as a function of Raman shift. The MH structure is clearly seen at about $-3.5 \text{ eV}$, and the CT structure at about $-9.5 \text{ eV}$. We observe energy dispersion of the MH structure for spectra 4 and 5. Corresponding to the fact that only $|cd^2\rangle$ is possible in the single-$M$ cluster limit, the XAS spectrum has the strong peak labeled with M, as in Fig. 3.6 (b). The additional peaks are also observed in its high energy tail. Their characters are depicted schematically in Fig. 3.9 (a), where each transition process between many-body states is mapped into a counterpart in the one-electron picture. In the states corresponding to the main peak M and the very weak satellite peak S, the core hole is mainly screened by the photoexcited electron itself. The peaks 4 and 5 correspond to the excitation to UHB. These are necessarily delocalized and poorly-screened. The peaks 2 and 3 have an intermediate character of the two states, and they are irrelevant to be depicted as a one-electron process.

Similarly, RXES final states are visualized in Fig. 3.9 (b) in terms of the one-electron density of states. The MH structure is related to one electron-hole pair creation between UHB and LHB, whereas the CT one between UHB and the filled ligand band. The dispersive $\Omega$-dependence for the spectra 4 and 5 is directly associated with energy dispersion of UHB. Although this behavior is somewhat similar to the fluorescence-like spectra, its energy width is too narrow under the realistic parameter set for Ti oxides \(^5\) to explain the experimental trend of, e.g., Ti$_2$O$_3$ [108].

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\(^5\)This is still true also for the larger value of $v=3.5 \text{ eV}$, which roughly simulates both $e_g$ and $t_{2g}$ orbitals.
Figure 3.9: Schematic explanation of representative final states in XAS and RXES spectra. The shaded and blank areas show occupied and unoccupied densities of states, respectively. The closed and open circles represent an electron and hole, respectively. (a) In the intermediate (XAS final) state, a core electron is photoexcited to bound states (represented with bars) or UHB. The labels M, S, 4 and 5 correspond to those in Fig. 3.8. (b) An electron-hole pair is left in the final state.

3.4.2 Degenerate $d^1$ system

Figure 3.10 shows XAS, NXES and RXES spectra calculated with degenerate single-$M$ cluster and $d_4 p_4$ models with $d^1$ filling. We fixed $S_z=1/2$ for the single-$M$ cluster calculation.

Let us first consider the single-$M$ cluster case. We see that the main manifold of XAS spectra exhibits a doubly-peaked structure. This is consistent to the $d^0$ calculation, but the lower energy absorption peak is considerably suppressed because of larger occupation number in the lower energy $d$-orbital. We also see that the higher branch of the main manifold in Fig. 3.10 (a) is composed of a few peaks with extremely small energy separation. This is attributed to the contribution of spin multiplet. When $\Omega$ is tuned at these peaks, the resultant final state would have large $D^1$ weight. Thus a strong inelastic peak observed 2.5 eV distant from the elastic peak in RXES spectrum 2 is attributed to the intra-site $d$-$d$ excitation, which has been shown in Fig. 1.8 (left). We denote this excitation by “$d$-$d$” hereafter. Note that the value 2.5 eV is the same order of $10Dq$, but from a quantitative point of view, it considerably deviates from $10Dq$ because of relatively large anisotropy of hybridization $v_1$ and $v_2$.

In addition to the $d$-$d$ peak, another structure is observed about 10 eV distant from the elastic line. This is attributed to charge-transfer to the metal site from the neighboring ligand sites. To study the origin of inelastic peaks more clearly, we arrange the same RXES spectra with Raman shift in Fig. 3.11 (a), where one sees that the CT structure is distributed over about 4 eV. Unlike the $d^0$ case, the permutation symmetry does not rule the separation between antibonding and nonbonding states when a finite $10Dq$ works, because the unperturbed state $|\psi_1\rangle \equiv d^\dagger_1 p_{\sigma} |11\rangle$ is not symmetric. Within the two-configuration approximation, there are two other state vectors, which have the same point group symmetry as $|\psi_1\rangle$,

$$|2_1 1\rangle \equiv d^\dagger_1 p_{\sigma} |11\rangle$$

$$|2_1 2\rangle \equiv \frac{1}{\sqrt{2}} \sum_{\sigma} D_{\sigma\sigma}^1 P_{\sigma} |11\rangle.$$
Figure 3.10: XAS, RXES and NXES spectra calculated with the degenerate models under $d^1$ filling, (a) the single-$M$ and (b) $d_4p_4$ periodic clusters. See the caption for Fig. 3.3.
Both of them have a doubly-occupied metal site. Consider a linear combination of these vectors, $|2_1\rangle$, under condition such that $|\langle 2_1 | H |1_1\rangle|$ is maximized. Following the effective hybridization theory, we have

$$|2_1\rangle = \frac{2}{V_{\text{eff}}(d^l)} \left( v_1 |2_1\rangle + \sqrt{2} v_2 |2_2\rangle \right),$$

where

$$V_{\text{eff}}(d^l) \equiv \sqrt{(2v_1)^2 + 2(2v_2)^2}.$$

Diagonalizing $2 \times 2$ Hamiltonian spanned by $\{ |1_1\rangle, |2_1\rangle \}$, we have bonding-antibonding separation

$$W_1 \simeq \sqrt{(\Delta + U_{dd})^2 + 4V_{\text{eff}}^2},$$

which is the same order of $W_0$. A peak at $-12.6$ eV labeled with “AB” in Fig. 3.11 (a) originates from this antibonding state, and it is strongly enhanced when $\Omega$ is tuned at the satellite structures 5 and 6, being consistent to the $d^0$ case. This is also described in Fig. 3.10 (a) with the shaded bars.

In this context, we consider the state orthogonal to $|2_1\rangle$ as the nonbonding state in the truncated Hilbert space,

$$|N2_1\rangle = \frac{2}{V_{\text{eff}}(d^l)} \left( -\sqrt{2} v_2 |2_1\rangle + v_1 |2_2\rangle \right).$$

This corresponds to a peak at $-8.8$ eV, which is strongly enhanced in the RXES spectrum 4. This fact suggests that the absorption spectra in the vicinity of the arrow labeled with 4 has also nonbonding character. In fact, it has relatively large weight in $|cD^1; d^2p\rangle$, which gives rise to relatively large $|2_1\rangle$ weight after radiative transition of the $D$ electron.

There is another class of nonbonding states, which has different point group symmetry from $|g\rangle$. When $\Omega$ is tuned at the main absorption peaks, it is this class of states that are the most strongly enhanced, as in the $d^0$ case. Corresponding to $|N1_0\rangle$ and $|N1_2\rangle$, state vectors such as

$$|N1_1\rangle \equiv d|p|1_1\rangle$$

$$|N1_2\rangle \equiv \frac{1}{\sqrt{2}} \sum_{\sigma} D^{\dagger}_{\sigma} p_{\sigma}|1_1\rangle$$

are of this kind. The former contributes to an inelastic peak at $-9.3$ eV when $\Omega$ is tuned at the peak 1, whereas the latter contributes an inelastic peak at $-11.3$ eV when $\Omega$ is tuned at the peak 2. The energy separation between them is naturally attributed to $10Dq$.

Apart from the $d-d$ structure, the $\Omega$ dependence of RXES spectra has much in common with the $d^0$ spectra in Fig. 3.4 (a) rather than the nondegenerate calculation in Fig. 3.6 (a). The multi-$M$ cluster ($d_4p_4$) results are shown in Figs. 3.10 (b) and 3.11 (b). In contrast to the single-$M$ cluster results, we observe fluorescence-like behavior there. Note that the nondegenerate multi-$M$ cluster calculation in Fig. 3.6 (b) exhibits no such behavior. Thus we conclude that it is essential for the appearance of the fluorescence-like spectra in $d^1$ systems to include orbital degeneracy.

The other large-cluster effect is inelastic peaks due to inter-site $d-d$ excitations. Compare Fig. 3.11 (b) with Fig. 3.8. As explained, the latter model is regarded as a truncated model to include only the $d-p$ transfer path of the former. We notice that a bump at about $-4$ eV in Fig. 3.11 (b) for RXES spectra 1, 2, 3 and 4. This is attributed to the inter-site $d-d$ excitation, and labeled with “MH”, as in Fig. 3.8. Although the MH structure is separated from the CT structure in Fig. 3.8, one observes that the center
of the spectral weight moves to lower energy roughly proportional to $\Omega$, from MH to CT structure and beyond, resulting in the fluorescence-like spectra in Fig. 3.11 (b).

On the other hand, we see that a structure at about $-10$ eV is enhanced for 1 and 2, and a structure at about $-11.9$ eV is enhanced for 3. This is explained by the enhancement of the nonbonding states which originate from $|N_1\rangle$, $|N_1\rangle$ and $|N_2\rangle$. We also observe an isolated peak at $-1.4$ due to the intra-site $d-d$ excitation. The resonance enhancement of the antibonding peak is also observed for the spectrum 7, as expressed with the shaded bar in Fig. 3.10 (b). Figure 3.11 (b) is very intriguing in that these structures of local origin, which are successfully explained with single-$M$ cluster model, coexist with the aforementioned structures due to inter-site effects.

3.5 Discussion

3.5.1 $d^0$ system

We defined a nonbonding state as that state which has no or little hybridization matrix element with the ground state. Mathematically, this definition may hold in realistic three-dimensional systems. Figures 3.4 (a) and (b) show slight $\Omega$-dependence in the nonbonding structure, where the spectral weight moves from higher energy to lower energy branch of the nonbonding peaks in going from the spectrum 1 to 3. As discussed within the single-$M$ cluster model, the energy separation between the two nonbonding states, which originate from $|N_1\rangle$ and $|N_1\rangle$, is attributed mainly to $10D_q$. While this kind of $\Omega$-dependence is consistent to experimental feature [106], the calculated spectra show considerable cluster size dependence of the separation. This is an example that a feature of local origin is renormalized by multi-$M$ cluster effects. Apart from this kind of slight dependence, the fact that $\Omega$-dependence of the nonbonding structure is not very strong in experimental Ti $3d-2p$ RXES of TiO$_2$ [106] suggests that the nonbonding structure is composed of states with various symmetries, and these states are highly smeared out by O $2p$ band effects.

The latest experimental data on Ti $3d-2p$ RXES of TiO$_2$ [106] shows a strong resonance enhancement of a peak 14 eV distant from the elastic line when $\Omega$ is tuned at the satellite structure of the XAS spectrum under a polarized configuration. This enhancement is not observed in Fig. 1.6, where the depolarized configuration is adopted. This fact means that the CT excited state corresponding to the 14 eV peak is the same symmetry as $|g\rangle$, and we naturally attribute it to the antibonding state, whose origin is the higher energy eigenstate in the truncated Hilbert space spanned by $|0\rangle$ and $|1\rangle$. Despite of its simplicity, our model well explains the essential physics of the experimental 14 eV enhancement. Note that spinless exciton models [103] can not describe the CT satellite of XAS, and therefore by no means describe the experimental polarization dependence.

There had been a controversy on the origin of the satellite structure of Ti $2p$-XPS or $2p$-XAS of TiO$_2$ [49, 112]. Okada and Kotani conclusively demonstrated that it is the CT satellite by their theoretical analysis with a TiO$_6$ cluster model [49]. With this regard, the polarization dependence of RXES when $\Omega$ is tuned at the satellite structure is significant in that it dramatically proves its character as the CT satellite. Moreover, the large bonding-antibonding separation offers evidence that TiO$_2$ is in the strong hybridization regime. Thus, parameter estimations based on the atomic picture would be subtle in many cases.

Apart from the fluorescence-like behavior, the single-$M$ cluster model well explained the $\Omega$-
Figure 3.11: RXES and XAS spectra for \(d^1\) filling calculated with (a) the degenerate single-\(M\) and (b) degenerate \(d_4p_4\) cluster models. All \(a_i\) and \(b_i\) are set to be unity, and all excitation energies and the numbers attached to the arrows are the same as in Fig. 3.10. See the caption for Fig. 3.3.
dependence of RXES spectra calculated with the multi-\(M\) cluster model. This means that the local transition picture as shown in Fig. 3.5 is at least partly applicable to the Raman component despite the translational symmetry of the system. This is a consequence of the special feature of RXES that reflects local as well as itinerant nature of the system.

We comment on the relative intensity of the structures of local origin, i.e. the antibonding and non-bonding structures. Comparing Fig. 3.3 with Fig. 3.4, we see that they are clearer in the latter than in the former. This suggests a trend that the more available internal degrees of freedom a unit cluster has, the more weight of spectra of local origin is observed. The reason is naturally related to the number of transition paths.

3.5.2 \(d^1\) system

We demonstrated the appearance of the intra-site \(d-d\) excitation in RXES spectra for \(d^1\) systems. Recently Higuchi et al. reported that intensity of a peak 2.3 eV distant from the elastic line increases with La doping for \(\text{SrTiO}_3\) [113]. Since \(\text{La}_x\text{Sr}_{1-x}\text{TiO}_3\) has nominally \(d^x\) filling, their explanation that the 2.3 eV peak is caused by the intra-site \(t_{2g} \rightarrow e_g\) transition (see Fig.1.8) seems to be natural. While they made estimation of the value of 10\(Dq\) simply as 2.3 eV, Fig. 3.11 shows considerable cluster size dependence of its energy separation from the elastic line. We have the value of 2.5 eV with the single-\(M\) cluster model, whereas 1.4 eV with the multi-\(M\) cluster model. Although the latter is fairly close to the actual value 10\(Dq\)=1.7 eV, whether or not this is the case in realistic three-dimensional systems is unclear because whether it gets smaller or larger would greatly depend on a band structure. What we can say definitely is that the anisotropy between \(t_{2g}\) and \(e_g\) orbitals play a certain role.

Experimentally observed \(d-d\) peak in Ti 3d-2\(p\) RXES of \(\text{Ti}_2\text{O}_3\) [108] is much weaker than other inelastic spectra even when \(\Omega\) is tuned at the \(e_g\) peak in XAS. Figure 3.11 shows, however, a strong \(d-d\) structure. This discrepancy is partly attributed to larger probability for electrons to occupy a \(d\) (or \(t_{2g}\)) orbital in \(|g\rangle\)\(^6\). In the weak hybridization limit, \(|g\rangle\) is trivially \(d^{\dagger}_d|d^0\rangle\), which gives the probability of 1/2 to occupy up or down \(d\) orbital. In realistic \(\text{Ti}_2\text{O}_3\), the probability is only 1/6, resulting in smaller amplitude of the transition from a \(t_{2g}\) to a core orbital. In this context, the maximum intensity of the \(d-d\) peak would get larger with increasing the occupation number of \(t_{2g}\) orbitals, i.e., \(\text{Ti}_2\text{O}_3 < \text{V}_2\text{O}_3 < \text{Cr}_2\text{O}_3\), etc.

For the CT structure, Fig. 3.10 shows \(\Omega\)-dependence similar to the results of the \(d^0\) systems in Fig. 3.4. This is related to the fact that we can successfully define the antibonding state as explained in the preceding section. The lower symmetry of the unperturbed \(d^1\) state, however, disturbs the resonance enhancement of the antibonding peak as compared to \(d^0\). Analogous to \(\text{TiO}_2\), there is a broad satellite structure in experimental Ti 2\(p\)-XAS of \(\text{Ti}_2\text{O}_3\) [108]. Our results on \(d^1\) systems predict that polarization dependence of the antibonding peak should be observed when \(\Omega\) is tuned at the satellite structure.

For band insulators, we have confirmed that spatially extended states are in the high energy tail of the main manifold of XAS, and that these states maintain the one-electron character to great extent against the strong \(U_{dd}\) and \(U_{dc}\). While we have some extended states also for MH insulators, they are quite unlike the simple one-electron states, but complicated many-electron states involving excitations in the Hubbard bands. It is not necessarily clear what kinds of extended states are created when orbital degeneracies are introduced in. What one can definitely say is that the orbital degrees of freedom relaxes

\(^6\)Polarization dependence is another possible reason.
the reduction effect due to the Pauli principle, and therefore encourages the dissipation of a photoexcited electron. In any case, the existence of highly delocalized states that are densely distributed over finite width in an absorption threshold is a necessary condition to display the fluorescence-like component in RXES spectra.

3.6 Conclusions

We have discussed the role of orbital degeneracy in metal 3d-2p RXES with periodic multi-M cluster models under \( d^0 \) and \( d^1 \) fillings. We first investigated \( d^0 \) systems with a single-\( M \) cluster model. Calculated RXES spectra showed only Raman component, which is composed of antibonding and nonbonding states. The origin of the antibonding state comes from totally symmetric states as to the permutation of degenerate orbitals, whereas that of the nonbonding state comes from those states which have different symmetry from the unperturbed ground state \( |d^0\rangle \). This mathematical definition well explains the \( \Omega \)-dependence of RXES spectra, which is quantitatively consistent to the experimentally observed resonance enhancement of the antibonding state under a polarized configuration.

With a degenerate multi-\( M \) cluster model, we demonstrated that the above properties of local origin are substantially conserved in RXES spectra. Large-cluster effects, however, were observed, first, in the modulation of intensity ratio between two main absorption peaks, and second, in the reduction of the peak separation in the nonbonding structure. Moreover, third, we again confirmed the appearance of the fluorescence-like RXES spectra, which is completely missing in the single-\( M \) cluster results. Our result is the first calculation that demonstrates the coexistence of the fluorescence-like and Raman components with a periodic Anderson model.

Next we showed calculated results for \( d^1 \) systems. RXES spectra calculated with nondegenerate models exhibit only Raman component for both single- and even multi-\( M \) cluster models, but the latter results show considerable \( \Omega \)-dependence. While a structure due to inter-site \( d-d \) transition is enhanced for lower \( \Omega \), a structure due to CT is enhanced for higher \( \Omega \). Although energy dispersion of UHB slightly reflects on the \( \Omega \)-dependence, it is too small to explain the occurrence of fluorescence-like spectra in realistic parameter set for Ti oxides.

The most remarkable effect of orbital degeneracy is the appearance of the fluorescence-like spectra in the multi-\( M \) cluster calculation, being qualitatively consistent to experimental spectra. The naive conjecture that effective hopping energy reduced by \( d-d \) on-site Coulomb interaction hinders the appearance of the fluorescence-like behavior does not hold when the orbital degeneracy is introduced. This result demonstrates the essential importance of the orbital degeneracy as well as the translational symmetry. The appearance of the fluorescence-like spectra seems to be a general phenomenon that is observed wherever highly delocalized continuum states exist.

In addition to the fluorescence-like spectra, the orbital degeneracy gives rise to, first, a peak due to the intra-site \( d-d \) excitation. The separation between this peak and the elastic line is of order of \( 10Dq \), but it considerably depends on cluster size. Second, nonbonding states as well as the antibonding state contribute to inelastic spectra. Despite the difference in symmetry of the ground state, the calculated results show \( \Omega \)-dependence similar to the \( d^0 \) case, from which resonance enhancement of the antibonding peak is predicted when \( \Omega \) is tuned at the XAS satellite structure under polarized configurations.
Chapter 4

Local and Nonlocal Excitations in Cu $4p-1s$ Resonant X-Ray Emission Spectra of Nd$_2$CuO$_4$

Theoretical study on Cu $4p$-$1s$ RXES of Nd$_2$CuO$_4$ is given in the context of local and nonlocal natures of electronic excitations. Detailed analyses with an impurity Anderson model and multi-Cu models are presented, based on the exact diagonalization technique. By investigating partial densities of states, substantial characters of each excited state are clarified. It is demonstrated that a disagreement with experimental data is unavoidable with the impurity model. The key concept to solve the difficulty is Zhang-Rice singlet formation in the intermediate state of RXES. We find that it survives in the final state of RXES as the lowest charge-transfer excitation. The limitation of the impurity model and the essential role of nonlocal excitations in RXES are stressed.

4.1 Introduction

Nd$_2$CuO$_4$ is well known as a mother material of $n$-type superconductor, Nd$_{2-x}$Ce$_x$CuO$_{4-y}$ [114], which has attracted special attention in the context of appearance of the electron-hole symmetry [115], a character which single-band models should have. Nd$_2$CuO$_4$ has two-dimensional (2D) corner-shared CuO$_2$ planes with nominally $d^9$ configuration, which is believed to be essential for high-$T_c$ superconductivity. Recently, Cu $4p$-$1s$ RXES of Nd$_2$CuO$_4$ has been measured by Hill and coworkers [116]. The Cu $4p$-$1s$ RXES process is schematically shown in Fig. 4.1. A completely localized $1s$ core electron is resonantly excited to an empty $4p$ conduction band by an incident photon ($\sim$ 9 keV), and then the excited $4p$ electron radiatively comes back to the $1s$ core orbital. In the intermediate state (Fig. 4.1 (b)), a valence hole on the core hole site is strongly scattered to move away to surrounding sites, so that the dynamics of the “dopant” hole such as Zhang-Rice (ZR) singlet formation [43] would be strongly reflected on the RXES spectra. It is interesting to see how the ZR singlet state decays or survives with going to the final states, and to examine what kind of state is created above the insulating gap through varying the incident photon energy.

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Figure 4.1: Schematic diagram of Cu 1s-4p-1s RXES process. The blank circle and blank arrows represent a 1s core hole and up- or down-spin valence holes, respectively. The shaded circles represent 1s or 4p electrons. (a) The ground state with antiferromagnetic order. (b) The intermediate state, where a photon excited a 1s-electron to an empty 4p level (the 4p band width is disregarded in this figure), creating a 1s core hole. The strong repulsive interaction $U_{dc}$ between 3d and 1s holes gives rise to a charge-transfer (CT) excitation. There is also attractive interaction $U_{4p3d}$ between 4p electron and 3d hole, but it can not completely compensate $U_{dc}$. (c) The final state with a CT excitation. The energy difference between the final and ground states is observed as energy loss of the X-ray.

Figure 4.2 shows the experimental data of the Cu 4p$\pi$-1s RXES of Nd$_2$CuO$_4$ [116]. The abscissa is the energy loss of X-ray, which is the same as the energy difference between the initial and final electronic states, $E_f - E_g$. The incident photon energy is taken in the region of Cu 1s-4p$\pi$ XAS, which is shown in the upper panels of Fig. 4.3 with the open circles. The first (at 8984 eV) and second (at 8990 eV) features of the Cu 1s-4p$\pi$ XAS are denoted by a main peak and a satellite, respectively. It is seen in Fig. 4.2 that an inelastic structure at about 6 eV is observed for 8987.5, 8989 and 8990 eV in addition to the extremely strong elastic peak at zero. The incident photon energy dependence of the 6 eV excitation is shown in the lower panels of Fig. 4.3 with the open circles. We recognize that the 6 eV intensity is strongly enhanced when the incident photon energy is tuned at the satellite of the XAS spectrum, but it indicates almost no enhancement at the main peak position.

The aim of this chapter is to give a theoretical interpretation for these experimental data. We will first analyze the experimental data with an impurity Anderson model. The calculated results will be in fair agreement with the experiment, but there exists a conspicuous difference between the theoretical and experimental results: The calculated 6 eV intensity shows a considerable enhancement at the main peak position. In order to remove this discrepancy, we will next use a multi-Cu cluster model. It will be shown that the 6 eV intensity is strongly suppressed at the main peak resonance because of the formation of a ZR singlet in the intermediate state.

The layout of the present chapter is as follows: In the next section, the models used are explained.

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$^2$It equals $-1 \times$ (Raman shift). Although the calculated RXES spectra will be arranged as a function of this quantity to compare with the experimental data, we hope that the readers do not confuse them.
Numerical analysis with the impurity Anderson model is described in §4.3. We discuss in §4.4 the role of the nonlocal screening effects with multi-Cu cluster models. In the last section a brief summary of the present study is given.

Figure 4.2: Cu 4$p_{\pi}$-1$s$ RXES of Nd$_2$CuO$_4$ [116] as a function of energy loss. Incident photon energies are tuned in the range of 1$s$-4$p_{\pi}$ absorption. The polarization vector of the incident X-ray has an angle 60° to the CuO$_2$ planes, and its momentum-transfer is perpendicular to those (see Fig. 5.2 (a)). The excitation energies are indicated in the upper panels of Fig. 4.3 with vertical bars.

### 4.2 Formulation

We consider a 2D extended periodic Anderson model including Cu 1$s$ and Cu 4$p$ orbitals, as shown in Fig. 4.4. The explicit form of the Hamiltonian is as follows:

$$H = H_{dp} + H_{pp} + H_{core} + H_{dc} + H_{4p} + H_{4pc} + H_{4p3d},$$

where

$$H_{dp} = -\Delta \sum_{R,\sigma} d_{\sigma R}^\dagger d_{\sigma R} + T_{pp} \sum_{\langle r, r' \rangle, \sigma} (-1)^{\alpha_1} \left[ p_{\sigma r}^\dagger p_{\sigma r'} + H.c. \right]$$

$$+ T_{pd} \sum_{\langle r, r' \rangle, \sigma} (-1)^{\alpha_2} \left[ d_{\sigma R}^\dagger p_{\sigma r} + H.c. \right] + U_{dd} \sum_{R} d_i^\dagger_{R} d_i^\dagger_{R} d_i_{R} d_i_{R},$$

$$H_{pp} = U_{pp} \sum_{r} p_{\uparrow r}^\dagger p_{\uparrow r} p_{\downarrow r}^\dagger p_{\downarrow r}.$$
Figure 4.3: (a) Lower panel: The 6 eV intensity as a function of the incident photon energy in Cu 4\(\rho_\pi\)-1s RXES of Nd\(_2\)CuO\(_4\). The open circles represent the experimental result by Hill et al. [116]. The solid and dashed curves represent calculated results with a Cu\(_1\)O\(_{256}\) cluster for \(R_c = 0.8\) and 1.0, respectively. In accordance with the experimental resolution [116], all the calculations are convoluted with Gaussian \(\Gamma_G = 0.95\) eV (HWHM) for the scattered photon, and \(\Gamma_G = 0.3\) eV for the incident photon. Upper panel: The open circles represent experimental Cu K-XAS of Nd\(_2\)CuO\(_4\) [117], where the polarization vector of the X-ray is 60° to the CuO\(_2\) plane (see Fig. 5.2 (a)). The definition of the two curves are the same as the lower panel, although they are convoluted with Lorentzian \(\Gamma_L = 0.8\) eV (HWHM) to take in lifetime effects, and further with \(\Gamma_G = 0.8\) eV to reproduce the experimental line width. (b) The same as (a), but calculated curves are obtained with a Cu\(_5\)O\(_{16}\) cluster. The calculated XAS spectra are broadened with \(\Gamma_L = 0.8\) eV and \(\Gamma_G = 1.2\) eV.
\[ H_{\text{core}} = e_{1s} \sum_{R} S_{R}^{i} S_{R}, \]  

and

\[ H_{dc} = U_{dc} \sum_{R} \left( \sum_{\sigma} d_{\sigma R}^{\dagger} d_{\sigma R} \right) S_{R}^{i} S_{R}^{j}. \]  

In these equations, \( d_{\sigma R}^{\dagger} \) creates a Cu \( d_{x^2-y^2} \) hole with \( \sigma \) spin at \( R \) site and \( p_{\sigma R}^{\dagger} \) creates a \( \sigma \)-bonded O 2\( p \) hole with \( \sigma \) spin at \( r \) site. \( \Delta (> 0) \) is the charge-transfer (CT) energy between the \( p \) and \( d \) orbitals, and intersite hopping energy \( T_{pp} \) and \( T_{pd} \) are related with the Slater-Koster parameters [118] as \( T_{pp} = [(pp\pi) - (pp\sigma)]/2 \) and \( T_{pd} = \sqrt{3}(pd\sigma)/2 \). The signs of \( T_{pp} \) and \( T_{pd} \) are described by \( \alpha_1 \) and \( \alpha_2 \), which are 0 or 1, depending on the relative position of a nearest-neighbor O-O and Cu-Cu pair, respectively. \( S_{R}^{i} \) creates a Cu 1\( s \) electron at \( R \) site. \( U_{dd} \) and \( U_{dc} \) are on-site Cu 3\( d \)-3\( d \) and Cu 3\( d \)-1\( s \) Coulomb repulsion energies, respectively.

Figure 4.4: Geometry of the system. (a) Orbitals in the model. O 2\( p \) and Cu \{1\( s \), 3\( d \)(\( b_{1g} \)), 4\( p \)\} orbitals are taken into account. The blank (shaded) area of the ellipses represents positive (negative) phase. (b) The Cu\( _{5} \)O\( _{16} \) cluster with open boundary condition. The oxygen sites are discriminated with \{\( a_{i}, b_{i}, c_{i} \}\) to construct molecular orbitals in the next section.

Generally, Cu 4\( p \) states are split off into \( \alpha_{1} (4p_{x}) \) and \( e \) (4\( p \)) symmetries in terms of the local D\( _{4h} \) irreducible representations. For 4\( p \)-1\( s \) RXES of Nd\(_{2}\)CuO\(_{4}\), however, both contributions are separable because there is no overlap between the experimental 4\( p \) and 4\( p \) absorption threshold. We only take into account the 1\( s \)-4\( p \)-1\( s \) transition process. The polarization dependence of Cu 4\( p \)-1\( s \) RXES will be discussed in the next chapter. Then \( H_{4p} \) is given by

\[ H_{4p} = e_{4p\pi} \sum_{R} Q_{R}^{4p\pi} Q_{R} + t_{0} \sum_{(R,R')} Q_{R}^{4p\pi} Q_{R'}, \]  

where \( Q_{R}^{4p\pi} \) creates a Cu 4\( p \)\_\( \pi \) electron at \( R \) site, \( t_{0} \) is 4\( p \)–4\( p \) nearest-neighbor hopping energy.

\( H_{4pc} \) and \( H_{4pc,3d} \) describe Cu 4\( p \)\_1\( s \) and Cu 4\( p \)\_3\( d \) intra-atomic interactions, respectively. The explicit forms are

\[ H_{4pc} = -U_{4pc} \sum_{R} Q_{R}^{4p\pi} S_{R}^{4p\pi} S_{R}^{4p\pi}. \]
\[ H_{4p3d} = -U_{4p3d} \sum_{R} Q_R^1 Q_R \sum_{\sigma} d_{R \sigma R}^d d_{R \sigma}. \] (4.7)

In accordance with systematics of high-\(T_c\) compounds discussed by Ohta et al. [119] and with an \textit{ab initio} calculation [120], we set the valence electron parameters for large-cluster calculations of Nd$_2$CuO$_4$ as \( \Delta = 2.5, T_{pd} = 1.21, T_{pp} = 0.55 \) and \( U_{dd} = 2U_{pp} = 8.8 \) [eV]. A band calculation for Nd$_2$CuO$_4$ [121] gave the $4p_{\pi}$ band width \( W_{\pi} = 2.5 \). Thereby we estimate \( t_0 = 0.3 \) eV, along with one-electron formula of the bandwidth \( W_{\pi} = 8t_0 \). \( U_{dc}, U_{4p3d} \) and \( U_{4p\sigma} \) are set to be 7.5, 3.0 and 4.0 [eV].

As far as the $1s$-$4p_{\pi}$ absorption process is concerned, the absorption operator \( T_a \) is given by

\[ T_a = \sum_R e^{-i q_1 \cdot R} Q_R^1 S_R, \] (4.8)

where \( q_1 \) is the wave vector of the incident photon. The emission operator \( T_e \) is defined as \((T_a)^\dagger\) with the substitution of \( q_1 \) with \( q_2 \), which is the wave vector of the emitted photon. Then the transition operator of the $4p_{\pi}$-$1s$ RXES can be written as

\[ T(\Omega) = \sum_R S_R^\dagger Q_R G_0(\Omega) Q_R^1 S_R, \] (4.9)

where \( G_0(\Omega) \) is the resolvent operator defined as \( G_0(\Omega) = (\Omega + E_g - H + i\Gamma)^{-1} \). \( E_g \) and \( \Omega \) are energies of the ground state and the incident photon, respectively. We set \( \Gamma = 0.8 \) eV in the present calculations, considering semi-empirical data of the Auger process [122], and another calculation of RXES for $3d$ systems [123]. In the above equation, we assume that \( q = q_2 - q_1 \) is perpendicular to the CuO$_2$ plane in accordance with the experiment. The polarization dependence [117] and the \( q \) dependence [152] of RXES will be discussed in the next chapter. To make sure, the explicit forms of spectral functions of XAS and RXES are

\[ F_{\text{XAS}}(\Omega) = \sum_{\mu} |\langle \mu | T_a | g \rangle|^2 \delta(\Omega + E_{\mu} - E_g) \] (4.10)

and

\[ F_{\text{RXES}}(\omega; \Omega) = \frac{1}{N} \sum_{f \neq g} |\langle f | T(\Omega) | g \rangle|^2 \delta(\omega - \Omega + E_f - E_g), \] (4.11)

where \( E_{\mu} (E_f) \) is a final state energy of XAS (RXES), and \( \omega \) denotes the emitted photon energy. \( N \) is the number of the Cu atoms.
4.3 Analysis with Impurity Anderson Model

4.3.1 Properties of eigenstates

It is well-known that the eigenequation of the impurity Anderson model is exactly constructed as \( x - \varepsilon_d = \Sigma_s(x) \), where \( \varepsilon_d \) is unperturbed energy of the \( d \) orbital, and \( \Sigma_s(x) \) is the self-energy function [124]:

\[
\Sigma_s(x) = \frac{1}{N} \sum_{jk} \frac{|V_{jk}|^2}{x - \varepsilon_{jk} - \delta i}.
\]

For the 2D periodic system with Cu-O distance \( a \), there are two oxygen 2p bands:

\[
\varepsilon_{jk} = \begin{cases} 
4T_{pp} \sin(k_xa) \sin(k_ya), & j = 1 \\
-4T_{pp} \sin(k_xa) \sin(k_ya), & j = 2 
\end{cases}.
\]

For each band, the \( d-p \) hybridization energy is

\[
V_{jk} = \begin{cases} 
-\sqrt{2}iT_{pd}[-\sin(k_xa) + \sin(k_ya)], & j = 1 \\
-\sqrt{2}iT_{pd}[\sin(k_xa) + \sin(k_ya)], & j = 2 
\end{cases}.
\]

The graphical representation of the eigenequation is depicted in Fig. 4.5. We see that a bound state exists at \(-4.3 \text{ eV}\). This is the ground state \( |g\rangle \). The above equation still holds for the intermediate state under substitution of \( \varepsilon_d \) with \( \varepsilon_d + U_{dc} - U_{4p3d} \), as far as the energy dispersion of the \( 4p \) electron is neglected. In this case we have two bound states \( M \) and \( S \), as described in the figure.

In order to study properties of the eigenstates further, we calculate partial density of states (PDOS) which is defined as

\[
\rho_\phi (\varepsilon) = \sum_n |\langle \phi | \varepsilon_n \rangle|^2 \delta(\varepsilon - \varepsilon_n)
\] (4.12)

for a \( \phi \) orbital. \( |\varepsilon_n\rangle \) is an eigenstate of the system.  

By constructing molecular orbitals with \( b_{1g} \) symmetry around the impurity site, it can be easily shown that the impurity Anderson model is equivalent to the model shown in Fig. 4.6. \( A \) is the nearest-neighbor orbitals to the Cu site, which is defined by

\[
A^\dagger = \frac{1}{2} (-a_1^\dagger + a_2^\dagger + a_3^\dagger - a_4^\dagger).
\] (4.13)

Starting with this, we come to more accurate description of the whole system by taking \( B, C, \ldots \) molecular orbitals, where \( B \) and \( C \) are defined by

\[
B^\dagger = \frac{1}{\sqrt{8}} (b_1^\dagger - b_2^\dagger + b_3^\dagger - b_4^\dagger + b_5^\dagger - b_6^\dagger + b_7^\dagger - b_8^\dagger)
\] (4.14)

and

\[
C^\dagger = \frac{1}{2} (-c_1^\dagger + c_2^\dagger + c_3^\dagger - c_4^\dagger),
\] (4.15)

respectively. Since they span the complete set, note that a sum rule \( \Sigma_\phi \rho_\phi = \rho \) as well as \( \int d\varepsilon \rho_\phi = 1 \) holds, \( \rho \) representing the total density of states (TDOS).

---

\(^3\) Several authors have tried to decompose calculated spectra according to different point group symmetry, see e.g. Ref. [127]. We here define this function in order to investigate contribution of a set of state vectors with a same point group symmetry but different spatial extent.
Figure 4.5: Graphical representation of the eigenquations of the 2D impurity Anderson model with $4 \times 4$ oxygen network.

Figure 4.6: A equivalent model of the 2D impurity Anderson model. The closed and open circles represent the impurity $3d$ orbital and O $2p$ molecular orbitals, respectively. The diagonal elements of the equivalent Hamiltonian are described above each of the circles. The hybridization matrix elements are described below each bond, where $T_1 = \sqrt{2}T_{pp}$ and $T_2 = \sqrt{2}T_{pd}$. Note that there happen to be degeneracies in molecular orbitals beyond $C$. 
Figure 4.7 (a) shows PDOS of $3d$ and the $A$, $B$ and $C$ orbitals as well as TDOS for RXES final state. We see that $\rho_d$ and $\rho_A$ have definite peaks at the ground state and at around 5.2 eV. The energy separation is approximately equal with the value obtained from the formula of the bonding-antibonding separation \[ W = \sqrt{(-\Delta + 2T_{pp})^2 + 16T_{pd}^2} \]
in the simple CuO$_4$ cluster. This implies that the 5.2 eV peak corresponds to the antibonding state. Since these bonding and antibonding orbitals are just two ones in the simple CuO$_4$ cluster, the 5.2 eV excitation is nearly local, i.e. the hole spend most of its time at the plaquette with the impurity.$^4$

On the other hand, we notice that the state at about 2 eV has little $d$ and $A$ weight. This means that it is a nearly pure $p$ state, which has little amplitude at the impurity plaquette. In other words, it is a nonlocally excited state. This character makes a sharp contrast to the ground state and the 5.2 eV excited state, and it is directly reflected in the $\Omega$ dependence of RXES.

\[ W = \sqrt{(-\Delta + 2T_{pp})^2 + 16T_{pd}^2} \]

Figure 4.7: (a) Total and partial densities of states of the impurity $3d$ orbital and O $2p$ molecular orbitals ($A$, $B$ and $C$) defined in the text. TDOS and PDOS’s are calculated with the impurity Anderson model with $N = 16 \times 16$ oxygen network, and they are convoluted with Lorentzian $\Gamma_L = 0.2$ eV (HWHM). All densities are normalized so that the integrated areas are to be unity. The shaded bars are guide to eye to represent unperturbed O $2p$ band width. (b) Total and partial densities of states (PDOS) in the intermediate state. The energy dispersion of the $4p$ electrons is disregarded for simplicity to calculate PDOS, but it is fully included to calculate XAS. The Cu $1s$-$4p_{e}$ XAS spectrum is convoluted with $\Gamma_L = 0.8$ eV. For both (a) and (b), the origin of the abscissa is adjusted to the lowest eigenenergy.

$^4$More exactly, this excitation energy, which corresponds to the experimental value 6 eV, depends on the model, and takes 5.2 eV for the impurity Anderson model, 5.5 eV for Cu$_3$O$_{10}$ cluster model and 5.7 eV for Cu$_5$O$_{16}$ cluster model.
4.3.2 XAS

Figure 4.7 (b) shows calculated Cu 1s-4p XAS and PDOS for the intermediate (XAS final) state. The energy dispersion of the 4p electron is neglected in the calculation of PDOS for simplicity, but it is fully included in that of XAS. We observe a doubly-peaked structure in the calculated XAS spectrum, which has been plotted with the dashed curve also in Fig. 4.3 (a). The energy separation between the main and satellite peaks is consistent to that of the experimental 1s-4p π XAS spectrum. If we subtract contribution of a steeply increasing background spectrum due to the secondary electron emission process [125, 126] from the experimental one, these two spectra would broadly agree.

We see that the major weight of the main peak of XAS, which is denoted by |M⟩ hereafter, lies on the A orbital. This is consistent with the standard notation cd10 in the electron picture, but there are no little weights in both d and C orbitals. The satellite peak of XAS, which is denoted by |S⟩ hereafter, is composed mainly of the d orbital and slightly of the A orbital, being consistent with the standard notation cd9.

As seen from Fig. 4.7 (a), |g⟩ as the initial state of XAS consists of d and A orbitals approximately in the ratio of 5 : 5. Large weight in these orbitals is a necessary condition to have a strong intensity in XAS. Although |M⟩ and |S⟩ similarly fulfill the condition, Fig. 4.7 (b) shows that their XAS intensities are quite different. The reason comes from a phase cancellation mechanism. Both |g⟩ and |M⟩ are split-off states at lower energy side of the continuum, whereas |S⟩ is the split-off one at the opposite side. Thus we have considerable phase cancellation in the process |g⟩ → |S⟩.

4.3.3 RXES

Calculated results of the Cu 4p π-1s RXES are shown in Fig. 4.8, where CT excitations appear as inelastic spectra. The elastic peak is omitted from each spectrum. Roughly speaking, we have broader spectra when Ω is tuned at M, whereas a single feature at around 5.2 eV appears for other Ω. As discussed in the preceding subsection, the value 5.2 eV is nearly the same as the bonding-antibonding separation in CuO4 cluster. Within the present parameters, it is approximately given by \( W \approx 4T_{pd} \). The lowest position of the inelastic peak is estimated as the energy difference between the bottom of the p band and the bonding state in CuO4 cluster:

\[
-4T_{pp} - \frac{1}{2}(-\Delta - 2T_{pp} - W) \approx \frac{\Delta}{2} + 2T_{pd} - 3T_{pp}.
\]

This formula gives a rough estimation of the CT gap from the viewpoint of the impurity Anderson model. Since it is believed that \( (\Delta - 2T_{pp}) \) is the same order of \( T_{pd} \) for high-\( T_c \) compounds, note that a naive estimation \( \varepsilon_{gap} \approx \Delta \) which comes from the simple limit of weak d-p hybridization does not hold.

We now discuss the Ω dependence of RXES. First we consider the case when Ω is at |S⟩. This intermediate state is strongly localized in the impurity plaquette, as shown in Fig. 4.7 (b). Moreover, the phase of it matches the 5.2 eV excitation well by the aforementioned reason. Thus the main peak of RXES appears around 5.2 eV.

Second, |M⟩ has not a little weight in extended orbitals such as B. Since |M⟩ is much closer to the continuum than |g⟩ in Fig. 4.5, it well hybridizes with p orbitals. The limit \( U_{dc} \rightarrow \infty \) is helpful to illustrate the situation. The d hole is completely pushed out to the p bands in this case, naturally getting over the nearest-neighbor ligand orbital. In this sense, |M⟩ as well as the 2 eV excitation has a nonlocal character, through which the transition from |M⟩ to the states around 2 eV is caused. |M⟩ has also large
weight in $A$, so that the overlap with the 5.2 eV excitation is large, although there is no reason for the intensity enhancement by the phase matching in this case. This brings about the emission intensity around 5.2 eV, resulting in the broader spectra.

Finally, since the absorption intensity in the region between $|M\rangle$ and $|S\rangle$ is extremely small, spectral shapes of 2, 3 and 4 in Fig. 4.8 are substantially determined by virtual transition process, although the 2 eV excitation is slightly favorable for these intermediate states which have large extended $p$ weight.

$4.3.4$ Excitation energy dependence of the 5.2 eV intensity

Let us consider the mechanism of the $\Omega$-dependence of the inelastic peak intensity around 5.2 eV. For the CuO$_4$ cluster, there are only two states in the final states of RXES. The intermediate states are also spanned in two-dimensional Hilbert space as far as the energy dispersion of 4$p$ electron is disregarded, so that $|M\rangle\langle M| + |S\rangle\langle S| = 1$ holds. Since the line width $\Gamma$ is much smaller than the energy separation between $S$ and $M$, we have the following identity between transition amplitudes $|g\rangle \rightarrow |5.2\rangle$ through $M$ and $S$ intermediate states:

$$
\frac{1}{\Gamma} \langle 5.2|T_a|g\rangle = \frac{1}{\Gamma} \langle 5.2|T_a|M\rangle = \frac{1}{\Gamma} \langle 5.2|T_a|S\rangle = 0,
$$

which demonstrates that the two amplitudes are the same except for their signs, and thus the $\Omega$-scan of the 5.2 eV intensity takes a symmetric “U-shape”. We then take its asymmetry as a measure of nonlocal nature of excitations.

Figure 4.8: Calculated Cu $4p_{\pi}-1s$ RXES and XAS spectra for the Cu$_{d256}$ cluster (impurity Anderson model). The arrows indicate the incident photon energies, and their numbers correspond to those in RXES.
The Ω-scan is plotted in Fig. 4.3 (a) with the dashed curve. It shows that the scan takes almost the U-shape, and that the large-cluster effect with respect to O 2p band plays a minor role. It suggests that the transition process which gives the 5.2 eV excitation as a final state of RXES is mainly ruled by local orbitals such as d and A.

Recently Nakazawa et al. [94] pointed out the importance of configuration dependence of cation-ligand hybridization in Ce 4f-3d RXES of CeO2. In order to see the effect, we here introduce a parameter $R_c$, which renormalizes $T_{pd}$ of the plaquette with the core hole as $R_c \times T_{pd}$ in the intermediate (XAS final) states.

The calculated results with $R_c = 0.8$ are also given in Fig. 4.3 (a) (solid curve). All calculated scans are normalized so that each height of the maximum peak is the same. We see that $R_c \neq 1$ suppresses the 5.2 eV intensity (although the suppression is too small to reproduce the experimental result) when Ω is tuned around $|M\rangle$, and strengthens its asymmetry. The limit of $R_c \to 0$ helps to make the situation clear. Since the main peak of XAS has no d weight in this case, and moreover the orbital A is not stabilized through d-p hybridization, the extra p weight contained in the extended B, C, ... orbitals necessarily comes into the state to reduce the large A weight. Also for a finite $R_c$, it must work to increase the extended weight in $|M\rangle$. Thus overlap between $|M\rangle$ and the 5.2 eV excitation tends to be decreased by $R_c$ in comparison with that of $|S\rangle$. This is the explanation of the asymmetric shape of the Ω-scan of the 5.2 eV intensity.

Although the calculated XAS with the impurity Anderson model well reproduces the experimental main-satellite separation, there are considerable discrepancies with experimental data in the Ω-scan of the 5.2 eV intensity. When Ω is tuned at the main peak of XAS, the 5.2 eV intensity always exhibits one of the two peaks of the U-shape as far as the impurity Anderson model is used. The observed suppression effect can not be reproduced at all. This is nothing but an indication of a nonlocal effect (which is brought about by Zhang-Rice singlet formation) in the intermediate states of multi-Cu clusters, beyond the simple O 2p band effects. It will be discussed in the next section in detail.

4.4 Analysis with Multi-Cu Models

4.4.1 Properties of eigenstates

Considering the results with the impurity Anderson model and the experimental fact that an antiferromagnetic order of d holes is realized in $|g\rangle$, we are led to an idea that eigenstates of a multi-Cu cluster model are described as some superposition of those of each plaquette [129]. We expect that there are relatively local excitations around 5.2 eV, but somewhat new states should be created around 2 eV above $|g\rangle$ upon going from the impurity to the multi-Cu model.

In order to see the point in detail, we again calculate PDOS and TDOS for a Cu$_3$O$_{10}$ cluster with Householder method [79], based on the fact that spectra of Cu$_3$O$_{10}$ are essentially the same as that of Cu$_5$O$_{16}$. We choose

$$|\text{AF}\rangle = d_{1\downarrow}^\dagger d_{1\uparrow}^\dagger d_{0\downarrow}^\dagger |\text{vacuum}\rangle,$$

as a counterpart of $|d\rangle$ in the impurity model, and

$$|\text{A}^\prime\rangle = L_{0\downarrow}^\dagger d_{0\downarrow} |\text{AF}\rangle,$$

The present result is essentially the same as that given in Ref. [116] with an impurity Anderson model, but quantitatively they are slightly different because of a slightly different O 2p band model and slightly different parameter values.
where

\[ N \]  

quette to the surroundings, where the local singlet is formed. Hence the CT gap may be defined by the energy to move a hole from the bonding orbital at a plaquette to the surroundings, where the local singlet is formed. If \( 2T_{pd} \ll \Delta \) held as Zhang and Rice originally discussed [43], the binding energy of the local singlet would be estimated by their formula

In addition to these, we define also \( |B'\rangle = B_{0\sigma}^{\dagger} d_{0\uparrow} |AF\rangle \) and \( |C'\rangle = C_{0\sigma}^{\dagger} d_{0\downarrow} |AF\rangle \), where \( B_{0\sigma}^{\dagger} \) and \( C_{0\sigma}^{\dagger} \) are defined by

\[
B_{0\sigma}^{\dagger} = \frac{1}{2} (b_{1\downarrow}^{\dagger} - b_{2\sigma}^{\dagger} + b_{3\sigma}^{\dagger} - b_{4\sigma}^{\dagger}),
\]

and

\[
C_{0\sigma}^{\dagger} = \frac{1}{\sqrt{2}} (c_{1\sigma}^{\dagger} - c_{2\sigma}^{\dagger}),
\]

respectively. The orbitals \( B_{0\sigma}^{\dagger} \), \( B_{0\sigma}^{\dagger} \) and \( C_{0\sigma}^{\dagger} \) have \( a_{g} \) symmetry in terms of the \( D_{2h} \) irreducible representation of the Cu\(_3\)O\(_{10}\) cluster, so that all the above states have the same symmetry \( (B_{3a}) \) as the ground state.

The result of the final state is shown in Fig. 4.9 (a) within the energy range corresponding to the one-hole CT excitation (\( E - E_g \) less than about 7 eV). We see that \( \rho_{AF} \) and \( \rho_{h} \) have definite structures at the ground state and at 5.5 eV. These features are similarly observed in Fig. 4.7. We thus conclude that the 5.5 eV excitation is nearly localized in each plaquette, i.e. “intra-plaquette” excitation.

There are also some structures in the energy region between \(|g\rangle\) and the 5.5 eV excitation, which are not observed in Fig. 4.7. A detailed calculation shows that the peak \( g_1 \) has large overlap with states which have frustrated \( d \)-spin arrangements such as

\[
\frac{1}{\sqrt{N_u}} \sum_{i=1}^{N_u} (-1)^{\alpha_d} d_{1i}^{\dagger} d_{0i}^{\dagger} d_{0\downarrow} |AF\rangle,
\]

where \( N_u \) is the number of up-spin hole, and \( \alpha_d \) is determined so that the state is the \( B_{3a} \) representation of the overall symmetry group \( D_{2h} \). Thus we conclude that the peak is due to spin excitations.

Figure 4.9 (a) also shows PDOS’s and TDOS of \( T_{pd} = 0 \) with the dashed curves. It is observed that a few peaks between 2 and 3 eV survive with slight energy shifts. Since the impurity Anderson model is reduced to the CuO\(_4\) cluster in this limit, we conclude that the existence of \( d-p \) network particular to multi-Cu models is their origin. In order to study the properties of these peaks we here define a new PDOS for

\[
|Z_{\pm}\rangle = \frac{1}{\sqrt{2}} (z_{1\pm}^{\dagger} d_{1\uparrow} + z_{2\pm}^{\dagger} d_{2\downarrow}) d_{0\downarrow} |AF\rangle,
\]

where the operator \( z_{1\pm}^{\dagger} \) is defined by

\[
z_{1\pm}^{\dagger} = \frac{1}{\sqrt{2}} (d_{1i}^{\dagger} L_{i}^{\dagger} \pm d_{1i}^{\dagger} L_{i}^{\dagger}).
\]

\(|Z_-(\rangle \langle Z_+)|\) describes a state where a hole pushed out from the central plaquette forms a local singlet (triplet) at the nearest-neighboring plaquettes. The phase factor in eq. (4.18) was determined so that its global symmetry is in agreement with that of the ground state \( (B_{3a}) \).

According to the calculated result, \( \rho_{Z_-} \) has clear structure \( (Z_1) \) between 2 and 3 eV, but little weight in \( \rho_{Z_+} \). Although the impurity Anderson model contains the nearly pure \( p \) states in this energy range, this result suggests that the CT excitation in this energy range has ZR singlet like character. Hence the CT gap may be defined by the energy to move a hole from the bonding orbital at a plaquette to the surroundings, where the local singlet is formed. If \( 2T_{pd} \ll \Delta \) held as Zhang and Rice originally discussed [43], the binding energy of the local singlet would be estimated by their formula.
$-8T_{pd}^{2}[1/\Delta^2 + 1/(U_{dd} - \Delta)^2]$. However, our parameter gives $2T_{pd} \simeq \Delta$. We hence obtain the conclusion again that the simple estimation that $\epsilon_{\text{gap}} \simeq \Delta$ does not hold. This point is made still clearer by studying Cu 4p-1s RXES of CuGeO$_3$, which has relatively larger $\Delta$ [130, 131]. In fact, our recent calculation shows that the charge gap is approximately half of $\Delta$ in CuGeO$_3$. The detailed discussion will be published elsewhere.

Except for this fact, PDOS’s in Fig. 4.7 and 4.9 have much in common. For example, the 2 eV excitation has hardly AF weight, but has relatively large weight in $\rho_B'$ and $\rho_C'$.

Figure 4.9: (a) Total and partial densities of states in RXES final state for Cu$_3$O$_{10}$ cluster, whose structures are shown in the panel. The definition of the state $|\text{AF}\rangle$ and so on is given in the text. The solid and dashed curves represent the results with $T_{pp} = 0.55$ and 0, respectively. (b) TDOS and PDOS in the intermediate (XAS final) state, and Cu 1s-4p XAS spectrum. The energy dispersion of the 4p electron is disregarded to calculate PDOS, but fully included to calculate XAS. The solid and dashed curves are obtained with $R_c = 1.0$ and 0.8, respectively. For both (a) and (b), the origin of the abscissa is adjusted to be the lowest eigenenergy, and all spectra are broadened with Lorentzian ($\Gamma_L = 0.2$ eV), whose integrated areas are normalized to be unity.

Similar arguments are applicable to the intermediate state. The calculated results are given in Fig. 4.9 (b) for the system with a core hole at the central site. The energy dispersion of 4p electron is neglected to calculate PDOS. It is clearly shown that AF weight is transferred to about 6.6 eV higher than the lowest energy state, being denoted by “S”. Naturally, the main structure in $\rho_{\text{AF}}$ corresponds to $c^d\bar{d}$ in the standard notation of the impurity Anderson model.

In addition, first, we can assign the lowest energy feature “Z” to the state with the local singlet (not triplet). This is the direct evidence of appearance of the ZR singlet in the intermediate state, also in the final state of 2p-XPS first discussed by van Veenendaal et al. [41], i.e. a hole pushed out by the corehole potential moves to the neighboring plaquettes to form the local singlet. Second, structures
about 1.5 eV above the ZR state is attributed to a charge-transferred state having a considerable weight in the nearest-neighbor orbital of the core hole site, corresponding to \( |M\rangle \) of the impurity Anderson model.

Figure 4.9 (b) also shows Cu 1s-4\( p_\pi \) XAS. In contrast to the impurity Anderson model, there are three structures in XAS, which are the above discussed Z, M and S. This interpretation has close relationship with that of 2\( p \)-XPS [86, 88].

### 4.4.2 RXES

Figure 4.10 shows XAS and RXES spectra with the Cu\(_5\)O\(_{16}\) cluster with open boundary condition. Calculated spike spectra of RXES are convoluted with Gaussian \( \Gamma_G = 0.95 \) eV (HWHM) in accordance with the experimental resolution [116]. XAS is also broadened with Lorentzian \( \Gamma_L = 0.8 \) to consider the lifetime effect and \( \Gamma_G = 0.8 \) eV to reproduce the experimental peak width. To avoid boundary effects, the core hole is fixed to the central site for both RXES and XAS. Effects of spatial coherence are discussed separately in the next chapter in the context of momentum-transfer dependence [152].

As is the case of the impurity Anderson model, RXES in Fig. 4.10 have two structures around 2 and 5.7 eV, which are hereafter symbolically denoted by \( |2\rangle \) and \( |5.7\rangle \), respectively. The latter value is somewhat larger than that of the impurity and Cu\(_3\)O\(_{10}\) models, but closer to the experimental value.

The 2 eV intensity is considerably enhanced when the incident photon energy \( \Omega \) is tuned at the main peak “1” of XAS. This is observed in common with the case of the impurity Anderson model, but the enhancement is extremely intense in this case. The reason is that both 2 eV excitation and
the main absorption peak have a ZR singlet, so that their overlap is very large. Because of the extremely strong elastic scattering, the 2 eV peak is hardly observed in Fig. 4.2. It is established from experimental [132] and theoretical results [133, 134] in the optical conductivity that the charge gap of undoped high-$T_c$ cuprates is of order of 2 eV. A recent high-resolution experiment in Cu 4p-1s RXES of Sr$_2$CuO$_2$Cl$_2$ [135] successfully observes the 2 eV peak. For the relative intensity of the 2 eV peak as compared to the 5.7 eV one, the spatial coherence of the core orbitals seems to play some role. We have fixed the core hole to the central Cu site in the present calculation. Roughly speaking, this corresponds to that situation, where RXES spectra with all kinds of the momentum transfer $q$ are mixed up. As will be suggested by a $q$-dependent calculation in the next chapter 6, the 2 eV peak might be excessively highlighted under this situation, as compared to the experimental data, where $q$ is perpendicular to the CuO$_2$ plane. At any rate, one needs experimental studies with higher resolution and theoretical studies with larger clusters for detailed discussion on the 2 eV peak.

On the other hand, since $|5.7\rangle$ is the intra-plaquette excitation, corresponding to the 5.5 eV excitation of Cu$_3$O$_{10}$ cluster discussed in the preceding subsection, the overlap with the ZR state is expected to be quite small. The ZR state contains a plaquette with almost no hole. As a result, the 5.7 eV intensity is suppressed when $\Omega$ is tuned at the XAS main peak. We believe that this is the fundamental mechanism of the experimental suppression effect. Note that this conclusion is hardly affected by the above-mentioned spatial coherence of the core orbitals, because of the intra-plaquette nature of $|5.7\rangle$.

Since the satellite peak “5” has the dominant weight in AF as shown in Fig.4.9 (b), it is likely for this state to have large overlap with $|5.7\rangle$, the state almost localized at each plaquette. This coupling would be preferred also from the phase matching point of view. In addition, it is expected to have little overlap with the 2 eV excitation containing the ZR singlet like state. Thus the RXES spectrum has an only structure around the 5.7 eV excitation.

When $\Omega$ is tuned at the shoulder “2”, which was denoted by M in the preceding subsection, the situation is halfway. The dominant weight of M lies on $|A'\rangle$, but more extended orbitals have no negligible weight as shown in Fig.4.9 (b), so that the former gives rise to the intensity of the 5.7 eV excitation, and the latter causes the transition to the 2 eV excitation, resulting somewhat broader spectra.

### 4.4.3 Excitation energy dependence of the 5.7 eV intensity

The disagreement with the experimental data in the $\Omega$-scan of the 5.2 eV intensity with the impurity Anderson model is essentially cleared up by considering the above multi-Cu effects. Calculated $\Omega$-scans of the 6 eV (actually 5.7 eV) intensity in 4$p_{x\pi}$-1s RXES of Nd$_2$CuO$_4$ are given in Fig. 4.3 (b), where the results with $R_c = 1$ and 0.8 are represented with the dashed and thick solid curves, respectively.

In contrast to the doubly-peaked shape of the impurity model calculation, the multi-Cu one gives a triply-peaked structure. Because of the suppression effect for $\Omega$ tuned at around $-3$ eV, it reproduces the experimental data much better than the impurity one.

Introducing $R_c$, we see that the 5.7 eV intensity is more suppressed when $\Omega$ is tuned at the main peak (Z), but enhanced when $\Omega$ is tuned at the shoulder (M), improving the agreement with the experiment. TDOS and PDOS's with $R_c = 0.8$ for Cu$_3$O$_{10}$ cluster is shown in Fig. 4.9 (b) with the dashed curve. We see that, first, $\rho_{Z-}$ is enhanced by $R_c \neq 1$ at the lowest state “Z”. This means that the hole is pushed out from the core hole plaquette more strongly, so that the overlap with the intra-plaquette excitation

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6See Fig. 5.9.
tends to be decreased. On the other hand, $\rho_{A'}$ is increased around the energy of the shoulder “M”, being consistent with the discussion in the subsection 4.3.4. However $\rho_{B'}$ and $\rho_{C'}$ are decreased at this energy, so that the overlap with the intra-plaquette excitation tends to be increased. This means that the existence of the ZR singlet state reduces extended nature of the state M.

We finally give a few comments on the present study. There is slight discrepancy with the experimental data mainly due to the incompleteness of the suppression effect. We have performed the calculations with relatively small clusters such as Cu$_3$O$_{10}$ or Cu$_5$O$_{16}$. All excitations necessarily have more or less local character as far as the system is finite. Moreover, it is impossible to avoid boundary effects perfectly. In order to make the point clear, detailed experimental and theoretical analysis is needed for one-dimensional systems [136], where one can extend the cluster size without facing the limitation of the memory size of computers.

4.5 Conclusions

We theoretically investigated the Cu $4p_{\pi}-1s$ RXES of Nd$_2$CuO$_4$ firstly with the impurity Anderson model. Utilizing PDOS functions, we found that excitations about 5.2 eV above the ground state have considerably localized character, and that excitations about 2 eV above the ground state are nearly pure $p$ states, having less amplitude at the plaquette with the impurity.

In the large cluster calculations, however, the low energy excitations created by CT processes have ZR singlet like character in contrast to the result with the impurity Anderson model, although excitations about 5.7 eV above the ground state is similarly local (“intra-plaquette”). This difference is clearly reflected in the RXES spectra when the main absorption peak is resonated.

A conspicuous disagreement with the experimental 6 eV intensity as a function of the incident photon energy could not be removed with the impurity Anderson model. It was demonstrated that the difficulty is solved by considering Zhang-Rice singlet formation, using the multi-Cu model.

We finally discussed the role of the configuration dependence of the $d$-$p$ transfer. The satisfactory agreement with the experimental data is obtained with the large cluster calculation with $R_c$. 
Chapter 5

Polarization and Momentum Dependence of Charge Transfer Excitations in Nd$_2$CuO$_4$

Polarization and momentum-transfer dependence in Cu 4$p_{\sigma}$-1$s$ resonant X-ray emission spectra (RXES) of Nd$_2$CuO$_4$ is theoretically studied. We explain the experimental polarization and angular dependence of the 5.7 eV excitation. Comparing results calculated with single- and multi-Cu models, we confirm again the essential contribution of the nonlocal screening effect in Cu 4$p_{\sigma}$-1$s$. We predict considerable dependence of a CT excitation at about 2 eV on momentum transfer along the CuO$_2$ planes, and the 5.7 eV excitation has less dependence.  

5.1 Introduction

As explained in § 1.1, RXES occupies a unique position in that it offers rich information on electronic structures in terms of both local and translational selection rules. With well-polarized X-rays created by synchrotron light sources, several groups have reported angular and polarization dependence of RXES in these days [71, 97, 106, 137, 138], and derived significant information on electronic structures. Since specific resonance enhancement occurs at the corresponding absorption peak in general, it is of great use also in that it may give clear explanation on the origin of somewhat complicated structure of XAS spectra such as Cu $K$-XAS of La$_2$CuO$_4$ [139].

Most of theoretical studies on polarization dependence of RXES in $d$ and $f$ electron systems within the framework of the second-order optical process have been based on impurity Anderson models so far. As well as the dipole transition, more complicated angular and polarization dependence of quadrupolar transition is recently discussed within an impurity Anderson model [140]. The applicability of impurity Anderson models to angle or polarization resolved RXES is mathematically understood from Eq. (1.37), where the scattering amplitude of whole crystal is expressed as Fourier transformation of the local scattering amplitude $M_{e'\epsilon}(R;\Omega)$ of angular and polarization dependence. Here we explicitly write $\Omega$-dependence of this amplitude defined in Eq. (1.39). As far as Cu 4$p$-1$s$ RXES of Nd$_2$CuO$_4$ is

\footnote{T. Idé and A. Kotani, submitted. A part of this chapter will be published also in Ref. [117].}
concerned, however, it is also apparent from these equations that the impurity limit disregards, first, the nonlocal screening effect due to the Zhang-Rice singlet formation, and second, the momentum transfer ($q$) dependence of RXES.

In this chapter, we discuss the polarization dependence in Cu $4p$-$1s$ RXES of Nd$_2$CuO$_4$ together with the latest experimental data. While definite polarization dependence of Cu $K$-XAS in this material has been already reported by a number of authors [141, 142, 143], little has been known about polarization dependence of RXES. Since a $1s$ orbital has no orbital degeneracy, theoretical analysis on polarization dependence is much simpler than that of, e.g., $3d$-$2p$ transition [107]. Furthermore, the absence of apex oxygen in Nd$_2$CuO$_4$ and no overlap between $4p_\pi$ and $4p_{\sigma}$ absorption edges make the situation clearer. Thus, comparison with experimental data offers us a plain confirmation on the theoretical framework of RXES.

In the preceding chapter, we considered the nonlocal screening mechanism for the absence of resonance enhancement when the main Cu $K$-absorption peak is targeted by an incident X-ray. Detailed character on spatial direction of $4p$ orbitals was not used to interpret the Cu $4p$-$1s$ RXES spectra. Hence what the experimental data with differently polarized photon are successfully interpreted with the same theory is the ideal justification of the theory. At the same time, it is interesting to investigate whether the anisotropy in $4p$ orbitals affects the screening process in the valence electronic state. We will show that the polarization dependence in RXES can be clearly understood in terms of the framework of the second-order optical process. We will also show that Cu $4p_{\sigma}$-$1s$ spectra essentially follows $4p_{\pi}$-$1s$ spectra discussed in the preceding chapter.

The other point that the impurity limit disregards is the $q$-dependence of RXES. Momentum resolved RXES with hard X-rays is a complement to angle-resolved PES to examine entire Brillouin zone. Recently, the $q$-dependence of RXES is measured for Mott-Hubbard systems [144, 145] and insulating cuprates [135]. Despite of their significance, there have been few theoretical studies on the $q$-dependence so far. Very recently, Tsutsui et al. reported a numerical calculation on the $q$-dependence of Cu $4p$-$1s$ RXES for the first time [82]. Based on an effective $4\times4$ Hubbard model, they discussed the energy dispersion of the CuO$_2$ planes of insulating cuprates. Within one-dimensional (1D) systems, we will show a model calculation on the $q$-dependence of Cu $4p$-$1s$ RXES of cuprates, and derive valuable information in the context of local and nonlocal excitations in Nd$_2$CuO$_4$.

The layout of this chapter is as follows. In the next section formulae for angular dependent transition operators are given. In § 5.3 we explain experimental polarization dependence with those formulæ. In § 5.4 the role of the nonlocal screening effect is briefly described. In § 5.5 we discuss intra- and interplaquette natures of CT excitations from a viewpoint of $q$-dependence of RXES. In the final section a brief summary is given.

## 5.2 Formulation

### 5.2.1 Hamiltonian

The model adopted in this chapter is the same as that of the preceding chapter except for terms describing $4p$ electrons. Calculated results are obtained with the multi-Cu (Cu$_5$O$_{16}$) model or the single-Cu (Cu$_1$O$_{256}$) model (impurity Anderson model). To discuss the polarization dependence, we introduce
$4p_\alpha$ Hamiltonians, $H_{4p\sigma}$, $H_{4pc}$ and $H_{4p3d}$. The one-electron part $H_{4p\sigma}$ is defined by

$$H_{4p\sigma} = \sum_{\eta=a,x,y} \sum_{R} \frac{1}{2} \left( \hat{S}_R^\eta \hat{Q}_R^{\eta \sigma} + \hat{Q}_R^{\eta \sigma} \hat{S}_R^\eta + H.c. \right)$$

where $\hat{Q}_R^{\eta \sigma}$ creates a Cu $4p_\eta$ ($\eta = a,x,y$) electron at $R$ site, $\hat{x}$ and $\hat{y}$ are two unit vectors along Cu-O direction in the CuO$_2$ plane. $a$ is the Cu-O distance. $t_1$ and $t_2$ are respectively ($pp\sigma$) and ($pp\pi$) of the $4p_\epsilon$ orbitals in terms of the Slater-Koster parameters [118].

$H_{4pc}$ and $H_{4p3d}$ describe Cu $4p$-$1s$ and Cu $4p$-$3d$ intra-atomic interactions, respectively. The explicit forms are

$$H_{4pc} = -\sum_{R} \left[ \sum_{\eta} U_{4pc} \hat{Q}_R^{\eta \sigma} \hat{Q}_R^{\eta \sigma} \right] S_R^\sigma \epsilon_R$$

and

$$H_{4p3d} = -\sum_{R} \left[ \sum_{\eta} U_{4p3d} \hat{Q}_R^{\eta \sigma} \hat{Q}_R^{\eta \sigma} \sum_{\alpha} \epsilon_\alpha R_\alpha \sigma R \right].$$

These are the same as those of in the preceding chapter except for $\eta \neq z$ and the numerical value of $U_{4p3d}$. Now total Hamiltonian is written as

$$H = H_{4p} + H_{pp} + H_{core} + H_{dc} + H_{4p\sigma} + H_{4pc} + H_{4p3d},$$

where the first four terms have been defined in the preceding chapter. All parameters are the same as those of the preceding chapter except for $t_1 = 0.24$ and $t_2 = -0.8$, and $U_{4p3d}=3.3$ eV. For the $4p$-$4p$ transfer energy parameters $t_1$ and $t_2$, we consider a first principle band calculation [121]. The difference between $U_{4p3d}(\sigma)$ and $U_{4p3d}(\pi)$ due to multipole contribution of the Slater integrals is estimated as 0.34 eV with Cowan’s numerical program [146] and the empirical reduction factor 0.85 [26], from which we take the value 3.3 for $U_{4p3d}(\sigma)$.

### 5.2.2 Angular-dependent transition operators

The general form of the X-ray absorption and emission operators has been given in Eq. (1.22). For $1s$ excitation, it is appropriate for $4p$ operators to be expressed under the Cartesian coordinates, $(4p_x,4p_y,4p_z)$. The definition of the coordinates, whose origin is fixed to a Cu site, is described in Fig. 5.1. We set unit vectors along the $x$, $y$ and $z$ axes to be $\hat{e}_x$, $\hat{e}_y$ and $\hat{e}_z$. In the atomic approximation, we immediately have the $1s$-$4p$ absorption operator as

$$T^\alpha_{\epsilon}(R) = \epsilon \sum_{\zeta=x,y,z} \xi_{\epsilon \zeta \hat{e}_{\zeta}} \hat{Q}_{\epsilon \zeta}^R S_R,$$

where we dropped a trivial prefactor.

Let us define another set of unit vectors, $\hat{y}_1$ and $\hat{y}_1$, which are parallel and perpendicular to the scattering plane, respectively. Both are perpendicular to the incident wave vector $q_1$. Experimentally, it is convenient to express the polarization vector in terms of these unit vectors, $\epsilon = \sum_{\alpha=\hat{y}_1, \hat{y}_1} \epsilon_\alpha \hat{a}\alpha$. 

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where for a $(\ell, m_c) \to (l, m)$ transition under the atomic dipole approximation. Rewriting $(n l m|\varepsilon \cdot p|n', l', m_c)$ in terms of spherical tensor operators, we have

$$T^q_x(R) = \delta_{q,0} \sum_{\xi, \alpha} \epsilon_{\alpha} (\hat{\alpha} \cdot \hat{\xi}) Q_{\xi_R}^\dagger S_R. \quad (5.3)$$

While this formula explicitly assigns the $1s \to 4p$ transition path, one can easily generalize $T^q_x(R)$ for a $(l, m_c) \to (l, m)$ transition under the atomic dipole approximation. Rewriting $(n l m|\varepsilon \cdot p|n', l', m_c)$ in terms of spherical tensor operators, we have

$$T^q_x(R) = \sum_{m, n, \ell, \sigma} \langle m_2|C_{q}^{(1)}|m_c\rangle A_q^{(\xi)}(\theta, \phi)|l\rangle^\dagger_{Rm\sigma} c_{Rm\sigma} \epsilon_{\alpha}, \quad (5.4)$$

where dipole geometrical function $A_q^{(\xi)}(\theta, \phi)$ is defined by

$$A_q^{(\xi_1)}(\theta, \phi) = \begin{cases} -\frac{1}{\sqrt{2}} q \cos \theta e^{-iq\phi}, & q = \pm 1 \\ -\sin \theta, & q = 0 \end{cases}, \quad (5.5)$$

$$A_q^{(\xi_2)}(\theta, \phi) = \frac{i}{\sqrt{2}} q |q| e^{-iq\phi}, \quad q = 0, \pm 1. \quad (5.6)$$

$\theta$ and $\phi$ designate the direction of $q_1$ (see Fig. 5.1) [110]. It is straightforward to derive the general formula for the X-ray emission due to the dipole transition, and therefore that for RXES. This matter is, however, beyond the scope of this chapter.

On the analogy of $T^q_x(R)$, the $4p-1s$ X-ray emission operator is given by

$$T^q_x'(R) = \sum_{\xi} \sum_{\beta=\xi_2, \xi_2} e_{\beta}(\hat{\beta} \cdot \hat{\xi}) S_{R}^\dagger Q_{\xi_R}, \quad (5.7)$$

where $\hat{\xi}_2$ and $\hat{\gamma}_2$ are unit vectors parallel and perpendicular to the scattering plane, respectively, defined for the emitted wave vector $q_2$ (see Fig. 5.1). Hence we obtain the transition operator of RXES at $R$, $T_{e'\varepsilon}(R; \Omega) = \sum_{\alpha, \beta, \xi} e_{\alpha} D_{\beta \alpha}^\xi(\theta, \theta, \phi) \epsilon_{\alpha} S_{R}^\dagger Q_{\xi_R} G_0(\Omega) Q_{\xi_R}^\dagger S_R, \quad (5.8)$

where $D_{\beta \alpha}^\xi(\theta, \theta, \phi) \equiv (\hat{\beta} \cdot \hat{\xi})(\hat{\xi} \cdot \hat{\alpha})$ is tabulated in Table 5.1. $G_0(\Omega)$ is the resolvent operator defined by $(\Omega + E_R - H + i\Gamma)^{-1}$. We take $\Gamma=0.8$ eV as in the preceding chapter. Eventually, the overall operator of RXES is given by

$$T_{e'\varepsilon}(\Omega) = \sum_{R} e^{iq_R} T_{e'\varepsilon}(R; \Omega),$$

where $q = q_2 - q_1$ is the momentum-transfer of the X-ray.

---

**Table 5.1: Angular dependent function $D_{\beta \alpha}^\xi(\theta, \theta, \phi)$.**

<table>
<thead>
<tr>
<th>$(\hat{\beta}, \hat{\alpha})$</th>
<th>$x$</th>
<th>$y$</th>
<th>$z$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$(\hat{\xi}_2, \hat{\gamma}_1)$</td>
<td>$\cos(\theta_1 + \theta)\cos\theta_1 \cos^2 \phi_i$</td>
<td>$\cos(\theta_1 + \theta)\cos\theta_1 \sin^2 \phi_i$</td>
<td>$\sin(\theta_1 + \theta)\sin\theta_1$</td>
</tr>
<tr>
<td>$(\hat{\gamma}_2, \hat{\gamma}_1)$</td>
<td>$-\cos\theta_1 \sin\phi_1 \cos\phi_1$</td>
<td>$\cos\theta_1 \sin\phi_1 \cos\phi_1$</td>
<td>0</td>
</tr>
<tr>
<td>$(\hat{\xi}_2, \hat{\gamma}_1)$</td>
<td>$-\cos(\theta_1 + \theta)\cos\phi_1 \sin\phi_i$</td>
<td>$\cos(\theta_1 + \theta)\cos\phi_1 \sin\phi_i$</td>
<td>0</td>
</tr>
<tr>
<td>$(\hat{\gamma}_2, \hat{\gamma}_1)$</td>
<td>$\sin^2 \phi_i$</td>
<td>$\cos^2 \phi_i$</td>
<td>0</td>
</tr>
</tbody>
</table>
Figure 5.1: Geometrical configuration of RXES. The semicircle represents the scattering plane. The solid and open circles are Cu and O atoms, respectively. x and y axes are taken along two Cu-O directions. $\phi_i$ and $\theta_i$ designate the direction of the wave vector of the incident photon, $q_1$. $q_2$ is the wave vector of the emitted photon with a scattering angle $\theta$. The polarization vector of the incident photon is described in terms of unit vectors $\hat{x}_1$ and $\hat{y}_1$. The former is parallel to the scattering plane, whereas the latter (not shown in the figure) is perpendicular to the scattering plane. These agree with each of the unit vectors of the x and y axes, respectively, in the limit $\phi_i, \theta_i \to 0$. The polarization vector of the emitted photon is described with $\hat{x}_2$ and $\hat{y}_2$, which agree with $\hat{x}_1$ and $\hat{y}_1$, respectively, in the limit $\phi_i, \theta_i$ and $\theta \to 0$.

5.3 Polarization Dependence

5.3.1 Experimental data

Experimental data were measured for a single crystal of Nd$_2$CuO$_4$ under two geometries depicted in Fig. 5.2. In the geometry (a), both polarization vectors, $\varepsilon$ and $\varepsilon'$, are parallel to the scattering plane, and they take $30^\circ$ to the z-axis (so-called c-axis). In the geometry (b), both polarization vectors are perpendicular to the scattering plane, being parallel to the ab-plane. Note that momentum transfer vector is common to both geometries.

Figure 5.2: The experimental geometries. (a) Polarization vectors of the incident and emitted photons are parallel to the scattering plane ("$\varepsilon \sim \parallel c$"). (b) Polarization vectors of the incident and emitted photons are perpendicular to the scattering plane ("$\varepsilon \parallel ab$"). For both (a) and (b), the scattering angle is $\theta = 60^\circ$, and the momentum transfer vector is perpendicular to the CuO$_2$ plane (so-called ab-plane).
The upper panel of Fig. 5.3 shows Cu K-XAS spectra for both geometries. We observe four distinct bumps from A to D for the geometry (a), which is denoted by “ε₁” in the figure, whereas only two structure C and D are observed for the geometry (b), which is denoted by “ε₂ab”. The first question to be answered is this polarization dependence.

Analogous to Cu 4pₐ-1s RXES shown in Fig. 4.2, where the geometry (a) is adopted, a charge-transfer (CT) excitation is observed at about 5.7 eV energy loss also under the geometry (b). The Ω-dependence of the 5.7 eV intensity is plotted in the lower panel of Fig. 5.3 for both geometries. The experimental Ω-scan represented with the open circles is just the same data as in the lower panels in Fig. 4.3. As seen in the figure, strong resonance enhancement is observed only when Ω passes by the absorption peak B in the case of the geometry (a). On the other hand, strong enhancement occurs only when Ω passes by the absorption peak D in the case of the geometry (b). To confirm this, RXES spectra under the two geometries with Ω=Ω₂=8990 eV (peak B) and Ω₁=8999.5 eV (peak D) are shown in the lower and upper panels in Fig. 5.4, respectively. We see that an inelastic peak is observed at about 5.7 eV in both geometries. However, no enhancement occurs in the geometry (b) when Ω is tuned at B (lower panel). This is the second question. Conversely, no enhancement occurs in the geometry (a) when Ω is tuned at D (upper panel). This is the third question. Moreover, the maximum intensity of the 5.7 eV peak is considerably different in both cases. This is the fourth question.

5.3.2 Theoretical explanation

For theoretical description, we put an assumption, as the lowest nontrivial approximation, that difference between σ and π in U₄ₐd, U₄₈c, and 4p-4p transfers do not substantially change the valence states in the intermediate state. Let us first consider the angular dependence of K-XAS by considering a steeply increasing background spectrum. Now the first question has been answered.

The function D₁₂₅₆ rules angular dependence of RXES. When (ε', ε) = (ŷ₂, ŷ₁) we see that there is no contribution of 4pₓ (4pᵧ) orbitals because of Dₓ₂,ŷ₁ = 0. This fact explains no enhancement over the 4pₓ absorption threshold under the geometry (b). This is the answer to the second question.

Next we notice that x₁ → y₂ and y₁ → x₂ transitions are not allowed if the ground state |g⟩ is not E representation of the D₄₈h group ². If it is the case,

\[ \langle f|T_{x}(\Omega)|g⟩ = \langle f|T_{y}(\Omega)|g⟩ \]

follows for a final state |f⟩ with the same symmetry as |g⟩ because Tₓ = C₄T₄(C₄)², C₄ being the rotation operator of π/4 around the z-axis at a Cu site R. Here we defined Tₓ(Ω) by

\[ T_{x}(\Omega) = \sum_{R} e^{iq R} S_{R} Q_{\varphi R} G_{0}(\Omega) Q_{\varphi R}^{*} S_{R} \]

²This assumption is numerically justified for undoped two-dimensional clusters, Cu₅O₁₆ and Cu₄O₁₂.
Figure 5.3: Upper panel: Cu K-XAS of Nd$_2$CuO$_4$ [117]. The open and closed circles represent experimental data under the geometries (a) and (b), respectively. The solid and dotted curves represent calculated Cu 1s $\rightarrow$ 4p$_{\sigma}$ absorption spectra under the geometry (b) with the multi-Cu and single-Cu models, respectively. Both curves are convoluted with Lorentzian $\Gamma_L = 0.8$ eV (HWHM) to consider lifetime of a 1s hole, and further convoluted with Gaussian $\Gamma_G = 0.8$ eV (HWHM) for the multi-Cu model, and with $\Gamma_G = 1.2$ eV (HWHM) for the single-Cu model to reproduce the experimental line width. Lower panel: the $\Omega$-dependence of the 5.7 eV intensity [117]. The definition of the open and closed circles is the same as the upper panel. The solid and dotted curves represent the $\Omega$-dependence of intensity of the 5.7 eV peak in Cu 4p$_{\sigma}$-1s RXES calculated under the geometry (b) with the multi-Cu and single-Cu models, respectively. Both curves are convoluted with $\Gamma_G = 1.10$ eV (HWHM) for the incident X-ray and with $\Gamma_G = 1.15$ eV (HWHM) for the emitted X-ray.
Figure 5.4: Experimental polarization dependence of Cu 4p-1s RXES [117]. The open and closed circles correspond to the geometries (a) and (b), respectively. In the upper panel $\Omega$ is tuned at the absorption peak D, and in the lower panel $\Omega$ is tuned at B. The definition of D and B are given in Fig. 5.3.
for $\zeta = x, y$ and $z$, with $q \perp R$ in this case. Thus $D_{\Delta}^{x} = -D_{\Delta}^{y}$ or $D_{\Delta}^{x} = -D_{\Delta}^{y}$, leads to the zero transition amplitude. Note that one can not suppress the elastic line by choosing $\varepsilon \cdot \varepsilon' = 0$ as far as $q \perp R$ holds, because elastic as well as inelastic scattering is not allowed in this case (see § 1.3.2).

Under the same assumption on the ground state, emission intensity under the geometry (b) is given as $I_2(\Omega) = |\langle f | T_{e}(\Omega) | g \rangle|^2$, and emission intensity under the geometry (a) as

$$I_1(\Omega) = |\langle f | T_{e}(\Omega) \cos(\theta_i + \theta) \cos \theta_i + T_{e}(\Omega) \sin(\theta_i + \theta) \sin \theta_i | g \rangle|^2.$$  

Thus we can estimate the intensity ratio between $\pi$- and $\sigma$-resonances under this geometry as

$$\frac{\sigma}{\pi} = \cos^2(\theta_i + \theta) \cos^2 \theta_i : \sin^2(\theta_i + \theta) \sin^2 \theta_i,$$

giving $\sigma : \pi = 1 : 9$ for $\theta_i = 60^\circ$. This ratio partly answers the third question, i.e. the little resonance enhancement when $\Omega$ passes by the $4p_{\pi}$ threshold under the geometry (a), although the relatively large error bars prevent us from further quantitative statement.

One can also roughly estimate the ratio of maximum intensity of the 5.7 eV peak for the two geometries. Since the maximum peak is realized at the $4p_{\pi}$ absorption threshold in the case of the geometry (a), we have $I_1 \sim \sin^2(\theta_i + \theta) \sin^2 \theta_i |\langle f | T_{e}(\Omega_2) | g \rangle|^2$. If $|\langle f | T_{e}(\Omega_2) | g \rangle|^2$ can be regarded to be the same order as $|\langle f | T_{e}(\Omega_0) | g \rangle|^2$, the assumption that is exactly justified in the isotropic limit of $4p$ orbitals, we have the ratio as

$$I_1/I_2 \sim \sin^2(\theta_i + \theta) \sin^2 \theta_i.$$

For $\theta_i = 60^\circ$, this is approximately 0.56, which broadly explains the ratio of the 5.7 eV intensity in Fig. 5.4 (the answer to the fourth question).

We have studied Cu $4p$-1s RXES under only the two geometries. Although the present calculation and experiment show no clear evidence that the assumption we put at the beginning of this subsection breaks down, it may be interesting to watch the angular and polarization dependence of RXES spectra in a class of materials. Ishihara and Maekawa recently emphasize the role of anisotropy between $U_{4p_{3d}}(\pi)$ and $U_{4p_{3d}}(\sigma)$ to explain anomalous elastic scattering in orbital ordered Mn compounds [147]. Analyzing angular and polarization dependence of also inelastic scattering, it is expected to obtain more detailed information on spatial direction of orbitals. This subject is left for the future study.

### 5.4 Incident Energy Dependence

#### 5.4.1 Calculated results

We carried out numerical calculations for the geometry (b) again with the multi-Cu (Cu$_5$O$_{16}$) cluster and the single-Cu (Cu$_1$O$_{256}$) cluster models. Part of the results are shown in Fig. 5.3 with solid (multi-Cu) and dotted (single-Cu) curves for both panels. Corresponding to the experimental structures C and D in the XAS spectra, a doubly-peaked structure in the calculated absorption spectra is observed in the upper panel. For convolution width of the calculated spectra, see the figure caption. We hardly find discrepancy between the multi-Cu and single-Cu results, except for slight difference in the width of the main structure. The resonant behavior of the 5.7 eV peak shown in the lower panel is, however, quite different. The multi-Cu model presents a singly-peaked $\Omega$-dependence, whereas the single-Cu model presents a doubly-peaked $\Omega$-dependence. Note that somewhat larger convolution width of Gaussian $\Gamma_G = 1.1$ eV for the incident X-ray is used to reproduce the experimental resolution, as compared to
Fig. 4.3. While the $\Omega$-scan of the multi-Cu calculation reproduces much better than the single-Cu one, the experimental $\Omega$-scan exhibits more definite suppression effect when $\Omega$ is tuned at the peak C.

To remove this discrepancy, we performed calculations including the reduction factor of the $d$-$p$ transfer, $R_c$, whose definition has been given in the preceding chapter. Calculated XAS and RXES spectra with $R_c = 0.8$ are shown in Fig. 5.5. Despite the difference in the transition process, these figures are very similar to Figs. 4.8 and 4.10, where $R_c = 1$ calculations are given. The only remarkable difference is that the main absorption structure is more broadened than in Fig. 4.10. This result is consistent to the experimental difference in line width between the peak A (B) and C (D).

The $\Omega$-scan of the 5.7 eV peak based on these improved calculations is plotted in the lower panel of Fig. 5.6. We see that agreement with the experimental data (closed circles) is considerably improved in the multi-Cu result (solid curve). Specifically, the suppression effect when $\Omega$ is tuned at the main absorption peak is more clearly reproduced. While including $R_c=0.8$ also in the single-cluster case seems to give rise to more suppression as compared to that in Fig. 5.3, the overall line shape is still doubly-peaked, being utterly different from the experimental data.

Figure 5.5: Cu $K$-XAS and $4p\sigma$-1s RXES with $R_c = 0.8$. (a) The impurity Anderson model ($\text{Cu}_1\text{O}_{256}$ cluster). The XAS spectrum shown in the right panel is convoluted with Lorentzian $\Gamma_L = 0.8$ eV (HWHM) to consider lifetime of a $1s$ core hole, and further convoluted with Gaussian $\Gamma_G = 1.2$ eV (HWHM) to reproduce the experimental line width. The RXES spectrum shown in the left panel is also convoluted with $\Gamma_G = 1.15$ (HWHM) to reproduce the experimental resolution. (b) The multi-Cu model ($\text{Cu}_5\text{O}_{16}$ cluster). The XAS spectrum shown in the right panel is convoluted with Lorentzian $\Gamma_L = 0.8$ eV (HWHM) to consider lifetime of a $1s$ core hole, and further convoluted with Gaussian $\Gamma_G = 0.8$ eV (HWHM) to reproduce the experimental line width. The RXES spectrum shown in the left panel is also convoluted with $\Gamma_G = 1.15$ (HWHM) to reproduce the experimental resolution. For (a) and (b), the elastic line, which should be located at zero, is omitted from the figure. The numbers attached to arrows in each XAS spectrum corresponds to those in RXES, representing the excitation energy.
Figure 5.6: The improved calculations of Cu K-XAS and the Ω-scan of the 5.7 eV inelastic peak with $R_c = 0.8$. The closed circles represent again the experimental results measured under the geometry (b) for both panels. See the caption in Fig. 5.3.
5.4.2 Discussion

Because of the similarity between $4p_\pi$ and $4p_\sigma$ spectra, we naturally assign the main absorption peak calculated with the multi-Cu cluster to that state which has a Zhang-Rice (ZR) singlet at plaquettes neighboring to the photoexcited one. The shoulder (3 in Fig. 5.5 (b)) of the main structure is attributed to a well-screened $cd^{10}_L$-like state, and the satellite peak (7 in Fig. 5.5 (b)) is attributed to a poorly-screened $cd^9$-like state, where $c$ and $L$ represent core and ligand holes, respectively. The main and satellite absorption peaks in the single-Cu model are, on the other hand, mainly $cd^{10}_L$ and $cd^9$ states, respectively.

![Diagram](image)

Figure 5.7: The essential contribution of the nonlocal screening effect in Cu $1s$-$4p$-$1s$ RXES when the incident photon energy $\Omega$ is tuned at the main peak of XAS.

Whichever model is used, there is a certain difference in spatial extent among these states, and this difference gives rise to the $\Omega$-dependence of RXES spectra. As demonstrated in the preceding chapter, the ZR state has the most nonlocal character because a $3d$ hole is pushed out by the strong $1s$-$3d$ repulsive Coulomb interaction into neighboring plaquette, so that it has little overlap with intra-plaquette CT states. Although the $4p$-$3d$ correlation $U_{4p3d}$ should more or less disturb the motion of the ZR singlet, it seems to act as only small perturbation. The final states are the same as those of $4p_\pi$-$1s$ RXES because of the absence of $4p$ electron. As discussed, the 5.7 eV inelastic peak is a $d^{10}_L$-dominant anti-bonding state, and the 2 eV peak is attributed to an excitation of a $3d$ hole from the upper Hubbard band to the ZR singlet band.

The mechanism of the suppression effect of the 5.7 eV inelastic peak is summarized in Fig. 5.7. When $\Omega$ is tuned at the ZR intermediate state, the 5.7 eV final state is unfavorable because it is an intra-plaquette excitation. To the contrary, the 2 eV final state has large overlap with this intermediate state as suggested in the figure. The effect of $R_c$ or detailed discussion on the $\Omega$-dependence of RXES spectra substantially follows those in the preceding chapter, and we do not repeat it here.
5.5 Momentum Transfer Dependence

In the context of local and nonlocal excitations, it is interesting to measure the energy dispersion over $k$-space, because an excited state completely localized in a unit cluster should exhibit no energy dispersion. Figure 5.8 shows the experimental $q$-dependence of RXES spectra [117], where $q$ is taken perpendicular to the $ab$-planes. We find that there is no shift in the peak position. This result clearly suggests weak coupling between the CuO$_2$ layers.

The energy dispersion in a CuO$_2$ plane can be measured by sweeping the in-plane component of $q$. We carried out numerical calculation on Cu 4$p$-1$s$ RXES for a 1D periodic Cu$_4$O$_{12}$ cluster for $q$=0, $\pi/2$ and $\pi$ in the unit of $(2a)^{-1}$. The results are shown in Fig. 5.9, where we adopt the same parameter set as that in Fig. 5.5 (b) except for $U_{dc}$=8.0. Note that all core orbitals are taken into account here, whereas we have fixed a core hole to the central Cu site so far. Analogous to Figs.4.10 and 5.5 (b), the main absorption structure is composed of two peaks, and a satellite structure is observed about 7 eV distant from the main peak. Recent experimental and theoretical studies on high-resolution Cu 2$p$-XPS of various cuprates show that the nonlocally screening path gives rise to the main peak of Cu 2$p$-XPS in one-dimensional as well as two-dimensional cuprates, as far as the corner-shared structure is concerned [136, 148, 149, 150]. Although close inspection shows that each spectrum has slight difference according to difference in physical parameters and dimensionality, the character of the shoulder of the main peak or the satellite structure is also broadly common to both dimensions [151]. Hence we can utilize the calculated results to infer $q$-dependence of the CT excitations in Nd$_2$CuO$_4$.

For the $q$-dependence of the RXES spectra, we find in Fig. 5.9 that the 2 eV peak exhibits considerable $q$-dependence in its intensity and position. Recently, Abbamonte et al. [135] successfully observed $q$-dependence of the 2 eV peak, which was hidden in the tale of the elastic line in Figs. 4.2, 5.4 and 5.8, in Cu 4$p$-1$s$ RXES of a two-dimensional insulating cuprate, Sr$_2$CuO$_2$Cl$_2$. Moreover, their experimental data show that the CT structure at about 5 eV displays little $q$-dependence in its peak position. This is qualitatively consistent to Fig. 5.9, and suggests the intra-plaquette nature of the 5.7 eV CT excited state in Nd$_2$CuO$_4$. On the contrary, the strong $q$-dependence of the 2 eV peak confirms the inter-plaquette (nonlocal) nature of the 2 eV CT excited state.

It is interesting to regard Fig. 5.9 as representing energy dispersion of a 1D system itself. Recently, angle-resolved PES measurements have been performed on (quasi) 1D cuprates, SrCuO$_2$ [153] and Sr$_2$CuO$_3$ [154], in the context of spin-charge separation [155, 156] due to photodoping. These experiments report that energy dispersion of a holon band, which is symmetric in each of halves of the first Brillouin zone ($k \geq 0$ or $k < 0$) with respect to the maximum at $|k|=\pi/2$, is much larger than that of Sr$_2$CuO$_2$Cl$_2$ [157]. Furthermore, they report that there is a spinon band over $-\pi/2 < k \leq \pi/2$ with smaller band width. While it has been established that the ZR singlet formation due to the “potential doping” (see § 1.4) in the intermediate state strongly contributes to Cu 4$p$-1$s$ RXES spectra, the relation with these phenomena unique to 1D systems is unclear. This is a subject left in the future.

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3This value of $U_{dc}$ is taken in order to keep the main-satellite separation in XAS spectrum the same as that in Fig. 5.5 (b).

4They assign the 5 eV structure to a “shakeup” scattering. However, it has been established from the analysis in the preceding chapter that this is the $d^{10}L$-dominant anti-bonding state.
Figure 5.8: The experimental momentum transfer dependence when $q$ is perpendicular to the CuO$_2$ planes [117]. The incident energy $\Omega$ is tuned at the $D$ peak in the XAS spectrum.

Figure 5.9: The $q$-dependence of Cu $4p_{\sigma}-1s$ REXS for a one-dimensional cluster as shown in the inset [152]. We see that the 2 eV CT excitation is strongly $q$-dependent, whereas the 5.7 eV peak has little $q$-dependence.
5.6 Conclusions

We have studied the polarization dependence of charge transfer excitations in Cu 4p-1s RXES of Nd$_2$CuO$_4$. Starting from the general formula introduced in Chap. 1, we derived a closed expression on angular and polarization dependence of RXES. The experimental polarization dependence is successfully explained with the formula, and the fact that the incident polarization dependence of the excitation process may be exploited to select the intermediate state of the resonance is shown.

Next, we confirmed the mechanism of the suppression of resonant inelastic scattering for nonlocally screened intermediate states. The difference between 4p$_\pi$ and 4p$_\sigma$ gave no drastic change in XAS and RXES spectra. Finally, we examined the $q$-dependence of the CT excitations in RXES spectra. The calculated spectra showed, first, that the 5.7 eV peak displays little $q$-dependence, and second, that the 2 eV peak considerably depends on $q$. These are interpreted in terms of intra- and inter-plaquette natures of the excitations, and are regarded as further support of the explanation of the suppression effect.
Chapter 6

Concluding Remarks

We have studied nonlocal effects in RXES with periodic Anderson models. The principal conclusions are twofold. First, the origin of the interplay between fluorescence-like and Raman components has been clarified. Second, the essential contribution of the nonlocal screening effect on Cu 4p-1s RXES spectra has been demonstrated. We recapitulate the conclusions of this thesis in what follows.

In Chap. 2, we studied the role of the translational symmetry on metal 3d-2p RXES of d⁰ systems. The model used is a one-dimensional nondegenerate periodic Anderson model, which is a minimal model having explicit translational symmetry. It was shown that RXES depends more sensitively on the cluster size than XAS and XPS, so that RXES is a useful probe in studying the duality between itinerant and localized characters of 3d electrons. From results calculated by changing the cluster size, we proposed the NXES-like mechanism for the appearance of the fluorescence-like RXES spectra. It is summarized in Fig. 3.1. The essential point of our picture is the existence of extended states against the strong core hole potential in the intermediate state, although such extended states may have negligible weight in the XAS spectrum.

Regarding the 3d orbitals as Ce 4f ones, it was also explained why the experimental Ce 4f-3d RXES of CeO₂ is well reproduced by calculations with a single-cation impurity Anderson model.

In Chap. 3, the theory in the preceding chapter was extended to include explicit orbital degeneracy. We devised a doubly-degenerate one-dimensional model which contains two kinds of local point group symmetry, and associated them with eₘ and t₂g orbitals in a crystal of O₈ symmetry. First we study 3d-2p RXES spectra for d⁰ systems. Within the single-metal-ion model, we mathematically defined antibonding and nonbonding states by utilizing the local point group symmetry or the permutation symmetry between the degenerate orbitals, and successfully explained the experimental polarization dependence of Ti 3d-2p RXES of TiO₂. In going from the single-metal-ion model to multi-metal-ion model, the fluorescence-like component comes arise, and the calculated spectra clearly exhibit the interplay between the fluorescence-like and Raman components.

Next we showed calculated results for d¹ systems. The calculated RXES spectra displayed inelastic structures due to inter- or intra-site d-d excitation as well as nonbonding, antibonding and fluorescence-like structures. We found that the energy separation of the inelastic peaks due to the intra-site d-d excitation from the inelastic line considerably depends on cluster size. The polarization dependence similar to the d⁰ system was predicted. The orbital degeneracy as well as the translational symmetry is essential to the appearance of the fluorescence-like spectra.
In Chap. 4, we theoretically investigated the Cu $4p_{\pi}$-1$s$ RXES of Nd$_2$CuO$_4$ with impurity Anderson and large-cluster models. While the former model failed to reproduce the experimentally observed suppression effect of resonance enhancement of the 5.7 eV inelastic peak, we obtained satisfactory agreement with the experimental data by using the large-cluster model. Utilizing PDOS functions, we found that the 2 eV structure is interpreted as an “inter-plaquette” excitation of a hole from a Cu site to other plaquettes to form a Zhang-Rice singlet, whereas the 5.7 eV excitation is attributed to the “intra-plaquette” CT excitation. This difference is clearly reflected on the excitation dependence of RXES spectra. The physical picture of the suppression effect is summarized in Fig. 5.7, which elucidates the essential contribution of the nonlocal screening effect on RXES.

In Chap. 5, first we studied the polarization dependence of charge transfer excitations in Cu $4p_{\pi}$-1$s$ RXES of Nd$_2$CuO$_4$. With a closed expression on angular and polarization dependence of RXES, the experimental polarization dependence is successfully explained. The calculated XAS and RXES spectra involving $4p_{\sigma}$ orbitals substantially followed those of the $4p_{\pi}$. We next examine the $q$-dependence of $4p_{\pi}$-1$s$ RXES spectra. The calculated spectra show, first, that the 5.7 eV peak displays little $q$-dependence, and second, that the 2 eV peak considerably depends on $q$. These are interpreted in terms of intra- and inter-plaquette natures of the excitations, and are consistent to the interpretation in the preceding chapter.

To complete the investigation, some problems are left for us. First, for the NXES-like mechanism, we need to extend more the cluster size to obtain results that are more conclusive, and need to clarify the limitation and applicability of the present effective one-dimensional model. This is interesting also as a subject to examine new numerical algorithms such as DMRG. Within the exact diagonalization method, it is extremely difficult to demonstrate the NXES-like mechanism for realistic three-dimensional, possibly degenerate, models. However, one-dimensional systems themselves have attracted much attention in the context of spin-charge separation [153, 158]. It interesting to study what kind of role RXES plays in such systems.

For cuprates, RXES would give significant information also in doped systems because RXES sensitively reflects electron dynamics associated with relaxation process due to a core hole creation. In fact, our (unpublished) calculation predicts considerable doping dependence of Cu $4p_{\pi}$-1$s$ RXES. Together with angle- or momentum-resolved RXES, detailed experimental and theoretical studies are left for the future problem. In this regard, one may investigate the network dependence in various cuprates. We have obtained in Chap. 5 a negative answer to whether the anisotropy of $4p$ orbitals gives observable effects on the valence electronic system. It is of considerable interest to examine orbital ordering with angular- and polarization-resolved RXES.
Bibliography


[124] Chap. 4 in Ref. [15].


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